

RL78/L12

**RENESAS MCU** 

R01DS0157EJ0100 Rev.1.00 2013.01.31

Integrated LCD controller/driver, True Low Power Platform (as low as 62.5  $\mu$ A/MHz, and 0.64  $\mu$ A for RTC + LVD), 1.6 V to 5.5 V operation, 8 to 32 Kbyte Flash, 31 DMIPS at 24 MHz, for All LCD Based Applications

#### 1. OUTLINE

#### 1.1 Features

#### **Ultra-Low Power Technology**

- 1.6 V to 5.5 V operation from a single supply
- Stop (RAM retained): 0.23  $\mu$ A, (LVD enabled): 0.31  $\mu$ A
- Halt (RTC + LVD): 0.64 μA
- Supports snooze
- Operating: 62.5 μA/MHz
- LCD operating current (Capacitor split method): 0.12 μA
- LCD operating current (Internal voltage boost method): 0.63 μA (V<sub>DD</sub> = 3.0 V)

## 16-bit RL78 CPU Core

- Delivers 31 DMIPS at maximum operating frequency of 24 MHz
- Instruction Execution: 86% of instructions can be executed in 1 to 2 clock cycles
- CISC Architecture (Harvard) with 3-stage pipeline
- Multiply Signed & Unsigned: 16 x 16 to 32-bit result in 1 clock cycle
- MAC: 16 x 16 to 32-bit result in 2 clock cycles
- 16-bit barrel shifter for shift & rotate in 1 clock cycle
- 1-wire on-chip debug function

## **Code Flash Memory**

- Density: 8 KB to 32 KB
- Block size: 1 KB
- On-chip single voltage flash memory with protection from block erase/writing
- Self-programming with flash shield window function

#### **Data Flash Memory**

- Data flash with background operation
- Data flash size: 2 KB size
- Erase cycles: 1 Million (typ.)
- Erase/programming voltage: 1.8 V to 5.5 V

#### RAM

- 1 KB and 1.5 KB size options
- Supports operands or instructions
- Back-up retention in all modes

#### **High-speed On-chip Oscillator**

- 24 MHz with +/- 1% accuracy over voltage (1.8 V to 5.5 V) and temperature (-20°C to 85°C)
- Pre-configured settings: 24 MHz, 16 MHz, 12 MHz, 8 MHz, 4 MHz & 1 MHz

#### **Reset and Supply Management**

- Power-on reset (POR) monitor/generator
- Low voltage detection (LVD) with 14 setting options (Interrupt and/or reset function)

#### LCD Controller/Driver

- Up to 35 seg x 8 com or 39 seg x 4 com
- Supports capacitor split method, internal voltage boost method and resistance division method
- · Supports waveform types A and B
- Supports LCD contrast adjustment (16 steps)
- Supports LCD blinking

#### **Data Memory Access (DMA) Controller**

- Up to 2 fully programmable channels
- Transfer unit: 8- or 16-bit

#### **Multiple Communication Interfaces**

- Up to  $1 \times I^2C$  multi-master
- Up to 2 × CSI/SPI (7-, 8-bit)
- Up to 1 × UART (7-, 8-, 9-bit)
- Up to 1 × LIN

#### **Extended-Function Timers**

- Multi-function 16-bit timers: Up to 8 channels
- Real-time clock (RTC): 1 channel (full calendar and alarm function with watch correction function)
- Interval Timer: 12-bit, 1 channel
- 15 kHz watchdog timer: 1 channel (window function)

#### Rich Analog

- ADC: Up to 10 channels, 10-bit resolution, 2.1  $\mu$ s conversion time
- Supports 1.6 V
- Internal voltage reference (1.45 V)
- On-chip temperature sensor

#### Safety Features (IEC or UL 60730 compliance)

- Flash memory CRC calculation
- RAM parity error check
- RAM write protection
- SFR write protection
- Illegal memory access detection
- Clock frequency detection
- ADC self-test

#### General Purpose I/O

- 5V tolerant, high-current (up to 20 mA per pin)
- Open-Drain, Internal Pull-up support

#### **Operating Ambient Temperature**

• Standard: -40 °C to +85 °C

#### **Package Type and Pin Count**

From 7mm x 7mm to 12mm x 12mm QFP: 32, 44, 48, 52, 64 QFN: 64

O ROM, RAM capacities

|       | 1     |                    | - capacitics |          |          |          |          |  |  |  |  |  |  |
|-------|-------|--------------------|--------------|----------|----------|----------|----------|--|--|--|--|--|--|
| Flash | Data  | RAM                |              | RL78/L12 |          |          |          |  |  |  |  |  |  |
| ROM   | flash |                    | 32 pins      | 44 pins  | 48 pins  | 52 pins  | 64 pins  |  |  |  |  |  |  |
| 32 KB | 2 KB  | 1.5                | R5F10RBC     | R5F10RFC | R5F10RGC | R5F10RJC | R5F10RLC |  |  |  |  |  |  |
|       |       | KB <sup>Note</sup> |              |          |          |          |          |  |  |  |  |  |  |
| 16 KB | 2 KB  | 1                  | R5F10RBA     | R5F10RFA | R5F10RGA | R5F10RJA | R5F10RLA |  |  |  |  |  |  |
|       |       | KB <sup>Note</sup> |              |          |          |          |          |  |  |  |  |  |  |
| 8KB   | 2 KB  | 1                  | R5F10RB8     | R5F10RF8 | R5F10RG8 | R5F10RJ8 | -        |  |  |  |  |  |  |
|       |       | KB <sup>Note</sup> |              |          |          |          |          |  |  |  |  |  |  |

**Note** In the case of the 1 KB, and 1.5 KB, this is 630 bytes when the self-programming function and data flash function is used.

**Remark** The functions mounted depend on the product. See **1.6 Outline of Functions**.

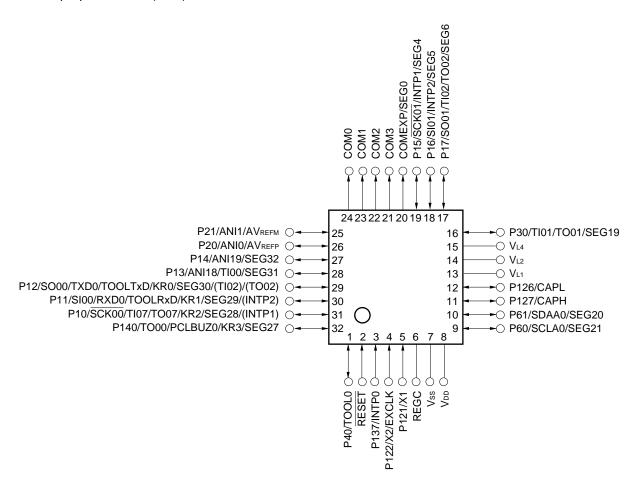
## 1.2 Ordering Information

## • Flash memory version (lead-free product)

| Pin count | Package                          | Part Number                           |
|-----------|----------------------------------|---------------------------------------|
| 32 pins   | 32-pin plastic LQFP (7 × 7)      | R5F10RB8AFP, R5F10RBAAFP, R5F10RBCAFP |
| 44 pins   | 44-pin plastic LQFP (10 × 10)    | R5F10RF8AFP, R5F10RFAAFP, R5F10RFCAFP |
| 48 pins   | 48-pin plastic LQFP              | R5F10RG8AFB, R5F10RGAAFB, R5F10RGCAFB |
|           | (fine pitch) $(7 \times 7)$      |                                       |
| 52 pins   | 52-pin plastic LQFP (10 × 10)    | R5F10RJ8AFA, R5F10RJAAFA, R5F10RJCAFA |
| 64 pins   | 64-pin plastic WQFN (8 × 8)      | R5F10RLAANB, R5F10RLCANB              |
|           | 64-pin plastic LQFP (fine pitch) | R5F10RLAAFB, R5F10RLCAFB              |
|           | (10 × 10)                        |                                       |
|           | 64-pin plastic LQFP (12 × 12)    | R5F10RLAAFA, R5F10RLCAFA              |

- 1.3 Pin Configuration (Top View)
- 1.3.1 32-pin products

• 32-pin plastic LQFP (7 × 7)

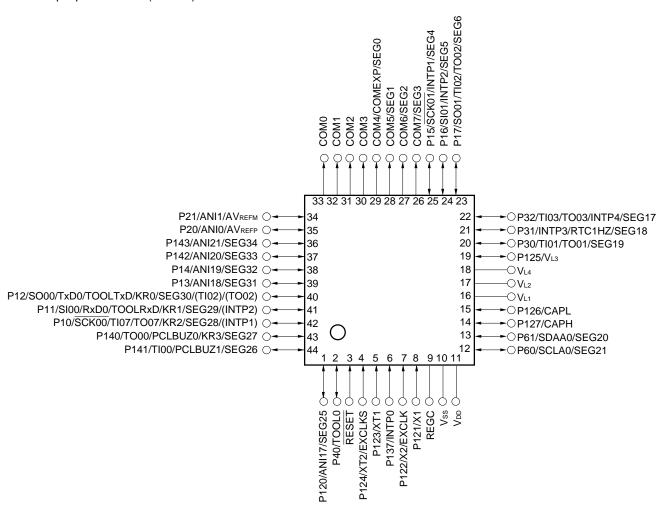


Caution Connect the REGC pin to Vss via a capacitor (0.47 to 1  $\mu$ F).

Remarks 1. For pin identification, see 1.4 Pin Identification.

#### 1.3.2 44-pin products

• 44-pin plastic LQFP (10 × 10)

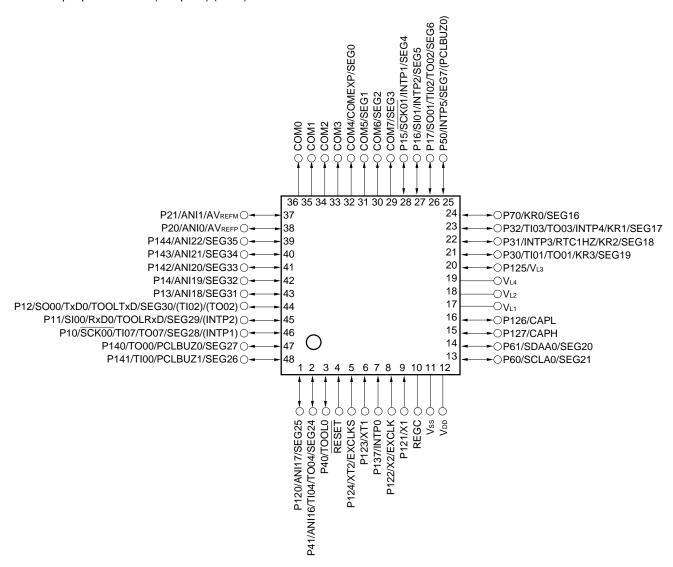


Caution Connect the REGC pin to Vss via a capacitor (0.47 to 1  $\mu$ F).

Remarks 1. For pin identification, see 1.4 Pin Identification.

#### 1.3.3 48-pin products

• 48-pin plastic LQFP (fine pitch) (7 × 7)

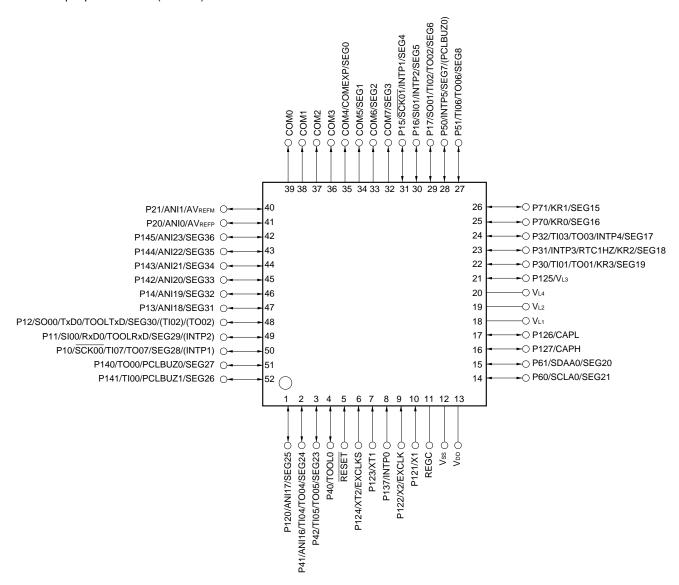


Caution Connect the REGC pin to Vss via a capacitor (0.47 to 1  $\mu$ F).

Remarks 1. For pin identification, see 1.4 Pin Identification.

#### 1.3.4 52-pin products

• 52-pin plastic LQFP (10 × 10)

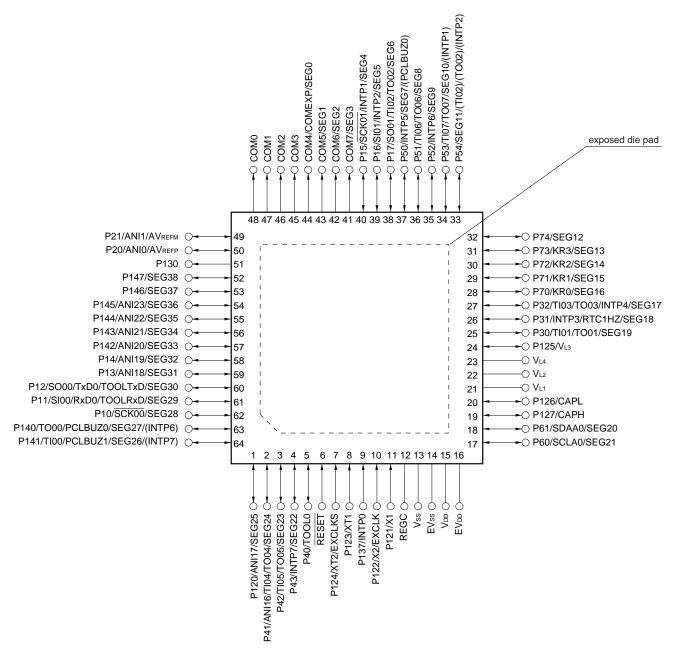


Caution Connect the REGC pin to Vss via a capacitor (0.47 to 1  $\mu$ F).

Remarks 1. For pin identification, see 1.4 Pin Identification.

## 1.3.5 64-pin products

• 64-pin plastic WQFN (8 × 8)

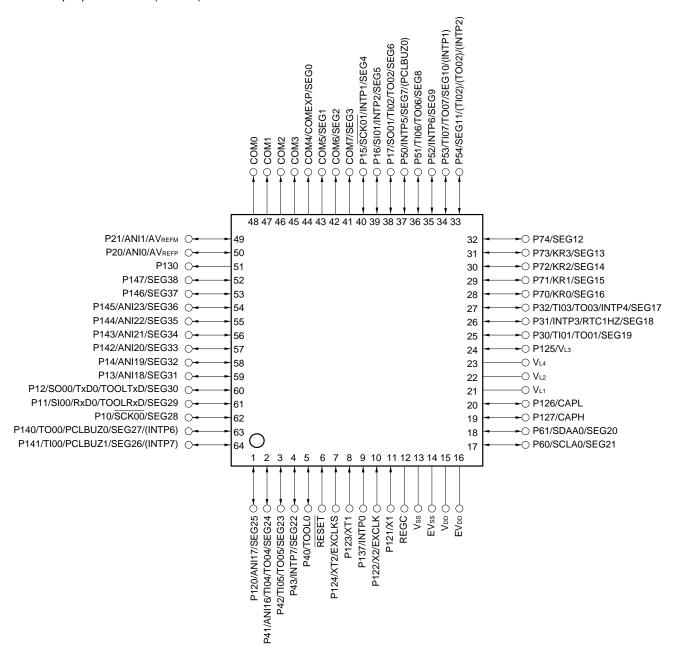


- Cautions 1. Make EVss pin the same potential as Vss pin.
  - 2. Make VDD pin the same potential as EVDD pin.
  - 3. Connect the REGC pin to Vss via a capacitor (0.47 to 1  $\mu$ F).

#### Remarks 1. For pin identification, see 1.4 Pin Identification.

- 2. When using the microcontroller for an application where the noise generated inside the microcontroller must be reduced, it is recommended to supply separate powers to the V<sub>DD</sub> and EV<sub>DD</sub> pins and connect the V<sub>SS</sub> and EV<sub>SS</sub> pins to separate ground lines.
- **3.** Functions in parentheses in the above figure can be assigned via settings in the peripheral I/O redirection register (PIOR)

- 64-pin plastic LQFP (fine pitch) (10 × 10)
- 64-pin plastic LQFP (12 × 12)



Cautions 1. Make EVss pin the same potential as Vss pin.

- 2. Make VDD pin the same potential as EVDD pin.
- 3. Connect the REGC pin to Vss via a capacitor (0.47 to 1  $\mu$ F).

Remarks 1. For pin identification, see 1.4 Pin Identification.

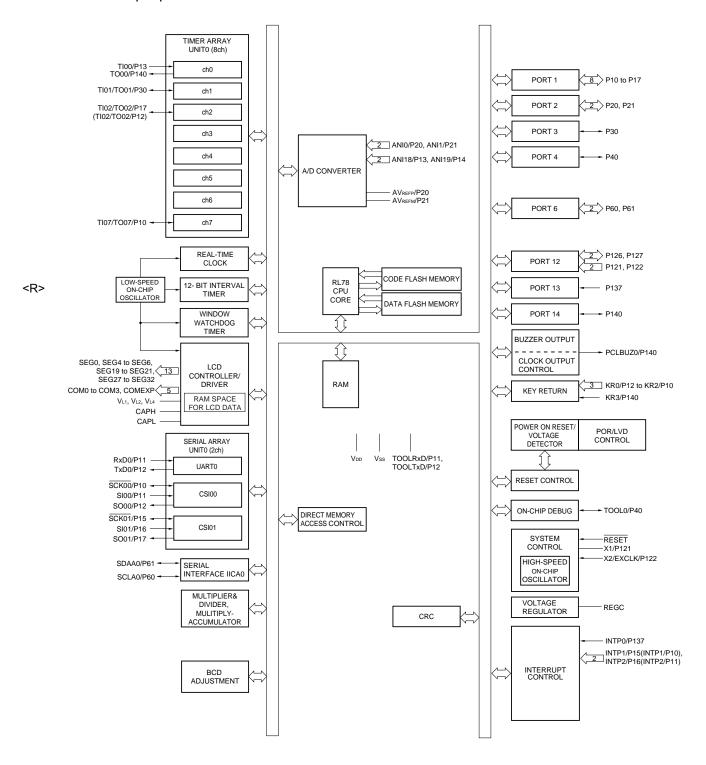
- 2. When using the microcontroller for an application where the noise generated inside the microcontroller must be reduced, it is recommended to supply separate powers to the VDD and EVDD pins and connect the Vss and EVss pins to separate ground lines.
- 3. Functions in parentheses in the above figure can be assigned via settings in the peripheral I/O redirection register (PIOR)

## 1.4 Pin Identification

| ANI0, ANI1,        |                        | P120 to P127:     | Port 12                                |
|--------------------|------------------------|-------------------|--|
| ANI16 to ANI23:    | Analog Input           | P130, P137:       | Port 13                                |
| AVREFM:            | Analog Reference       | P140 to P147:     | Port 14                                |
|                    | Voltage Minus          | PCLBUZ0, PCLBUZ1: | Programmable Clock                     |
| AVREFP:            | Analog Reference       |                   | Output/Buzzer Output                   |
|                    | Voltage Plus           | REGC:             | Regulator Capacitance                  |
| CAPH, CAPL:        | Capacitor for LCD      | RESET:            | Reset                                  |
| COM0 to COM7,      |                        | RTC1HZ:           | Real-time Clock Correction Clock       |
| COMEXP:            | LCD Common Output      |                   | (1 Hz) Output                          |
| EV <sub>DD</sub> : | Power Supply for Port  | RxD0:             | Receive Data                           |
| EVss:              | Ground for Port        | SCK00, SCK01:     | Serial Clock Input/Output              |
| EXCLK:             | External Clock Input   | SCLA0:            | Serial Clock Input/Output              |
|                    | (Main System Clock)    | SDAA0:            | Serial Data Input/Output               |
| EXCLKS:            | External Clock Input   | SEG0 to SEG38:    | LCD Segment Output                     |
|                    | (Subsystem Clock)      | SI00, SI01:       | Serial Data Input                      |
| INTP0 to INTP7:    | Interrupt Request From | SO00, SO01:       | Serial Data Output                     |
|                    | Peripheral             | TI00 to TI07:     | Timer Input                            |
| KR0 to KR3:        | Key Return             | TO00 to TO07:     | Timer Output                           |
| P10 to P17:        | Port 1                 | TOOL0:            | Data Input/Output for Tool             |
| P20, P21:          | Port 2                 | TOOLRxD, TOOLTxD: | Data Input/Output for External Device  |
| P30 to P32:        | Port 3                 | TxD0:             | Transmit Data                          |
| P40 to P43:        | Port 4                 | V <sub>DD</sub> : | Power Supply                           |
| P50 to P54:        | Port 5                 | VL1 to VL4:       | LCD Power Supply                       |
| P60, P61:          | Port 6                 | Vss:              | Ground                                 |
| P70 to P74:        | Port 7                 | X1, X2:           | Crystal Oscillator (Main System Clock) |
|                    |                        | XT1, XT2:         | Crystal Oscillator (Subsystem Clock)   |
|                    |                        |                   |  |

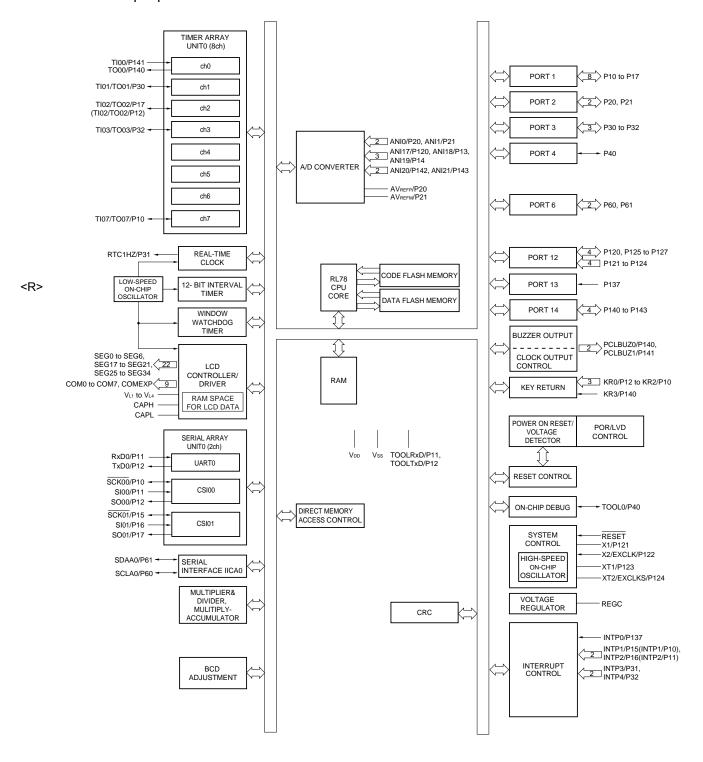
#### 1.5 Block Diagram

#### 1.5.1 32-pin products



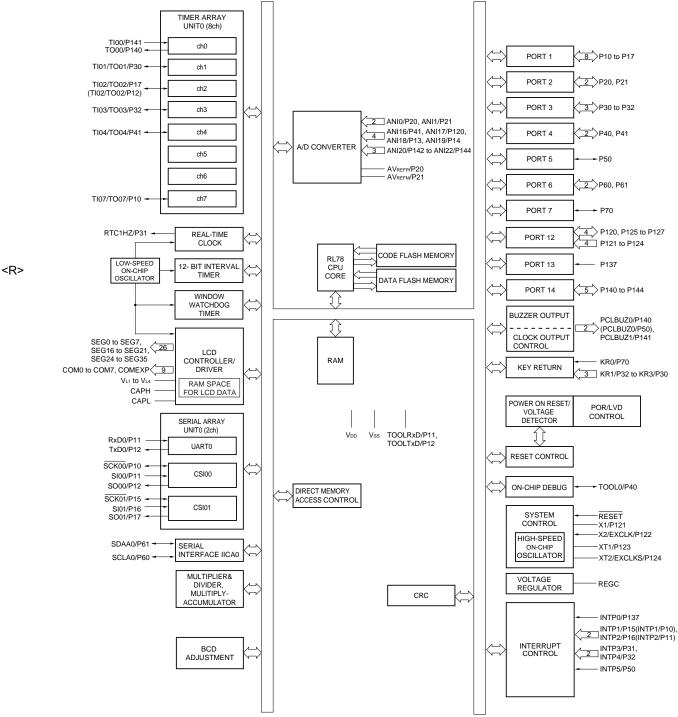
**Remark** Functions in parentheses in the above figure can be assigned via settings in the peripheral I/O redirection register (PIOR)

## 1.5.2 44-pin products



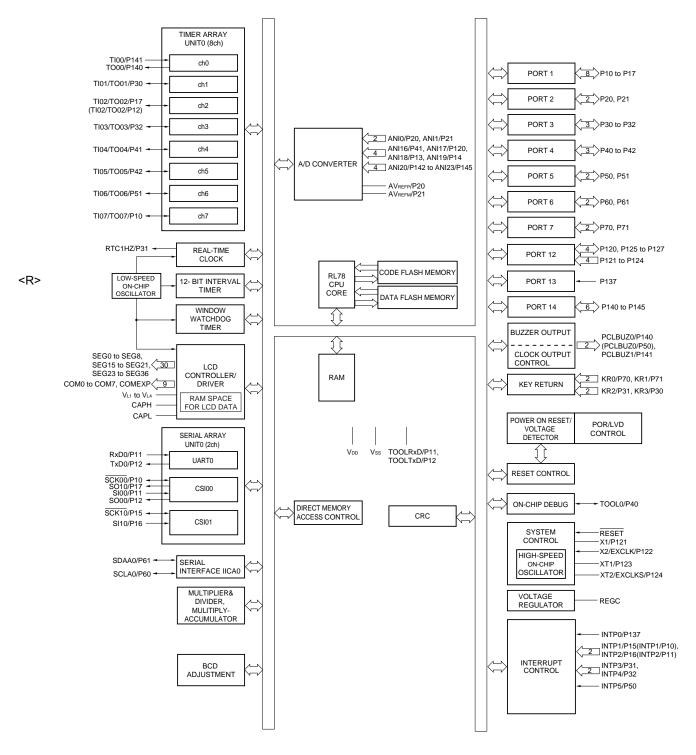
**Remark** Functions in parentheses in the above figure can be assigned via settings in the peripheral I/O redirection register (PIOR)

## 1.5.3 48-pin products



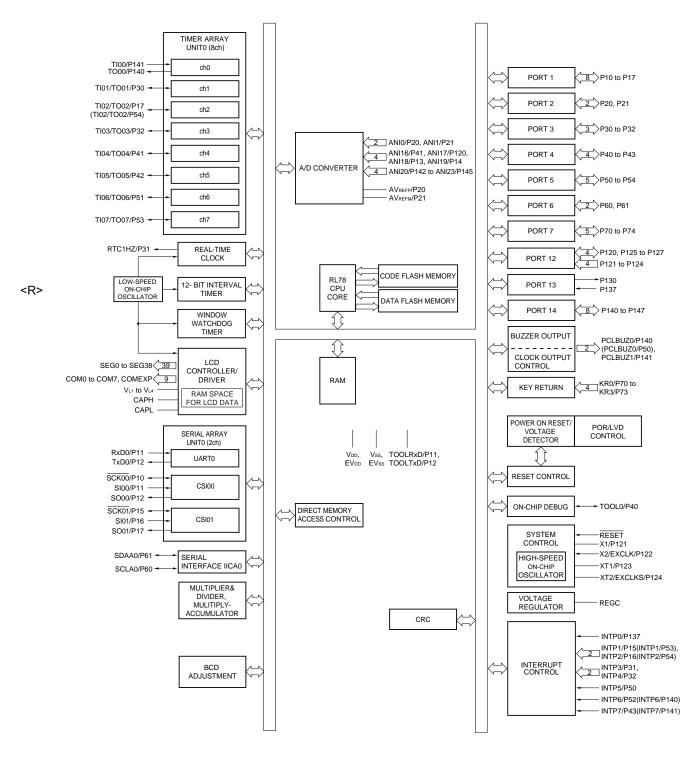
**Remark** Functions in parentheses in the above figure can be assigned via settings in the peripheral I/O redirection register (PIOR)

## 1.5.4 52-pin products



**Remark** Functions in parentheses in the above figure can be assigned via settings in the peripheral I/O redirection register (PIOR)

## 1.5.5 64-pin products



**Remark** Functions in parentheses in the above figure can be assigned via settings in the peripheral I/O redirection register (PIOR)

## 1.6 Outline of Functions

Caution This outline describes the functions at the time when Peripheral I/O redirection register (PIOR) is set to 00H.

(1/2)

|                                    |  | -   |   |  |                                    | (1/2)                    |  |  |  |
|------------------------------------|--|---|---|--|------------------------------------|--------------------------|--|--|--|
|                                    | Item   | 32-pin  | 44-pin  | 48-pin   | 52-pin                             | 64-pin                   |  |  |  |
|                                    |  | R5F10RBx  | R5F10RFx  | R5F10RGx   | R5F10RJx                           | R5F10RLx                 |  |  |  |
| Code flash me                      | emory (KB)                                       | 8 to 32   | 8 to 32   | 8 to 32  | 8 to 32                            | 16, 32                   |  |  |  |
| Data flash me                      | mory (KB)  | 2   | 2   | 2  | 2                                  | 2                        |  |  |  |
| RAM (KB)                           |  | 1, 1.5 Note 1   | 1, 1.5 Note 1   | 1, 1.5 Note 1  | 1, 1.5 Note 1                      | 1, 1.5 <sup>Note 1</sup> |  |  |  |
| Memory space                       | e  | 1 MB  | 1 MB  |  |                                    |                          |  |  |  |
| Main system clock                  | High-speed system clock                          | ` ,   | amic) oscillation, obb = 2.7 to 5.5 V,  | ,  | •                                  | ` ,                      |  |  |  |
|                                    | High-speed on-chip oscillator clock              | HS (high-speed<br>LS (low-speed)  | HS (high-speed main) operation: 1 to 24 MHz (V <sub>DD</sub> = 2.7 to 5.5 V),<br>HS (high-speed main) operation: 1 to 16 MHz (V <sub>DD</sub> = 2.4 to 5.5 V),<br>LS (low-speed main) operation: 1 to 8 MHz (V <sub>DD</sub> = 1.8 to 5.5 V),<br>LV (low-voltage main) operation: 1 to 4 MHz (V <sub>DD</sub> = 1.6 to 5.5 V) |  |                                    |                          |  |  |  |
| Subsystem cl                       | ock  | -   |   | cillation , external<br>'P.): V <sub>DD</sub> = 1.6 to | -                                  | input (EXCLKS)           |  |  |  |
| Low-speed or                       | n-chip oscillator clock                          | Internal oscillati<br>15 kHz (TYP.):  | ion<br>V <sub>DD</sub> = 1.6 to 5.5   | V  |                                    |                          |  |  |  |
| General-purpose register           |  | 8 bits × 32 registers (8 bits × 8 registers × 4 banks)  |   |  |                                    |                          |  |  |  |
| Minimum instruction execution time |  | 0.04167 <i>μ</i> s (Hig   | gh-speed on-chip  | oscillator clock:                                      | fін = 24 MHz оре                   | eration)                 |  |  |  |
|                                    |  | 0.05 μs (High-speed system clock: f <sub>MX</sub> = 20 MHz operation)   |   |  |                                    |                          |  |  |  |
|                                    |  | 30.5 μs (Subsystem clock: fsub = 32.768 kHz operation)  |   |  |                                    |                          |  |  |  |
| Instruction set                    | t  | <ul> <li>Data transfer (8/16 bits)</li> <li>Adder and subtractor/logical operation (8/16 bits)</li> <li>Multiplication (8 bits × 8 bits)</li> <li>Rotate, barrel shift, and bit manipulation (Set, reset, test, and Boolean operation), etc.</li> </ul> |   |  |                                    |                          |  |  |  |
| I/O port                           | Total  | 20  | 29  | 33   | 37                                 | 47                       |  |  |  |
|                                    | CMOS I/O   | 15  | 22  | 26   | 30                                 | 39                       |  |  |  |
|                                    | CMOS input                                       | 3   | 5   | 5  | 5                                  | 5                        |  |  |  |
|                                    | CMOS output                                      | -   | -   | _  | _                                  | 1                        |  |  |  |
|                                    | N-ch open-drain I/O (EV <sub>DD</sub> tolerance) | 2   | 2   | 2  | 2                                  | 2                        |  |  |  |
| Timer                              | 16-bit timer                                     | 8 channels  | 8 channels  | (with 1 channel re                                     | emote control ou                   | tput function)           |  |  |  |
|                                    | Watchdog timer                                   |   |   | 1 channel  |                                    |                          |  |  |  |
|                                    | Real-time clock (RTC)                            |   |   | 1 channel  |                                    |                          |  |  |  |
|                                    | 12-bit interval timer (IT)                       |   |   | 1 channel  |                                    |                          |  |  |  |
|                                    | Timer output                                     | 4 channels<br>(PWM outputs:<br>3 Note 2)  | 5 channels<br>(PWM outputs:<br>4 Note 2)  | 6 channels<br>(PWM outputs:<br>5 Note 2)               | 8 channels (PWM outputs: 7 Note 2) |                          |  |  |  |
|                                    | RTC output                                       | - 1 • 1 Hz (subsystem clock: fsub = 32.768 kHz or )   |   |  |                                    |                          |  |  |  |

**Notes 1.** In the case of the 1 KB, and 1.5 KB, this is 630 bytes when the self-programming function and data flash function is used.

2. The number of PWM outputs varies depending on the setting of channels in use (the number of masters and slaves).

(2/2)

|                                    |   |   |  |                    |                  | (2/2)            |  |  |
|------------------------------------|---|---|--|--------------------|------------------|------------------|--|--|
| Ite                                | m   | 32-pin  | 44-pin   | 48-pin             | 52-pin           | 64-pin           |  |  |
|                                    |   | R5F10RBx  | R5F10RFx   | R5F10RGx           | R5F10RJx         | R5F10RLx         |  |  |
| Clock output/buzz                  | er output                                   | 1   | 1 2  |                    |                  |                  |  |  |
|                                    |   | (Main system  | 38 kHz, 9.76 kHz<br>n clock: fмаіn = 20<br>Hz, 1.024 kHz, 2  | MHz operation)     |                  |                  |  |  |
|                                    |   | (Subsystem  | clock: fsub = 32.7   | 68 kHz operation   | n)               |                  |  |  |
| 8/10-bit resolution                | A/D converter                               | 4 channels  | 7 channels   | 9 channels         | 10 channels      | 10 channels      |  |  |
| Serial interface                   |   | CSI: 2 chan   | nel/UART (LIN-b  | us supported): 1   | channel          |                  |  |  |
| I <sup>2</sup> C bus               |   | 1 channel   | 1 channel  | 1 channel          | 1 channel        | 1 channel        |  |  |
| LCD controller/driver              |   | Internal voltage<br>division<br>method are swi  | boosting method  | d, capacitor split | method, and exte | ernal resistance |  |  |
| Segment sig                        | anal output                                 | 13  | 22 (18) Note 1   | 26 (22) Note 1     | 30 (26) Note 1   | 39 (35) Note 1   |  |  |
| Common si                          |   | 4   | 4 (8) Note 1   |                    |                  |                  |  |  |
| Multiplier and divider/multiply-ac | Multiplier and divider/multiply-accumulator |   | <ul> <li>16 bits × 16 bits = 32 bits (Unsigned or signed)</li> <li>32 bits ÷ 32 bits = 32 bits (Unsigned)</li> <li>16 bits × 16 bits + 32 bits = 32 bits (Unsigned or signed)</li> </ul> |                    |                  |                  |  |  |
| DMA controller                     | T   | 2 channels  | 1  | 1                  | 1                |                  |  |  |
| Vectored interrupt                 | Internal                                    | 23  | 23   | 23                 | 23               | 23               |  |  |
| sources                            | External                                    | 4   | 6  | 7                  | 7                | 9                |  |  |
| Key interrupt                      |   |   |  | 4                  |                  |                  |  |  |
| Reset                              |   | <ul> <li>Reset by RESET pin</li> <li>Internal reset by watchdog timer</li> <li>Internal reset by power-on-reset</li> <li>Internal reset by voltage detector</li> <li>Internal reset by illegal instruction execution Note 2</li> <li>Internal reset by RAM parity error</li> <li>Internal reset by illegal-memory access</li> </ul> |  |                    |                  |                  |  |  |
| Power-on-reset cir                 | cuit  | Power-on-reset: 1.51 ±0.04 V     Power-down-reset: 1.50 ±0.04 V   |  |                    |                  |                  |  |  |
| Voltage detector                   |   | • Rising edge: 1.67 V to 4.06 V (14 stages) • Falling edge: 1.63 V to 3.98 V (14 stages)  |  |                    |                  |                  |  |  |
| On-chip debug fur                  | nction                                      | Provided  |  |                    |                  |                  |  |  |
| Power supply volta                 | age   | V <sub>DD</sub> = 1.6 to 5.5  | 5 V  |                    |                  |                  |  |  |
| Operating ambien                   | t temperature                               | $T_A = -40 \text{ to } +85$   | 5 °C   |                    |                  |                  |  |  |

**Notes 1.** The values in parentheses are the number of signal outputs when 8 com is used.

The illegal instruction is generated when instruction code FFH is executed.
 Reset by the illegal instruction execution not issued by emulation with the in-circuit emulator or on-chip debug emulator.



#### <R> 2. ELECTRICAL SPECIFICATIONS

- Cautions 1. The RL78/L12 microcontrollers have an on-chip debug function, which is provided for development and evaluation. Do not use the on-chip debug function in products designated for mass production, because the guaranteed number of rewritable times of the flash memory may be exceeded when this function is used, and product reliability therefore cannot be guaranteed. Renesas Electronics is not liable for problems occurring when the on-chip debug function is used.
  - 2. With products not provided with an EV<sub>DD</sub>, or EV<sub>SS</sub> pin, replace EV<sub>DD</sub> with V<sub>DD</sub>, or replace EV<sub>SS</sub> with V<sub>SS</sub>.
  - 3. The pins mounted depend on the product. Refer to 1.3.1 32-pin products to 1.3.5 64-pin products.



<R>

#### 2.1 Absolute Maximum Ratings

## Absolute Maximum Ratings ( $T_A = 25$ °C) (1/3)

| Parameter              | Symbols          | Conditions   | Ratings  | Unit |
|------------------------|------------------|--|--|------|
| Supply voltage         | V <sub>DD</sub>  | V <sub>DD</sub> = EV <sub>DD</sub>   | -0.5 to +6.5   | ٧    |
|                        | EV <sub>DD</sub> | V <sub>DD</sub> = EV <sub>DD</sub>   | -0.5 to +6.5   | ٧    |
|                        | Vss              |  | -0.5 to +0.3   | ٧    |
|                        | EVss             |  | -0.5 to +0.3   | V    |
| REGC pin input voltage | VIREGC           | REGC   | $-0.3 \text{ to } +2.8$ and $-0.3 \text{ to V}_{DD} +0.3^{\text{Note 1}}$                    | V    |
| Input voltage          | VI1              | P10 to P17, P30 to P32, P40 to P43, P50 to P54, P70 to P74, P120, P125 to P127, P140 to P147                       | -0.3 to EV <sub>DD</sub> +0.3<br>and -0.3 to V <sub>DD</sub> +0.3 <sup>Note 2</sup>          | V    |
|                        | V <sub>12</sub>  | P60, P61 (N-ch open-drain)   | -0.3 to EV <sub>DD</sub> +0.3 and $-0.3$ to V <sub>DD</sub> +0.3 <sup>Note 2</sup>           | V    |
|                        | Vıз              | P20, P21, P121 to P124, P137, EXCLK, EXCLKS, RESET   | $-0.3$ to $V_{DD}$ +0.3 $^{Note 2}$  | V    |
| Output voltage         | Vo <sub>1</sub>  | P10 to P17, P30 to P32, P40 to P43,<br>P50 to P54, P60, P61, P70 to P74, P120,<br>P125 to P127, P130, P140 to P147 | -0.3 to EV <sub>DD</sub> +0.3<br>and -0.3 to V <sub>DD</sub> +0.3 <sup>Note 2</sup>          | V    |
|                        | V <sub>O2</sub>  | P20, P21   | -0.3 to V <sub>DD</sub> +0.3 Note 2  | ٧    |
| Analog input voltage   | VAI1             | ANI16 to ANI23   | -0.3 to EV <sub>DD</sub> +0.3 and<br>-0.3 to AV <sub>REF(+)</sub> +0.3 <sup>Notes 2, 3</sup> | V    |
|                        | V <sub>Al2</sub> | ANIO, ANI1   | -0.3 to V <sub>DD</sub> +0.3 and<br>-0.3 to AV <sub>REF(+)</sub> +0.3 <sup>Notes 2, 3</sup>  | V    |

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- **Notes 1.** Connect the REGC pin to Vss via a capacitor (0.47 to 1  $\mu$ F). This value regulates the absolute maximum rating of the REGC pin. Do not use this pin with voltage applied to it.
  - 2. Must be 6.5 V or lower.
  - **3.** Do not exceed  $AV_{REF(+)} + 0.3 \text{ V}$  in case of A/D conversion target pin.

Caution Product quality may suffer if the absolute maximum rating is exceeded even momentarily for any parameter. That is, the absolute maximum ratings are rated values at which the product is on the verge of suffering physical damage, and therefore the product must be used under conditions that ensure that the absolute maximum ratings are not exceeded.

- **Remarks 1.** Unless specified otherwise, the characteristics of alternate-function pins are the same as those of the port pins.
  - **2.** AVREF(+): + side reference voltage of the A/D converter.

<R>

#### Absolute Maximum Ratings ( $T_A = 25$ °C) (2/3)

|         | Parameter   | Symbols         | Conditions                                 | Ratings      | Unit |
|---------|-------------|-----------------|--|--------------|------|
| <r></r> | LCD voltage | V <sub>L1</sub> | V <sub>L1</sub> voltage <sup>Note</sup>    | -0.3 to +2.8 | ٧    |
|         |             | VL2             | V <sub>L2</sub> voltage <sup>Note</sup>    | -0.3 to +6.5 | V    |
|         |             | V <sub>L3</sub> | V <sub>L3</sub> voltage <sup>Note</sup>    | -0.3 to +6.5 | V    |
|         |             | VL4             | V <sub>L4</sub> voltage <sup>Note</sup>    | -0.3 to +6.5 | V    |
|         |             | V <sub>L5</sub> | CAPL, CAPH voltage <sup>Note</sup>         | -0.3 to +6.5 | V    |
|         |             | VL6             | COM0 to COM7, SEG0 to SEG38, COMEXP output | -0.3 to +6.5 | V    |
|         |             |                 | voltage                                    |              |      |

- Note This value only indicates the absolute maximum ratings when applying voltage to the V<sub>L1</sub>, V<sub>L2</sub>, V<sub>L3</sub>, and V<sub>L4</sub> pins; it does not mean that applying voltage to these pins is recommended. When using the internal voltage boosting method or capacitance split method, connect these pins to Vss via a capacitor (0.47  $\mu$  F  $\pm$  30%) and connect a capacitor (0.47  $\mu$  F  $\pm$  30%) between the CAPL and CAPH pins.
- <R> Caution Product quality may suffer if the absolute maximum rating is exceeded even momentarily for any parameter. That is, the absolute maximum ratings are rated values at which the product is on the verge of suffering physical damage, and therefore the product must be used under conditions that ensure that the absolute maximum ratings are not exceeded.

Absolute Maximum Ratings (TA = 25°C) (3/3)

| Parameter                     | Symbols          |                              | Conditions   | Ratings     | Unit |
|-------------------------------|------------------|------------------------------|--|-------------|------|
| Output current, high          | Іонт             | Per pin                      | P10 to P17, P30 to P32,<br>P40 to P43, P50 to P54,<br>P70 to P74, P120, P125 to P127,<br>P130, P140 to P147              | -40         | mA   |
|                               |                  | Total of all pins<br>–170 mA | P10 to P14, P40 to P43, P120,<br>P130, P140 to P147  | -70         | mA   |
|                               |                  |                              | P15 to P17, P30 to P32,<br>P50 to P54, P70 to P74,<br>P125 to P127   | -100        | mA   |
|                               | <b>І</b> он2     | Per pin                      | P20, P21   | -0.5        | mA   |
|                               |                  | Total of all pins            |  | -1          | mA   |
| Output current, low           | lo <sub>L1</sub> | Per pin                      | P10 to P17, P30 to P32,<br>P40 to P43, P50 to P54, P60,<br>P61, P70 to P74, P120,<br>P125 to P127, P130,<br>P140 to P147 | 40          | mA   |
|                               |                  | Total of all pins<br>170 mA  | P10 to P14, P40 to P43, P120,<br>P130, P140 to P147  | 70          | mA   |
|                               |                  |                              | P15 to P17, P30 to P32,<br>P50 to P54, P60, P61,<br>P70 to P74, P125 to P127   | 100         | mA   |
|                               | lol2             | Per pin                      | P20, P21   | 1           | mA   |
|                               |                  | Total of all pins            | ]  | 2           | mA   |
| Operating ambient temperature | Та               | In normal operati            | on mode programming mode   | -40 to +85  | °C   |
| Storage temperature           | Tstg             | ,                            |  | -65 to +150 | °C   |

Caution Product quality may suffer if the absolute maximum rating is exceeded even momentarily for any parameter. That is, the absolute maximum ratings are rated values at which the product is on the verge of suffering physical damage, and therefore the product must be used under conditions that ensure that the absolute maximum ratings are not exceeded.

#### <R> 2.2 Oscillator Characteristics

#### 2.2.1 X1, XT1 oscillator characteristics

 $(T_A = -40 \text{ to } +85^{\circ}\text{C}, 1.6 \text{ V} \le \text{EV}_{DD} = \text{V}_{DD} \le 5.5 \text{ V}, \text{Vss} = \text{EV}_{SS} = 0 \text{ V})$ 

| Parameter   | Resonator         | Recommended<br>Circuit     | Conditions                      | MIN.  | TYP.   | MAX. | Unit |
|---|-------------------|----------------------------|---------------------------------|-------|--------|------|------|
| X1 clock oscillation  |                   | Vss X1 X2                  | $2.7~V \leq V_{DD} \leq 5.5~V$  | 1.0   |        | 20.0 | MHz  |
| frequency (fx) <sup>Note</sup>                              |                   | C1= C2=                    | 1.8 V ≤ V <sub>DD</sub> < 2.7 V | 1.0 8 | 8.0    | MHz  |      |
|   |                   | <i>m</i>                   | 1.6 V ≤ V <sub>DD</sub> <1.8 V  | 1.0   |        | 4.0  | MHz  |
| XT1 clock<br>oscillation<br>frequency (fxT) <sup>Note</sup> | Crystal resonator | Vss XT2 XT1  Rd  C4 — C3 — |                                 | 32    | 32.768 | 35   | kHz  |

Note Indicates only oscillator characteristics. Refer to 2.4 AC Characteristics for instruction execution time.

Cautions 1. When using the X1 oscillator, XT1 oscillator, wire as follows in the area enclosed by the broken lines in the above figures to avoid an adverse effect from wiring capacitance.

- Keep the wiring length as short as possible.
- Do not cross the wiring with the other signal lines.
- Do not route the wiring near a signal line through which a high fluctuating current flows.
- Always make the ground point of the oscillator capacitor the same potential as Vss.
- Do not ground the capacitor to a ground pattern through which a high current flows.
- Do not fetch signals from the oscillator.
- 2. Since the CPU is started by the high-speed on-chip oscillator clock after a reset release, check the X1 clock oscillation stabilization time using the oscillation stabilization time counter status register (OSTC) by the user. Determine the oscillation stabilization time of the OSTC register and the oscillation stabilization time select register (OSTS) after sufficiently evaluating the oscillation stabilization time with the resonator to be used.
- 3. The XT1 oscillator is designed as a low-amplitude circuit for reducing power consumption, and is more prone to malfunction due to noise than the X1 oscillator. Particular care is therefore required with the wiring method when the XT1 clock is used.



## 2.2.2 On-chip oscillator characteristics

#### $(T_A = -40 \text{ to } +85^{\circ}\text{C}, 1.6 \text{ V} \le \text{EV}_{DD} = \text{V}_{DD} \le 5.5 \text{ V}, \text{Vss} = \text{EV}_{SS} = 0 \text{ V})$

| ,   |            |               |                 |      |    |      |      |
|---|------------|---------------|-----------------|------|----|------|------|
| Oscillators   | Parameters |               | Conditions      |      |    | MAX. | Unit |
| High-speed on-chip oscillator clock frequency Note 1  | fін        |               |                 | 1    |    | 24   | MHz  |
| High-speed on-chip oscillator                         |            | −20 to +85 °C | 1.8 V≤VDD≤5.5 V | -1   |    | +1   | %    |
| clock frequency accuracy Note 2                       |            |               | 1.6 V≤Vpp≤1.8 V | -5   |    | +5   | %    |
|   |            | –40 to –20 °C | 1.8 V≤Vpp≤5.5 V | -1.5 |    | +1.5 | %    |
|   |            |               | 1.6 V≤Vpp≤1.8 V | -5.5 |    | +5.5 | %    |
| Low-speed on-chip oscillator clock frequency          | fiL        |               |                 |      | 15 |      | kHz  |
| Low-speed on-chip oscillator clock frequency accuracy |            |               |                 | -15  |    | +15  | %    |

- **Notes 1.** High-speed on-chip oscillator frequency is selected by bits 0 to 3 of option byte (000C2H) and bits 0 to 2 of HOCODIV register.
  - **2.** This indicates the oscillator characteristics only. Refer to **2.4 AC Characteristics** for instruction execution time.

#### 2.3 DC Characteristics

#### 2.3.1 Pin characteristics

#### $(T_A = -40 \text{ to } +85^{\circ}\text{C}, 1.6 \text{ V} \le \text{EV}_{DD} = \text{V}_{DD} \le 5.5 \text{ V}, \text{Vss} = \text{EV}_{SS} = 0 \text{ V})$

(1/5)

| Items                                     | Symbol        |  | Conditions   |                                  | MIN. | TYP.        | MAX.            | Unit |
|---|---------------|--|--|----------------------------------|------|-------------|-----------------|------|
| Output current,<br>high <sup>Note 1</sup> | Іон1          |  | P10 to P17, P30 to P32, P40 to P120, P125 to P127, P130, F                 | <i>'</i>                         |      |             | -10.0<br>Note 3 | mA   |
|   |               | Total of P10 to P14, P40 to P43, P120, | $4.0~V \leq EV_{DD} \leq 5.5~V$  |                                  |      | -40.0       | mA              |      |
|   |               | P130, P140                             |  | 2.7 V ≤ EV <sub>DD</sub> < 4.0 V |      |             | -8.0            | mA   |
|   |               | (vvnen duty                            | uty = $70\%^{\text{Note 2}}$ ) 1.8 V $\leq$ EV <sub>DD</sub> $<$ 2.7 \     |                                  |      |             | -4.0            | mA   |
|   |               |  |  | 1.6 V ≤ EV <sub>DD</sub> < 1.8 V |      |             | -2.0            | mA   |
|   |               | Total of P15 to P17, P30 to P32,       |  | $4.0~V \leq EV_{DD} \leq 5.5~V$  |      |             | -60.0           | mA   |
|   |               | · · · · · · · · · · · · · · · · · · ·  | P50 to P54, P70 to P74, P125 to P127 (When duty = $70\%^{\text{Note 2}}$ ) |                                  |      |             | -15.0           | mA   |
|   |               | (when duty                             | = 70% )  | 1.8 V ≤ EV <sub>DD</sub> < 2.7 V |      |             | -8.0            | mA   |
|   |               |  |  | 1.6 V ≤ EV <sub>DD</sub> < 1.8 V |      |             | -4.0            | mA   |
| lo  |               | Total of all p                         |  |                                  |      |             | -100.0          |      |
|   | loн2 P20, P21 | Per pin                                |  |                                  |      | -0.1 Note 3 | mA              |      |
|   |               |  | Total of all pins (When duty = 70% Note 2)                                 | $1.6~V \leq V_{DD} \leq 5.5~V$   |      |             | -1.5            | mA   |

- **Notes 1**. Value of current at which the device operation is guaranteed even if the current flows from the V<sub>DD</sub>, EV<sub>DD</sub> pins to an output pin.
  - 2. Specification under conditions where the duty factor is 70%.

The output current value that has changed the duty ratio can be calculated with the following expression (when changing the duty factor from 70% to n%).

- Total output current of pins =  $(loh \times 0.7)/(n \times 0.01)$ 
  - <Example> Where n = 50% and loh = -10.0 mA

Total output current of pins =  $(-10.0 \times 0.7)/(50 \times 0.01) = -14.0 \text{ mA}$ 

However, the current that is allowed to flow into one pin does not vary depending on the duty factor. A current higher than the absolute maximum rating must not flow into one pin.

3. Do not exceed the total current value.

Caution P10, P12, P15, P17 do not output high level in N-ch open-drain mode.

#### $(T_A = -40 \text{ to } +85^{\circ}\text{C}, 1.6 \text{ V} \le \text{EV}_{DD} = \text{V}_{DD} \le 5.5 \text{ V}, \text{Vss} = \text{EV}_{SS} = 0 \text{ V})$

(2/5)

| Items                                 | Symbol           |                         | Conditions   |   | MIN.  | TYP. | MAX.           | Unit |
|---------------------------------------|------------------|-------------------------|--|---|-------|------|----------------|------|
| Output current, low <sup>Note 1</sup> | lo <sub>L1</sub> |                         | P10 to P17, P30 to P32, F<br>1, P70 to P74, P120, P125<br>147                        | •   |       |      | 20.0<br>Note 3 | mA   |
|                                       |                  | Per pin for             | P60, P61   |   |       |      | 15.0 Note 3    | mA   |
|                                       |                  | Total of P1             | 0 to P14, P40 to P43,  | $4.0~V \leq EV_{DD} \leq 5.5~V$                     |       |      | 70.0           | mA   |
|                                       |                  | I                       | P130, P140 to P147 2.7 V ≤ EV <sub>DD</sub> < 4.0 V                                  |   |       |      | 15.0           | mA   |
|                                       |                  | (when duty              | $y = 70\%^{\text{Note 2}})$  | $1.8 \text{ V} \leq \text{EV}_{DD} < 2.7 \text{ V}$ |       |      | 9.0            | mA   |
|                                       |                  |                         |  | 1.6 V ≤ EV <sub>DD</sub> < 1.8 V                    |       |      | 4.5            | mA   |
|                                       |                  | Total of P1             | of P15 to P17, P30 to P32, $4.0 \text{ V} \le \text{EV}_{DD} \le 5.5 \text{ V}_{DD}$ |   |       |      | 80.0           | mA   |
|                                       |                  | P50 to P54              | 1, P60, P61, P70 to P74,   | $2.7 \text{ V} \leq \text{EV}_{DD} < 4.0 \text{ V}$ |       |      | 35.0           | mA   |
|                                       |                  |                         | y = 70% <sup>Note 2</sup> )  | 1.8 V ≤ EV <sub>DD</sub> < 2.7 V                    |       |      | 20.0 mA        |      |
|                                       |                  |                         | ,  | 1.6 V ≤ EV <sub>DD</sub> < 1.8 V                    |       |      | 10.0           | mA   |
|                                       |                  | Total of all (When duty | pins $y = 70\%^{\text{Note 2}}$  |   | 150.0 |      | 150.0          | mA   |
|                                       | lo <sub>L2</sub> | P20, P21                | Per pin for  |   | _     |      | 0.4 Note 3     | mA   |
|                                       |                  |                         | Total of all pins (When duty = 70% <sup>Note 2</sup> )                               | $1.6~V \leq V_{DD} \leq 5.5~V$                      |       |      | 5.0            | mA   |

- **Notes 1**. Value of current at which the device operation is guaranteed even if the current flows from an output pin to the EVss and Vss pin.
  - 2. Specification under conditions where the duty factor is 70%.

The output current value that has changed the duty ratio can be calculated with the following expression (when changing the duty factor from 70% to n%).

- Total output current of pins =  $(lol \times 0.7)/(n \times 0.01)$
- <Example> Where n = 50% and lol = 10.0 mA

Total output current of pins =  $(10.0 \times 0.7)/(50 \times 0.01) = 14.0 \text{ mA}$ 

However, the current that is allowed to flow into one pin does not vary depending on the duty factor. A current higher than the absolute maximum rating must not flow into one pin.

3. Do not exceed the total current value.

# (Ta = -40 to +85°C, 1.6 V $\leq$ EVDD = VDD $\leq$ 5.5 V, Vss = EVss = 0 V)

(3/5)

| Items                  | Symbol           | Conditions   |   | MIN.                | TYP.               | MAX.                | Unit |
|------------------------|------------------|--|---|---------------------|--------------------|---------------------|------|
| Input voltage,<br>high | V <sub>IH1</sub> | P10 to P17, P30 to P32, P40 to P43,<br>P50 to P54, P70 to P74, P120,<br>P125 to P127, P140 to P147 | Normal input buffer   | 0.8EV <sub>DD</sub> |                    | EV <sub>DD</sub>    | ٧    |
|                        | V <sub>IH2</sub> | P10, P11, P15, P16   | TTL input buffer 4.0 V ≤ EV <sub>DD</sub> ≤ 5.5 V                         | 2.2                 |                    | EV <sub>DD</sub>    | V    |
|                        |                  |  | TTL input buffer 3.3 V ≤ EV <sub>DD</sub> < 4.0 V                         | 2.0                 |                    | EV <sub>DD</sub>    | V    |
|                        |                  |  | TTL input buffer $1.6~\text{V} \leq \text{EV}_{\text{DD}} < 3.3~\text{V}$ | 1.50                |                    | EV <sub>DD</sub>    | V    |
|                        | V <sub>IH3</sub> | P20, P21   | 0.7V <sub>DD</sub>  |                     | V <sub>DD</sub>    | V                   |      |
|                        | V <sub>IH4</sub> | P60, P61   | 0.7EV <sub>DD</sub>   |                     | EV <sub>DD</sub>   | V                   |      |
|                        | V <sub>IH5</sub> | P121 to P124, P137, EXCLK, EXCLKS  | S, RESET  | 0.8V <sub>DD</sub>  |                    | V <sub>DD</sub>     | V    |
| Input voltage,<br>low  | V <sub>IL1</sub> | P10 to P17, P30 to P32, P40 to P43,<br>P50 to P54, P70 to P74, P120,<br>P125 to P127, P140 to P147 | P74, P120,  |                     |                    | 0.2EV <sub>DD</sub> | V    |
|                        | VIL2             | P10, P11, P15, P16   | TTL input buffer 4.0 V ≤ EV <sub>DD</sub> ≤ 5.5 V                         | 0                   |                    | 0.8                 | V    |
|                        |                  |  | TTL input buffer $3.3 \text{ V} \leq \text{EV}_{DD} < 4.0 \text{ V}$      | 0                   |                    | 0.5                 | V    |
|                        |                  |  | TTL input buffer 1.6 V ≤ EV <sub>DD</sub> < 3.3 V                         | 0                   |                    | 0.32                | V    |
|                        | V <sub>IL3</sub> | P20, P21   |   | 0                   |                    | 0.3V <sub>DD</sub>  | V    |
|                        | VIL4             | P60, P61   |   | 0                   |                    | 0.3EV <sub>DD</sub> | V    |
|                        | VIL5             | P121 to P124, P137, EXCLK, EXCLKS  | 0   |                     | 0.2V <sub>DD</sub> | V                   |      |

Caution The maximum value of VIH of P10, P12, P15, P17 is EVDD, even in the N-ch open-drain mode.

# (Ta = -40 to +85°C, 1.6 V $\leq$ EVDD = VDD $\leq$ 5.5 V, Vss = EVss = 0 V)

(4/5)

| Items                | Symbol           | Conditions  |  | MIN.                  | TYP. | MAX. | Unit |
|----------------------|------------------|---|--|-----------------------|------|------|------|
| Output voltage, high |                  | $4.0 \text{ V} \leq \text{EV}_{\text{DD}} \leq 5.5 \text{ V},$ $I_{\text{OH1}} = -10 \text{ mA}$    | EV <sub>DD</sub> -1.5  |                       |      | V    |      |
|                      |                  | P125 to P127, P130, P140 to P147  | $4.0 \text{ V} \leq \text{EV}_{\text{DD}} \leq 5.5 \text{ V},$ $I_{\text{OH1}} = -3.0 \text{ mA}$    | EV <sub>DD</sub> -0.7 |      |      | V    |
|                      |                  |   | $2.7 \text{ V} \leq \text{EV}_{\text{DD}} \leq 5.5 \text{ V},$ $I_{\text{OH1}} = -2.0 \text{ mA}$    | EV <sub>DD</sub> -0.6 |      |      | V    |
|                      |                  |   | 1.8 V $\leq$ EV <sub>DD</sub> $\leq$ 5.5 V,<br>Іон1 = $-1.5$ mA                                      | EV <sub>DD</sub> -0.5 |      |      | V    |
|                      |                  |   | $1.6 \text{ V} \le \text{EV}_{DD} < 5.5 \text{ V},$ Iон1 = $-1.0 \text{ mA}$                         | EV <sub>DD</sub> -0.5 |      |      | V    |
|                      | V <sub>OH2</sub> | P20, P21  | 1.6 V $\leq$ V <sub>DD</sub> $\leq$ 5.5 V, I <sub>OH2</sub> = $-100~\mu$ A                           | V <sub>DD</sub> -0.5  |      |      | V    |
| Output voltage, low  |                  | $4.0~\textrm{V} \leq \textrm{EV}_\textrm{DD} \leq 5.5~\textrm{V},$ $\textrm{IoL1} = 20~\textrm{mA}$ |  |                       | 1.3  | V    |      |
|                      |                  | P125 to P127, P130, P140 to P147  | $4.0~\text{V} \leq \text{EV}_{\text{DD}} \leq 5.5~\text{V},$ $\text{IoL1} = 8.5~\text{mA}$           |                       |      | 0.7  | V    |
|                      |                  |   | $2.7~\textrm{V} \leq \textrm{EV}_\textrm{DD} \leq 5.5~\textrm{V},$ $\textrm{IoL1} = 3.0~\textrm{mA}$ |                       |      | 0.6  | V    |
|                      |                  |   | $2.7~\textrm{V} \leq \textrm{EV}_\textrm{DD} \leq 5.5~\textrm{V},$ $\textrm{IoL1} = 1.5~\textrm{mA}$ |                       |      | 0.4  | V    |
|                      |                  |   | $1.8 \text{ V} \leq \text{EV}_{\text{DD}} \leq 5.5 \text{ V},$ $I_{\text{OL1}} = 0.6 \text{ mA}$     |                       |      | 0.4  | V    |
|                      |                  |   | $1.6 \text{ V} \le \text{EV}_{DD} < 5.5 \text{ V},$ $I_{OL1} = 0.3 \text{ mA}$                       |                       |      | 0.4  | V    |
|                      |                  |   | 1.6 V $\leq$ V <sub>DD</sub> $\leq$ 5.5 V,<br>lol2 = 400 $\mu$ A                                     |                       |      | 0.4  | V    |
|                      | Vol3             | P60, P61  | $4.0 \text{ V} \le \text{EV}_{\text{DD}} \le 5.5 \text{ V},$ $\text{Iol3} = 15.0 \text{ mA}$         |                       |      | 2.0  | V    |
|                      |                  |   | $4.0 \text{ V} \le \text{EV}_{DD} \le 5.5 \text{ V},$ $log = 5.0 \text{ mA}$                         |                       |      | 0.4  | V    |
|                      |                  |   | $2.7 \text{ V} \leq \text{EV}_{\text{DD}} \leq 5.5 \text{ V},$ $\text{Iol3} = 3.0 \text{ mA}$        |                       |      | 0.4  | V    |
|                      |                  |   | $1.8 \text{ V} \le \text{EV}_{\text{DD}} \le 5.5 \text{ V},$ $lol3 = 2.0 \text{ mA}$                 |                       |      | 0.4  | V    |
|                      |                  | $1.6 \text{ V} \le \text{EV}_{\text{DD}} < 5.5 \text{ V},$ $\text{Iol3} = 1.0 \text{ mA}$           |  |                       | 0.4  | V    |      |

Caution P10, P12, P15, P17 do not output high level in N-ch open-drain mode.

# $(T_A = -40 \text{ to } +85^{\circ}\text{C}, 1.6 \text{ V} \le \text{EV}_{DD} = \text{V}_{DD} \le 5.5 \text{ V}, \text{Vss} = \text{EV}_{SS} = 0 \text{ V})$

(5/5)

| Items                         | Symbol            | Conditio  | ns   |                                       | MIN. | TYP. | MAX. | Unit |
|-------------------------------|-------------------|---|--|---------------------------------------|------|------|------|------|
| Input leakage current, high   | Ішн1              | P10 to P17, P30 to P32,<br>P40 to P43, P50 to P54, P60,<br>P61, P70 to P74, P120,<br>P125 to P127, P140 to P147 | VI = EVDD  |                                       |      |      | 1    | μΑ   |
|                               | I <sub>LIH2</sub> | P20, P21, P137, RESET   | Vı = Vdd   |                                       |      |      | 1    | μΑ   |
|                               | Ішнз              | P121 to P124<br>(X1, X2, XT1, XT2, EXCLK,<br>EXCLKS)  | VI = VDD   | In input port or external clock input |      |      | 1    | μΑ   |
|                               |                   |   |  | In resonator connection               |      |      | 10   | μΑ   |
| Input leakage<br>current, low | ILIL1             | P10 to P17, P30 to P32,<br>P40 to P43, P50 to P54, P60,<br>P61, P70 to P74, P120,<br>P125 to P127, P140 to P147 | Vı = EVss  |                                       |      |      | -1   | μΑ   |
|                               | I <sub>LIL2</sub> | P20, P21, P137, RESET   | Vı = Vss   |                                       |      |      | -1   | μΑ   |
|                               | Ішз               | P121 to P124<br>(X1, X2, XT1, XT2, EXCLK,<br>EXCLKS)  |  | In input port or external clock input |      |      | -1   | μΑ   |
|                               |                   |   |  | In resonator connection               |      |      | -10  | μΑ   |
| On-chip pll-up                | R <sub>U1</sub>   | Vı = EVss   | SEGxx port   |                                       |      |      |      |      |
| resistance                    |                   |   | 2.4 V ≤ I  | $EV_{DD} = V_{DD} \le 5.5 \text{ V}$  | 10   | 20   | 100  | kΩ   |
|                               |                   |   | 1.6 V ≤ EV <sub>DD</sub> = V <sub>DD</sub> < 2.4 V |                                       | 10   | 30   | 100  | kΩ   |
|                               | Ru2               |   | Ports other than above                             |                                       | 10   | 20   | 100  | kΩ   |
|                               |                   |   | (Except for P60, P61, and P130)                    |                                       |      |      |      |      |

## 2.3.2 Supply current characteristics

## $(T_A = -40 \text{ to } +85^{\circ}\text{C}, 1.6 \text{ V} \le \text{EV}_{DD} = \text{V}_{DD} \le 5.5 \text{ V}, \text{Vss} = \text{EV}_{SS} = 0 \text{ V})$

(1/3)

| Parameter | Symbol |           |                                     | Conditions                                   |                      |                         | MIN. | TYP. | MAX. | Unit |
|-----------|--------|-----------|-------------------------------------|--|----------------------|-------------------------|------|------|------|------|
| Supply    |        | Operating | HS                                  | fih = 24 MHz Note 3                          | Basic                | V <sub>DD</sub> = 5.0 V |      | 1.5  |      | mA   |
| current   |        | mode      | (high-speed main) mode              |  | operation            | V <sub>DD</sub> = 3.0 V |      | 1.5  |      | mA   |
|           |        |           | Note 5                              |  | Normal               | V <sub>DD</sub> = 5.0 V |      | 3.3  | 5.0  | mA   |
|           |        |           |                                     |  | operation            | V <sub>DD</sub> = 3.0 V |      | 3.3  | 5.0  | mA   |
|           |        |           |                                     | fin = 16 MHz Note 3                          | Normal               | V <sub>DD</sub> = 5.0 V |      | 2.5  | 3.7  | mA   |
|           |        |           |                                     |  | operation            | V <sub>DD</sub> = 3.0 V |      | 2.5  | 3.7  | mA   |
|           |        |           | LS                                  | fin = 8 MHz Note 3                           | Normal               | V <sub>DD</sub> = 3.0 V |      | 1.2  | 1.8  | mA   |
|           |        |           | (low-speed<br>main) mode            |  | operation            | V <sub>DD</sub> = 2.0 V |      | 1.2  | 1.8  | mA   |
|           |        |           | LV                                  | f <sub>IH</sub> = 4 MHz <sup>Note 3</sup>    | Normal               | V <sub>DD</sub> = 3.0 V |      | 1.2  | 1.7  | mA   |
|           |        |           | (low-voltage<br>main) mode Note     |  | operation            | V <sub>DD</sub> = 2.0 V |      | 1.2  | 1.7  | mA   |
|           |        |           | HS                                  | $f_{MX} = 20 \text{ MHz}^{\text{Note 2}},$   | Normal operation     | Square wave input       |      | 2.8  | 4.4  | mA   |
|           |        |           | (high-speed<br>main) mode<br>Note 5 | V <sub>DD</sub> = 5.0 V                      |                      | Resonator connection    |      | 3.0  | 4.6  | mA   |
|           |        |           |                                     | f <sub>MX</sub> = 20 MHz <sup>Note 2</sup> , | Normal operation     | Square wave input       |      | 2.8  | 4.4  | mA   |
|           |        |           |                                     | V <sub>DD</sub> = 3.0 V                      |                      | Resonator connection    |      | 3.0  | 4.6  | mA   |
|           |        |           |                                     | $f_{MX} = 10 \text{ MHz}^{\text{Note 2}},$   | Normal operation     | Square wave input       |      | 1.8  | 2.6  | mA   |
|           |        |           |                                     | V <sub>DD</sub> = 5.0 V                      |                      | Resonator connection    |      | 1.8  | 2.6  | mA   |
|           |        |           |                                     | $f_{MX} = 10 \text{ MHz}^{\text{Note 2}},$   | Normal operation     | Square wave input       |      | 1.8  | 2.6  | mA   |
|           |        |           |                                     | V <sub>DD</sub> = 3.0 V                      |                      | Resonator connection    |      | 1.8  | 2.6  | mA   |
|           |        |           | LS<br>(low-speed<br>main) mode      | $f_{MX} = 8 MHz^{Note 2}$                    | Normal operation     | Square wave input       |      | 1.1  | 1.7  | mA   |
|           |        |           |                                     | V <sub>DD</sub> = 3.0 V                      |                      | Resonator connection    |      | 1.1  | 1.7  | mA   |
|           |        |           |                                     | $f_{MX} = 8 MHz^{Note 2}$                    | Normal               | Square wave input       |      | 1.1  | 1.7  | mA   |
|           |        |           |                                     | $V_{DD} = 2.0 \text{ V}$                     | operation            | Resonator connection    |      | 1.1  | 1.7  | mA   |
|           |        |           | Subsystem                           | fsub = 32.768 kHz Note 4                     | Normal               | Square wave input       |      | 3.5  | 4.9  | μΑ   |
|           |        |           | clock<br>operation                  | $T_A = -40^{\circ}C$                         | operation            | Resonator connection    |      | 3.6  | 5.0  | μΑ   |
|           |        |           | Орстаногт                           | fsub = 32.768 kHz Note 4                     | Normal               | Square wave input       |      | 3.6  | 4.9  | μΑ   |
|           |        |           |                                     | T <sub>A</sub> = +25°C                       | operation            | Resonator connection    |      | 3.7  | 5.0  | μΑ   |
|           |        |           |                                     | fsub = 32.768 kHz Note 4                     | Normal               | Square wave input       |      | 3.7  | 5.5  | μΑ   |
|           |        |           | T <sub>A</sub> = +50°C              | operation                                    | Resonator connection |                         | 3.8  | 5.6  | μΑ   |      |
|           |        |           |                                     | fsub = 32.768 kHz Note 4                     | Normal               | Square wave input       |      | 3.8  | 6.3  | μΑ   |
|           |        |           |                                     | T <sub>A</sub> = +70°C                       | operation            | Resonator connection    |      | 3.9  | 6.4  | μА   |
|           |        |           |                                     | fsub = 32.768 kHz Note 4                     | Normal               | Square wave input       |      | 4.1  | 7.7  | μΑ   |
|           |        |           |                                     | $T_A = +85^{\circ}C$                         | operation            | Resonator connection    |      | 4.2  | 7.8  | μΑ   |

(Notes and Remarks are listed on the next page.)

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- Notes 1. Total current flowing into VDD and EVDD, including the input leakage current flowing when the level of the input pin is fixed to VDD, EVDD or Vss, EVss. The values below the MAX. column include the peripheral operation current (except for back ground operation (BGO)). However, not including the current flowing into the watchdog timer, 12-bit interval timer, A/D converter, LVD circuit, I/O port, on-chip pull-up/pull-down resistors, and LCD controller driver.
  - 2. When high-speed on-chip oscillator and subsystem clock are stopped. When real-time clock is stopped.
  - 3. When high-speed system clock and subsystem clock are stopped. When real-time clock is stopped.
  - **4.** When high-speed on-chip oscillator and high-speed system clock are stopped. When real-time clock, serial interface IICA, multiplier and divider/multiply-accumulator, and DMA contoroller are stopped. When AMPHS1 = 1 (Ultra-low power consumption oscillation).
  - **5.** Relationship between operation voltage width, operation frequency of CPU and operation mode is as below.

HS (high-speed main) mode:  $2.7 \text{ V} \le \text{V}_{DD} \le 5.5 \text{ V}@1 \text{ MHz}$  to 24 MHz

 $2.4 \text{ V} \le \text{V}_{DD} \le 5.5 \text{ V}@1 \text{ MHz to } 16 \text{ MHz}$ 

LS (low-speed main) mode: 1.8 V  $\leq$  V<sub>DD</sub>  $\leq$  5.5 V@1 MHz to 8 MHz LV (low-voltage main) mode: 1.6 V  $\leq$  V<sub>DD</sub>  $\leq$  5.5 V@1 MHz to 4 MHz

- Remarks 1. fmx: High-speed system clock frequency (X1 clock oscillation frequency or external main system clock frequency)
  - 2. fih: High-speed on-chip oscillator clock frequency
  - 3. fsub: Subsystem clock frequency (XT1 clock oscillation frequency)
  - 4. Except subsystem clock operation, temperature condition of the TYP. value is TA = 25°C

# (Ta = -40 to +85°C, 1.6 V $\leq$ EVDD = VDD $\leq$ 5.5 V, Vss = EVss = 0 V)

(2/3)

| Parameter         | Symbol                 |             | Conditions                     |  |                         |  | TYP. | MAX. | Unit |
|-------------------|------------------------|-------------|--------------------------------|--|-------------------------|--|------|------|------|
| Supply IDD2       |                        | HALT        | HS                             | f <sub>IH</sub> = 24 MHz <sup>Note 4</sup>   | V <sub>DD</sub> = 5.0 V |  | 0.44 | 1.28 | mA   |
| current<br>Note 1 | Note 2                 | mode        | (high-speed                    |  | V <sub>DD</sub> = 3.0 V |  | 0.44 | 1.28 | mA   |
|                   |                        |             | main) mode                     | fin = 16 MHz Note 4                          | V <sub>DD</sub> = 5.0 V |  | 0.40 | 1.00 | mA   |
|                   |                        |             |                                |  | V <sub>DD</sub> = 3.0 V |  | 0.40 | 1.00 | mA   |
|                   |                        |             | LS                             | fin = 8 MHz Note 4                           | V <sub>DD</sub> = 3.0 V |  | 260  | 530  | μA   |
|                   |                        |             | (low-speed<br>main) mode       |  | V <sub>DD</sub> = 2.0 V |  | 260  | 530  | μΑ   |
|                   |                        |             | LV                             | f <sub>IH</sub> = 4 MHz <sup>Note 4</sup>    | V <sub>DD</sub> = 3.0 V |  | 420  | 640  | μА   |
|                   |                        |             | (low-voltage<br>main) mode     |  | V <sub>DD</sub> = 2.0 V |  | 420  | 640  | μА   |
|                   |                        |             | HS                             | $f_{MX} = 20 \text{ MHz}^{\text{Note 3}},$   | Square wave input       |  | 0.28 | 1.00 | mA   |
|                   |                        |             | (high-speed                    | V <sub>DD</sub> = 5.0 V                      | Resonator connection    |  | 0.45 | 1.17 | mA   |
|                   |                        |             | main) mode                     | f <sub>MX</sub> = 20 MHz <sup>Note 3</sup> , | Square wave input       |  | 0.28 | 1.00 | mA   |
|                   |                        |             |                                | V <sub>DD</sub> = 3.0 V                      | Resonator connection    |  | 0.45 | 1.17 | mA   |
|                   |                        |             |                                | f <sub>MX</sub> = 10 MHz <sup>Note 3</sup> , | Square wave input       |  | 0.19 | 0.60 | mA   |
|                   |                        |             |                                | V <sub>DD</sub> = 5.0 V                      | Resonator connection    |  | 0.26 | 0.67 | mA   |
|                   |                        |             |                                | f <sub>MX</sub> = 10 MHz <sup>Note 3</sup> , | Square wave input       |  | 0.19 | 0.60 | mA   |
|                   |                        |             |                                | V <sub>DD</sub> = 3.0 V                      | Resonator connection    |  | 0.26 | 0.67 | mA   |
|                   |                        |             | LS<br>(low-speed<br>main) mode | fmx = 8 MHz <sup>Note 3</sup> ,              | Square wave input       |  | 95   | 330  | μA   |
|                   |                        |             |                                | V <sub>DD</sub> = 3.0 V                      | Resonator connection    |  | 145  | 380  | μA   |
|                   |                        |             | Note 7                         | f <sub>MX</sub> = 8 MHz <sup>Note 3</sup> ,  | Square wave input       |  | 95   | 330  | μA   |
|                   |                        |             |                                | V <sub>DD</sub> = 2.0 V                      | Resonator connection    |  | 145  | 380  | μA   |
|                   |                        |             | Subsystem                      | fsub = 32.768 kHz <sup>Note 5</sup>          | Square wave input       |  | 0.31 | 0.57 | μA   |
|                   |                        |             | clock                          | T <sub>A</sub> = -40C                        | Resonator connection    |  | 0.50 | 0.76 | μA   |
|                   |                        |             | operation                      | fsub = 32.768 kHz <sup>Note 5</sup>          | Square wave input       |  | 0.37 | 0.57 | μA   |
|                   |                        |             |                                | T <sub>A</sub> = +25°C                       | Resonator connection    |  | 0.56 | 0.76 | μA   |
|                   |                        |             |                                | fsub = 32.768 kHz <sup>Note 5</sup>          | Square wave input       |  | 0.46 | 1.17 | μA   |
|                   |                        |             |                                | T <sub>A</sub> = +50°C                       | Resonator connection    |  | 0.65 | 1.36 | μA   |
|                   |                        |             |                                | fsub = 32.768 kHz <sup>Note 5</sup>          | Square wave input       |  | 0.57 | 1.97 | μA   |
|                   |                        |             |                                | T <sub>A</sub> = +70°C                       | Resonator connection    |  | 0.76 | 2.16 | μA   |
|                   |                        |             |                                | fsub = 32.768 kHz <sup>Note 5</sup>          | Square wave input       |  | 0.85 | 3.37 | μA   |
|                   |                        |             |                                | T <sub>A</sub> = +85°C                       | Resonator connection    |  | 1.04 | 3.56 | μA   |
|                   | IDD3 <sup>Note 6</sup> | STOP        | $T_A = -40$ °C                 |  |                         |  | 0.17 | 0.50 | μΑ   |
|                   |                        | mode Note 8 | T <sub>A</sub> = +25°C         |  |                         |  | 0.23 | 0.50 | μА   |
|                   |                        |             | T <sub>A</sub> = +50°C         |  |                         |  | 0.32 | 1.10 | μΑ   |
|                   |                        |             | T <sub>A</sub> = +70°C         |  |                         |  | 0.43 | 1.90 | μΑ   |
| _                 |                        |             | T <sub>A</sub> = +85°C         |  |                         |  | 0.71 | 3.30 | μΑ   |

(Notes and Remarks are listed on the next page.)

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- Notes 1. Total current flowing into VDD and EVDD, including the input leakage current flowing when the level of the input pin is fixed to VDD, EVDD or Vss, EVss. The values below the MAX. column include the peripheral operation current (except for back ground operation (BGO)). However, not including the current flowing into the watchdog timer, 12-bit interval timer, A/D converter, LVD circuit, I/O port, on-chip pull-up/pull-down resistors, and LCD controller driver.
  - 2. During HALT instruction execution by flash memory.
  - **3.** When high-speed on-chip oscillator and subsystem clock are stopped. When real-time clock and multiplier and divider/multiply-accumulator are stopped.
    - **4.** When high-speed system clock and subsystem clock are stopped. When real-time clock and multiplier and divider/multiply-accumulator are stopped.
    - 5. When operating real-time clock (RTC) and setting ultra-low current consumption (AMPHS1 = 1). When high-speed on-chip oscillator and high-speed system clock are stopped. When real-time clock, serial interface IICA, multiplier and divider/multiply-accumulator, and DMA contoroller are stopped. The values below the MAX. column include the leakage current.
    - **6.** When high-speed on-chip oscillator, high-speed system clock, and subsystem clock are stopped. When real-time clock, serial interface IIC, multiplier and divider/multiply-accumulator, and DMA contoroller are stopped. The values below the MAX. column include the leakage current.
    - **7.** Relationship between operation voltage width, operation frequency of CPU and operation mode is as below.

HS (high-speed main) mode:  $2.7 \text{ V} \le \text{V}_{DD} \le 5.5 \text{ V} @ 1 \text{ MHz}$  to 24 MHz

 $2.4 \text{ V} \leq \text{V}_{DD} \leq 5.5 \text{ V}@1 \text{ MHz to } 16 \text{ MHz}$ 

LS (low-speed main) mode: 1.8 V  $\leq$  VDD  $\leq$  5.5 V@1 MHz to 8 MHz LV (low-voltage main) mode: 1.6 V  $\leq$  VDD  $\leq$  5.5 V@1 MHz to 4 MHz

- **8.** Regarding the value for current operate the subsystem clock in STOP mode, refer to that in HALT mode.
- Remarks 1. fmx: High-speed system clock frequency (X1 clock oscillation frequency or external main system clock frequency)
  - 2. fin: High-speed on-chip oscillator clock frequency
  - 3. fsub: Subsystem clock frequency (XT1 clock oscillation frequency)
  - **4.** Except subsystem clock operation and STOP mode, temperature condition of the TYP. value is T<sub>A</sub> = 25°C

# (Ta = -40 to +85°C, 1.6 V $\leq$ EVDD = VDD $\leq$ 5.5 V, Vss = EVss = 0 V)

(3/3)

| Parameter                                      | Symbol                                 |                                  | Conditions                                  |   | MIN. | TYP.         | MAX.       | Unit     |
|--|--|----------------------------------|---|---|------|--------------|------------|----------|
| RTC operating current                          | IRTC Notes 1, 2                        | fmain is stopped                 | 00.110.110                                  |   |      | 0.08 Note 12 |            | μА       |
| 12-bit inteval timer current                   | I <sub>IT</sub> Notes 1, 2             | fmain is stopped                 |   |   |      | 0.08 Note 12 |            | μА       |
| Watchdog timer operating current               | IWDT Notes 2, 3                        | fil = 15 kHz, fmain is           | fiL = 15 kHz, fмain is stopped              |   |      |              |            | μА       |
| A/D converter operating current                | IADC Note 4                            | When conversion at maximum speed |   | $V_{REFP} = V_{DD} = 5.0 \text{ V}$<br>de, $AV_{REFP} = V_{DD} = 3.0 \text{ V}$   |      | 1.3<br>0.5   | 1.7<br>0.7 | mA<br>mA |
| A/D converter reference voltage current        | ladref                                 |                                  |   |   |      | 75.0         |            | μA       |
| Temperature sensor operating current           | Ітмрѕ                                  |                                  |   |   |      |              |            | μΑ       |
| LVD operating current                          | ILVD Note 5                            |                                  |   |   |      |              |            | μА       |
| BGO operating current                          | IBGO Notes 6, 7                        |                                  |   |   |      |              |            | mA       |
| Flash<br>self-programming<br>operating current | IFSP Note 8                            |                                  |   |   |      | 2.00         | 12.20      | mA       |
| LCD operating current                          | LCD1<br>Notes 9, 10                    | External resistance              | division method                             | V <sub>DD</sub> = E <sub>DD</sub> = 5.0 V<br>V <sub>L4</sub> = 5.0 V              |      | 0.04         | 0.2        | μА       |
|  | ILCD2 Note 9                           | Internal voltage boo             | osting method                               | V <sub>DD</sub> = E <sub>DD</sub> = 5.0 V<br>V <sub>L4</sub> = 5.1 V (VLCD = 12H) |      | 1.12         | 3.7        | μА       |
|  |  |                                  |   | $V_{DD} = E_{DD} = 3.0 \text{ V}$ $V_{L4} = 3.0 \text{ V (VLCD} = 04\text{H)}$    | 0.63 |              | 2.2        | μА       |
|  | ILCD3 Note 9                           | Capacitor split met              | hod   | V <sub>DD</sub> = E <sub>DD</sub> = 3.0 V<br>V <sub>L4</sub> = 3.0 V              |      | 0.12         | 0.5        | μА       |
| SNOOZE   | I <sub>SNOZ</sub>                      | ADC operation                    | ADC operation The mode is performed Note 11 |   |      |              | 0.60       | mA       |
| operating<br>current                           | operating The A/D conversion operating |                                  |   | on operations are   |      | 1.20         | 1.44       | mA       |
|  |  | CSI/UART operation               |   | 0.70  | 0.84 | mA           |            |          |

(Note, Caution and Remark are lisited on the next page)

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- Notes 1. Current flowing only to the real-time clock (excluding the operating current of the XT1 oscillator). The TYP. value of the current value of the RL78/L12 is the sum of the TYP. values of either IDD1 or IDD2, and IRTC, when the real-time clock operates in operation mode or HALT mode. The IDD1 and IDD2 MAX. values also include the real-time clock operating current. However, IDD2 subsystem clock operation includes the operational current of the real-time clock.
  - 2. When high-speed on-chip oscillator and high-speed system clock are stopped.
  - 3. Current flowing only to the watchdog timer (including the operating current of the 15 kHz low-speed on-chip oscillator). The supply current value of the RL78/L12 is the sum of IDD1, IDD2 or IDD3 and IWDT when the watchdog timer operates.
  - **4.** Current flowing only to the A/D converter. The supply current value of the RL78/L12 is the sum of IDD1 or IDD2 and IADC when the A/D converter operates in an operation mode or the HALT mode.
  - **5.** Current flowing only to the LVD circuit. The supply current value of the RL78/L12 is the sum of IDD1, IDD2 or IDD3 and ILVD when the LVD circuit operates.
  - **6.** Current flowing only when the BGO operates. The supply current value of the RL78/L12 is the sum of IDD1 or IDD2 and IBGO when the BGO operates in an operation mode.
  - 7. Current flowing during data flash programming (not including the CPU operating current). The TYP. value indicates the averaged current for repeated writing and erasing of contiguous 1 KB on the flash memory. The MAX. value indicates the inrush current that flows during flash programming.
  - **8.** Current flowing during code flash programming (not including the CPU operating current). The TYP. value indicates the averaged current for repeated writing and erasing of contiguous 1 KB on the flash memory. The MAX. value indicates the inrush current that flows during flash programming.
  - 9. Current flowing only to the LCD controller/driver (VDD pin). The supply current value of the RL78/L12 microcontrollers is the sum of the LCD operating current (ILCD1, ILCD2 or ILCD3) to the supply current (IDD1, or IDD2) when the LCD controller/driver operates in an operation mode or HALT mode. Not including the current that flows through the LCD panel.

The TYP. value and MAX. value are following conditions.

- · Set 20 pins as a segment function, all lighting
- When fsuB is selected for system clock, LCD clock = 128 Hz (LCDC0 = 07H)
- 4-Time-Slice, 1/3 Bias Method
- **10.** Not including the current that flows through the external divider resistor when the external resistance division method is used.
- 11. For shift time to the SNOOZE mode, see 19.3.3 SNOOZE mode in the RL78/L12 User's Manual: Hardware (R01UH0330E).
- <R> 12. Add 200 nA when using fil.

Remarks 1. fil: Low-speed on-chip oscillator clock frequency

- 2. fsub: Subsystem clock frequency (XT1 clock oscillation frequency)
- 3. fclk: CPU/peripheral hardware clock frequency
- **4.** Temperature condition of the TYP. value is  $T_A = 25^{\circ}C$



#### 2.4 AC Characteristics

## 2.4.1 Basic operation

## (Ta = -40 to +85°C, 1.6 V $\leq$ EVDD = VDD $\leq$ 5.5 V, Vss = EVss = 0 V)

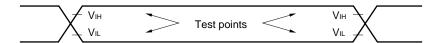
| Items  | Symbol          |   | Conditio                   | ns  |   | MIN.    | TYP. | MAX. | Unit |
|--|-----------------|---|----------------------------|---|---|---------|------|------|------|
| Instruction cycle (minimum instruction execution time)             | Тсч             | Main system                                       |                            | ed 2.7  | $7 \text{ V} \le \text{V}_{DD} \le 5.5 \text{ V}$ | 0.04167 |      | 1    | μS   |
|  |                 | clock (fmain)<br>operation                        | main) mode                 | 2.4   | 4 V ≤ V <sub>DD</sub> < 2.7 V                     | 0.0625  |      | 1    | μs   |
|  |                 | ·   | LV (low voltage main) mode | ge 1.6  | $6 \text{ V} \le \text{V}_{DD} \le 5.5 \text{ V}$ | 0.25    |      | 1    | μS   |
|  |                 |   | LS (low-spee<br>main) mode | ed 1.8  | $3V \le V_{DD} \le 5.5V$                          | 0.125   |      | 1    | μS   |
|  |                 | Subsystem c operation                             | lock (fsuв)                | 1.8   | $3 \text{ V} \le \text{V}_{DD} \le 5.5 \text{ V}$ | 28.5    | 30.5 | 31.3 | μS   |
|  |                 | In the self                                       | HS (high-spe               | ed 2.7  | $7 \text{ V} \le \text{V}_{DD} \le 5.5 \text{ V}$ | 0.04167 |      | 1    | μS   |
|  |                 | programming mode                                  | main) mode                 | 2.4   | $4 \text{ V} \le \text{V}_{DD} < 2.7 \text{ V}$   | 0.0625  |      | 1    | μs   |
|  |                 |   | LV (low voltage main) mode | ge 1.8  | 3 V ≤ V <sub>DD</sub> ≤ 5.5 V                     | 0.25    |      | 1    | μs   |
|  |                 |   | LS (low-spee main) mode    | ed 1.8  | $3 \text{ V} \le \text{V}_{DD} \le 5.5 \text{ V}$ | 0.125   |      | 1    | μS   |
| External main system clock   | fex             | 2.7 V ≤ V <sub>DD</sub> ≤                         | 5.5 V                      | •   |   | 1.0     |      | 20.0 | MHz  |
| frequency  |                 | 1.8 V ≤ V <sub>DD</sub> <                         | : 2.7 V                    |   |   | 1.0     |      | 8.0  | MHz  |
|  |                 | $1.6 \text{ V} \le \text{V}_{DD} < 1.8 \text{ V}$ |                            |   | 1.0   |         | 4.0  | MHz  |      |
|  | fexs            |   |                            |   |   | 32      |      | 35   | kHz  |
| External main system clock input high-level width, low-level width | texh, texl      | $2.7~V \leq V_{DD} \leq 5.5~V$                    |                            |   | 24  |         |      | ns   |      |
| nign-iever width, low-iever width                                  |                 | 1.8 V ≤ V <sub>DD</sub> < 2.7 V                   |                            |   | 60  |         |      | ns   |      |
|  |                 | 1.6 V ≤ V <sub>DD</sub> < 1.8 V                   |                            |   | 120   |         |      | ns   |      |
|  | texhs,<br>texhs |   | 13.7                       |   |   | μS      |      |      |      |
| TI00 to TI07 input high-level width, low-level width               | tтін,<br>tті∟   |   |                            | 1/fмск+10   |   |         | ns   |      |      |
| TO00 to TO07 output frequency                                      | fто             | HS (high-speed                                    | main) 4.0                  | V ≤ E   | $V_{DD} \le 5.5 \text{ V}$                        |         |      | 12   | MHz  |
|  |                 | mode  | 2.7                        | V ≤ E   | VDD < 4.0 V                                       |         |      | 8    | MHz  |
|  |                 |   | 2.4                        | $2.4 \text{ V} \leq \text{EV}_{DD} < 2.7 \text{ V}$ |   |         |      | 4    | MHz  |
|  |                 | LV (low voltage mode                              | main) 1.6                  | V ≤ E   | V <sub>DD</sub> ≤ 5.5 V                           |         |      | 2    | MHz  |
|  |                 | LS (low-speed r<br>mode                           | main) 1.8                  | V ≤ E   | $V_{DD} \le 5.5 \text{ V}$                        |         |      | 4    | MHz  |
| PCLBUZ0, PCLBUZ1 output  | fpcL            | HS (high-speed                                    | main) 4.0                  | V ≤ E\  | $V_{DD} \le 5.5 \text{ V}$                        |         |      | 16   | MHz  |
| frequency  |                 | mode  |                            |   | VDD < 4.0 V                                       |         |      | 8    | MHz  |
|  |                 |   |                            | V ≤ E\  | VDD < 2.7 V                                       |         |      | 4    | MHz  |
|  |                 | LV (low voltage                                   |                            |   | $V_{DD} \le 5.5 \text{ V}$                        |         |      | 4    | MHz  |
|  |                 | mode  |                            |   | VDD < 1.8 V                                       |         |      | 2    | MHz  |
|  |                 | LS (high-speed mode                               | main) 1.8                  | V ≤ E   | V <sub>DD</sub> ≤ 5.5 V                           |         |      | 4    | MHz  |
| Interrupt input high-level width,                                  | tinth,          | INTP0   |                            |   | 5.5  V  | 1       |      |      | μS   |
| low-level width  | tintl           | INTP1 to INT                                      |                            |   | $V_{DD} \le 5.5 \text{ V}$                        | 1       |      |      | μS   |
| Key interrupt input low-level width                                | <b>t</b> kr     | KR0 to KR3  |                            |   | $V_{DD} \le 5.5 \text{ V}$                        | 250     |      |      | ns   |
|  |                 |   | 1.6                        | V ≤ E\  | VDD < 1.8 V                                       | 1       |      |      | μS   |
| RESET low-level width  | trsl            |   |                            |   |   | 10      |      |      | μS   |

Remark fmck: Timer array unit operation clock frequency

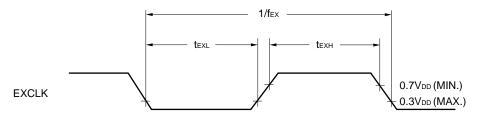
(Operation clock to be set by the CKS0n bit of timer mode register 0n (TMR0n). n: Channel number (n = 0 to 7))



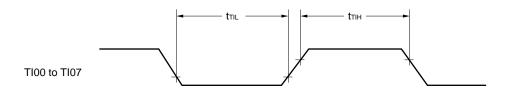
## <R> AC Timing Test Points

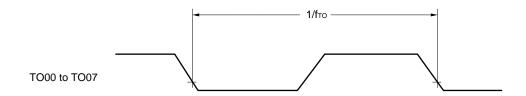


#### **External System Clock Timing**

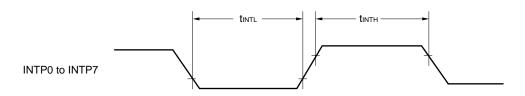


## **TI/TO Timing**

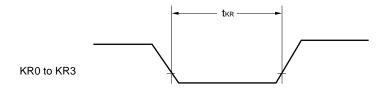




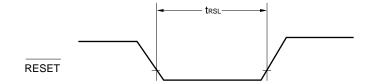
## **Interrupt Request Input Timing**



## **Key Interrupt Input Timing**



# **RESET** Input Timing



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### 2.5 Peripheral Functions Characteristics

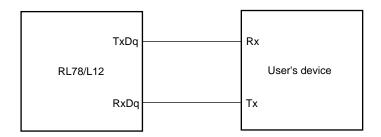
### 2.5.1 Serial array unit

#### (1) During communication at same potential (UART mode) (dedicated baud rate generator output)

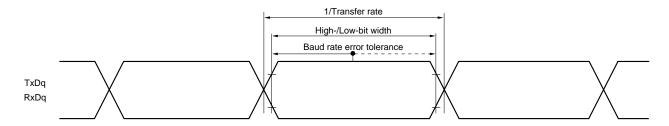
 $(T_A = -40 \text{ to } +85^{\circ}\text{C}, 1.6 \text{ V} \le \text{EV}_{DD} = \text{V}_{DD} \le 5.5 \text{ V}, \text{Vss} = \text{EV}_{SS} = 0 \text{ V})$ 

| Parameter     | Symbol | Conditions  | HS   | Note 1           | LS   | Note 2           | LV   | Note 3           | Unit |
|---------------|--------|---|------|------------------|------|------------------|------|------------------|------|
|               |        |   | MIN. | MAX.             | MIN. | MAX.             | MIN. | MAX.             |      |
| Transfer rate |        | $2.4 \text{ V} \le \text{EVdd} = \text{Vdd} \le 5.5 \text{ V}$            |      | fMCK/6<br>Note 4 |      | fMCK/6<br>Note 4 |      | fMCK/6<br>Note 4 | bps  |
|               |        | Theoretical value of the maximum transfer rate fmck = fclk Note 5         |      | 4.0              |      | 1.3              |      | 0.7              | Mbps |
|               |        | 1.8 V ≤ EVDD = VDD ≤ 5.5 V  |      |                  |      | fMCK/6<br>Note 4 |      | fMCK/6<br>Note 4 | bps  |
|               |        | Theoretical value of the maximum transfer rate $f_{MCK} = f_{CLK}$ Note 5 |      |                  |      | 1.3              |      | 0.7              | Mbps |
|               |        | 1.6 V ≤ EVDD = VDD ≤ 5.5 V  |      |                  |      |                  |      | fMCK/6<br>Note 4 | bps  |
|               |        | Theoretical value of the maximum transfer rate fmck = fclk Note 5         |      |                  |      |                  |      | 0.7              | Mbps |

### **UART** mode connection diagram (during communication at same potential)



#### **UART** mode bit width (during communication at same potential) (reference)



- <R> Notes 1. HS is condition of HS (high-speed main) mode.
  - 2. LS is condition of LS (low-speed main) mode.
  - 3. LV is condition of LV (low-voltage main) mode.
  - 4. Transfer rate in the SNOOZE mode is max. 9600 bps, min. 4800 bps.
  - 5. fclk in each operating mode is as below.

HS (high-speed main) mode:  $f_{CLK} = 24 \text{ MHz}$ LS (low-speed main) mode:  $f_{CLK} = 8 \text{ MHz}$ LV (low-voltage main) mode:  $f_{CLK} = 4 \text{ MHz}$ 

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Caution Select the normal input buffer for the RxDq pin and the normal output mode for the TxDq pin by using port input mode register g (PIMg) and port output mode register g (POMg).

- **Remarks 1.** q: UART number (q = 0), g: PIM and POM number (g = 1)
  - 2. fmck: Serial array unit operation clock frequency
    (Operation clock to be set by the CKSmn bit of serial mode register mn (SMRmn). m: Unit number,
    n: Channel number (mn = 00, 01))



## (2) During communication at same potential (CSI mode) (master mode (fmck/2, fmck/4), SCKp... internal clock output)

 $(T_A = -40 \text{ to } +85^{\circ}\text{C}, 1.6 \text{ V} < \text{FV}_{DD} = \text{V}_{DD} < 5.5 \text{ V}, \text{Vss} = \text{FV}_{SS} = 0.4)$ 

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| Parameter                                       | Symbol        | (          | Conditions   | HS             | Note 1 | LS             | Note 2 | LV              | Note 3 | Unit |
|---|---------------|------------|--|----------------|--------|----------------|--------|-----------------|--------|------|
|   |               |            |  | MIN.           | MAX.   | MIN.           | MAX.   | MIN.            | MAX.   |      |
| SCKp cycle time                                 | tkcy1         | 2.7 V ≤ EV | / <sub>DD</sub> ≤ 5.5 V                                | 167 Note 4     |        | 500 Note 4     |        | 1000 Note 4     |        | ns   |
|   |               | 2.4 V ≤ EV | / <sub>DD</sub> ≤ 5.5 V                                | 250 Note 4     |        | 500 Note 4     |        | 1000 Note 4     |        | ns   |
|   |               | 1.8 V ≤ EV | / <sub>DD</sub> ≤ 5.5 V                                |                |        | 500 Note 4     |        | 1000 Note 4     |        | ns   |
|   |               | 1.6 V ≤ EV | / <sub>DD</sub> ≤ 5.5 V                                |                |        |                |        | 1000 Note 4     |        | ns   |
| SCKp high-/low-level width                      | tkh1,<br>tkL1 | 4.0 V ≤ EV | $V_{DD} \le 5.5 \text{ V}$                             | tксү1/2<br>-12 |        | tксү1/2<br>-50 |        | tkcy1/2<br>-100 |        | ns   |
|   |               | 2.7 V ≤ EV | / <sub>DD</sub> ≤ 5.5 V                                | tксү1/2<br>-18 |        | tксү1/2<br>-50 |        | tксү1/2<br>-100 |        | ns   |
|   |               | 2.4 V ≤ EV | $f_{DD} \leq 5.5 \text{ V}$                            | tксү1/2<br>-38 |        | tксү1/2<br>-50 |        | tkcy1/2<br>-100 |        | ns   |
|   |               | 1.8 V ≤ EV | / <sub>DD</sub> ≤ 5.5 V                                |                |        | tксү1/2<br>-50 |        | tkcy1/2<br>-100 |        | ns   |
|   |               | 1.6 V ≤ EV | /DD ≤ 5.5 V  |                |        |                |        | tkcy1/2<br>-100 |        | ns   |
| Slp setup time (to SCKp↑)                       | tsık1         | 4.0 V ≤ E\ | / <sub>DD</sub> ≤ 5.5 V                                | 44             |        | 110            |        | 220             |        | ns   |
| Note 5  |               | 2.7 V ≤ EV | / <sub>DD</sub> ≤ 5.5 V                                | 44             |        | 110            |        | 220             |        | ns   |
|   |               | 2.4 V ≤ EV | / <sub>DD</sub> ≤ 5.5 V                                | 75             |        | 110            |        | 220             |        | ns   |
|   |               | 1.8 V ≤ E\ | / <sub>DD</sub> ≤ 5.5 V                                |                |        | 110            |        | 220             |        | ns   |
|   |               | 1.6 V ≤ E\ | $I_{DD} \leq 5.5 \text{ V}$                            |                |        |                |        | 220             |        | ns   |
| SIp hold time (from $\overline{SCKp}\uparrow$ ) | <b>t</b> ksii | 2.4 V ≤ EV | $I_{DD} \leq 5.5 \text{ V}$                            | 19             |        | 19             |        | 19              |        | ns   |
| Note 6  |               | 1.8 V ≤ E\ | / <sub>DD</sub> ≤ 5.5 V                                |                |        | 19             |        | 19              |        |      |
|   |               | 1.6 V ≤ EV | / <sub>DD</sub> ≤ 5.5 V                                |                |        |                |        | 19              |        |      |
| Delay time from SCKp↓ to                        | <b>t</b> KSO1 |            | $2.4~V \le EV_{DD} \le 5.5~V$                          |                | 25     |                | 25     |                 | 25     | ns   |
| SOp output Note 7                               |               | Note 8     | $1.8~V \le EV_{DD} \le 5.5~V$                          |                |        |                | 25     |                 | 25     |      |
|   |               |            | $1.6 \text{ V} \leq \text{EV}_{DD} \leq 5.5 \text{ V}$ |                |        |                |        |                 | 25     |      |

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- Notes 1. HS is condition of HS (high-speed main) mode.
- <R> 2. LS is condition of LS (low-speed main) mode.
  - 3. LV is condition of LV (low-voltage main) mode.
  - 4. For CSI00, set a cycle of 2/fmcκ or longer. For CSI01, set a cycle of 4/fmcκ or longer.
  - 5. When DAPmn = 0 and CKPmn = 0, or DAPmn = 1 and CKPmn = 1. The SIp setup time becomes "to  $\overline{\text{SCKp}}\downarrow$ " when DAPmn = 0 and CKPmn = 1, or DAPmn = 1 and CKPmn = 0.
  - 6. When DAPmn = 0 and CKPmn = 0, or DAPmn = 1 and CKPmn = 1. The Slp hold time becomes "from  $\overline{SCKp}\downarrow$ " when DAPmn = 0 and CKPmn = 1, or DAPmn = 1 and CKPmn = 0.
  - 7. When DAPmn = 0 and CKPmn = 0, or DAPmn = 1 and CKPmn = 1. The delay time to SOp output becomes "from SCKp↑" when DAPmn = 0 and CKPmn = 1, or DAPmn = 1 and CKPmn = 0.
  - 8. C is the load capacitance of the SCKp and SOp output lines.

Caution Select the normal input buffer for the SIp pin and the normal output mode for the SOp pin and SCKp pin by using port input mode register g (PIMg) and port output mode register g (POMg).

- **Remarks 1.** p: CSI number (p = 00, 01), m: Unit number (m = 0), n: Channel number (n = 0, 1), g: PIM and POM numbers (g = 1)
  - 2. fmck: Serial array unit operation clock frequency (Operation clock to be set by the CKSmn bit of serial mode register mn (SMRmn). m: Unit number, n: Channel number (mn = 00, 01))

# (3) During communication at same potential (CSI mode) (slave mode, $\overline{SCKp}$ ... external clock input) (T<sub>A</sub> = -40 to +85°C, 1.6 V $\leq$ EV<sub>DD</sub> = V<sub>DD</sub> $\leq$ 5.5 V, Vss = EVss = 0 V)

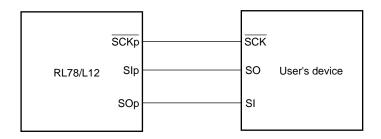
HS Note 1 LS Note 2 LV Note 3 <R> Parameter Symbol Conditions Unit MIN. MAX. MIN. MAX. MIN. MAX. SCKp cycle time Note 4 4.0 V ≤ EVDD ≤ 5.5 V | 20 MHz < fMCK 8/fмск tkCY2 ns  $f_{MCK} \le 20 \; MHz$ 6/fмск 6/fмск 6/fмск ns 2.7 V ≤ EVDD < 4.0 V | 16 MHz < fmck 8/fмск ns fмcк ≤ 16 MHz 6/fмск 6/fмск 6/fмск ns  $2.4 \text{ V} \leq \text{EV}_{DD} < 2.7 \text{ V}$ 12 MHz < fмск 8/fмск 6/fмск  $f_{MCK} \le 12 \; MHz$ 6/fмск 6/fмск ns  $1.8~V \leq EV_{DD} < 2.4~V$ 6/fмск 6/fмск ns  $1.6 \text{ V} \leq \text{EV}_{DD} < 1.8 \text{ V}$ 6/fмск ns SCKp high-/low-level **t**KH2,  $4..0 \text{ V} \leq \text{EV}_{\text{DD}} \leq 5.5 \text{ V}$ tkcy2/2 tkcy2/2 tkcy2/2 ns width **t**KL2 -7 -7 -7  $2.7 \text{ V} \leq \text{EV}_{DD} < 4.0 \text{ V}$ tkcy2/2 tkcy2/ tkcy2/2 ns -8 **--8** -8  $2.4 \text{ V} \leq \text{EV}_{\text{DD}} < 2.7 \text{ V}$ tkcy2/2 tkcy2/2 tkcy2/2 ns -18 -18 -18  $1.8 \text{ V} \leq \text{EV}_{\text{DD}} < 2.4 \text{ V}$ tkcy2/2 tkcy2/2 ns -18-18  $1.6 \text{ V} \leq \text{EV}_{\text{DD}} < 1.8 \text{ V}$ tkcy2/2 ns -66 SIp setup time tsik2  $2.7~V \leq EV_{DD} \leq 5.5~V$ 1/fмcк 1/fмcк 1/fмcк ns (to SCKp↑) Note 5 +20 +30 +30  $2.4~V \leq EV_{DD} < 2.7~V$ 1/fмck 1/fmck 1/fmck +30 +30 +30  $1.8 \text{ V} \leq \text{EV}_{DD} < 2.4 \text{ V}$ 1/fмcк 1/fмcк ns +30 +30  $1.6 \text{ V} \leq \text{EV}_{DD} < 1.8 \text{ V}$ 1/fмcк ns +40 Slp hold time  $2.4 \text{ V} \leq \text{EV}_{\text{DD}} \leq 5.5 \text{ V}$ 1/fмcк 1/fмck **t**KSI2 1/fmck ns (from  $\overline{\mathsf{SCKp}} \uparrow$ ) Note 6 +31 +31 +31  $1.8 \text{ V} \leq \text{EV}_{DD} < 2.4 \text{ V}$ 1/fмcк 1/fмck +31 +31  $1.6 \text{ V} \leq \text{EV}_{\text{DD}} < 1.8 \text{ V}$ 1/fмск+ ns 250 Delay time from SCKp↓ C = 30 pF $4.0~V \leq EV_{DD} \leq 5.5~V$ **t**KSO2 2/fmck 2/fmck 2/fmck ns to SOp output Note 7 +44 +110 +110  $2.7 \text{ V} \leq \text{EV}_{DD} < 4.0 \text{ V}$ 2/fmck 2/fmck 2/fmck ns +44 +110 +110  $2.4~V \leq EV_{DD} < 2.7~V$ 2/fmck 2/fmck 2/fмcк ns +75 +110 +110  $1.8~V \leq EV_{DD} < 2.4~V$ 2/fmck 2/fmck +110 +110  $1.6~V \leq EV_{DD} < 1.8~V$ 2/fмcк+ 220

(Note, Caution and Remark are listed on the next page.)

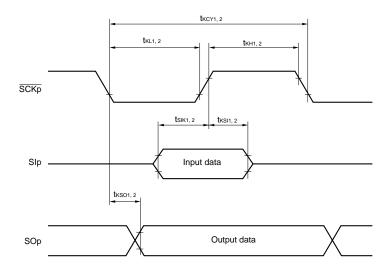
<R>

- <R> Notes 1. HS is condition of HS (high-speed main) mode.
- <R> 2. LS is condition of LS (low-speed main) mode.
  - 3. LV is condition of LV (low-voltage main) mode.
    - 4. Transfer rate in the SNOOZE mode: MAX. 1 Mbps
    - 5. When DAPmn = 0 and CKPmn = 0, or DAPmn = 1 and CKPmn = 1. The SIp setup time becomes "to SCKp↓" when DAPmn = 0 and CKPmn = 1, or DAPmn = 1 and CKPmn = 0.
    - 6. When DAPmn = 0 and CKPmn = 0, or DAPmn = 1 and CKPmn = 1. The SIp hold time becomes "from SCKp↓" when DAPmn = 0 and CKPmn = 1, or DAPmn = 1 and CKPmn = 0.
    - 7. When DAPmn = 0 and CKPmn = 0, or DAPmn = 1 and CKPmn = 1. The delay time to SOp output becomes "from  $\overline{SCKp}\uparrow$ " when DAPmn = 0 and CKPmn = 1, or DAPmn = 1 and CKPmn = 0.
    - 8. C is the load capacitance of the SOp output lines.
- <R> Caution Select the normal input buffer for the SIp pin and SCKp pin and the normal output mode for the SOp pin by using port input mode register g (PIMg) and port output mode register g (POMg).
  - **Remarks 1.** p: CSI number (p = 00, 01), m: Unit number (m = 0), n: Channel number (n = 0, 1), g: PIM number (g = 1)
    - 2. fmck: Serial array unit operation clock frequency (Operation clock to be set by the CKSmn bit of serial mode register mn (SMRmn). m: Unit number, n: Channel number (mn = 00, 01))

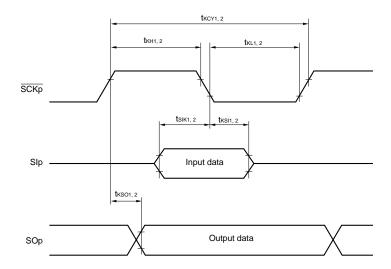
### CSI mode connection diagram (during communication at same potential)



# CSI mode serial transfer timing (during communication at same potential) (When DAPmn = 0 and CKPmn = 0, or DAPmn = 1 and CKPmn = 1.)



# CSI mode serial transfer timing (during communication at same potential) (When DAPmn = 0 and CKPmn = 1, or DAPmn = 1 and CKPmn = 0.)



**Remarks 1.** p: CSI number (p = 00, 01)

2. m: Unit number, n: Channel number (mn = 00, 01)

<R>

# (4) Communication at different potential (1.8 V, 2.5 V, 3 V) (UART mode) (dedicated baud rate generator output) (1/2)

 $(T_A = -40 \text{ to } +85^{\circ}\text{C}, 1.8 \text{ V} \le \text{EV}_{DD} = \text{V}_{DD} \le 5.5 \text{ V}, \text{Vss} = \text{EV}_{SS} = 0 \text{ V})$ 

| Parameter     | Symbol |           | Conditions  | S   | HS   | Note 1           | LS   | Note 2               | LV   | Note 3               | Unit |
|---------------|--------|-----------|---|---|------|------------------|------|----------------------|------|----------------------|------|
|               |        |           |   |   | MIN. | MAX.             | MIN. | MAX.                 | MIN. | MAX.                 |      |
| Transfer rate |        | reception | $4.0 \text{ V} \le \text{EV}_{DD} \le 5.5 \text{ V},$<br>$2.7 \text{ V} \le \text{V}_{b} \le 4.0 \text{ V}$ |   |      | fMCK/6<br>Note 4 |      | fMCK/6<br>Notes 4, 5 |      | fMCK/6<br>Notes 4, 5 | bps  |
|               |        |           |   | Theoretical value of the maximum transfer rate fmck = fclk Note 6 |      | 4.0              |      | 1.3                  |      | 0.7                  | Mbps |
|               |        |           | $2.7 \text{ V} \le \text{EV}_{DD} < 4.0 \text{ V},$<br>$2.3 \text{ V} \le \text{V}_{b} \le 2.7 \text{ V}$   |   |      | fMCK/6<br>Note 4 |      | fMCK/6<br>Notes 4, 5 |      | fMCK/6<br>Notes 4, 5 | bps  |
|               |        |           |   | Theoretical value of the maximum transfer rate fmck = fclk Note 6 |      | 4.0              |      | 1.3                  |      | 0.7                  | Mbps |
|               |        |           | $2.4 \text{ V} \le \text{EV}_{DD} < 3.3 \text{ V},$<br>$1.6 \text{ V} \le \text{V}_{b} \le 2.0 \text{ V}$   |   |      | fMCK/6<br>Note 4 |      | fMCK/6<br>Notes 4, 5 |      | fMCK/6<br>Notes 4, 5 | bps  |
|               |        |           |   | Theoretical value of the maximum transfer rate fMCK = fCLK Note 6 |      | 4.0              |      | 1.3                  |      | 0.7                  | Mbps |
|               |        |           | 1.8 $V \le EV_{DD} < 3.3 V$ ,<br>1.6 $V \le V_b \le 2.0 V$  |   |      |                  |      | fMCK/6<br>Notes 4, 5 |      | fMCK/6<br>Notes 4, 5 | bps  |
|               |        |           |   | Theoretical value of the maximum transfer rate fmck = fclk Note 6 |      |                  |      | 1.3                  |      | 0.7                  | Mbps |

- <R> Notes 1. HS is condition of HS (high-speed main) mode.
- <R> 2. LS is condition of LS (low-speed main) mode.
- <R> 3. LV is condition of LV (low-voltage main) mode.
  - 4. Transfer rate in the SNOOZE mode: MAX. 9600 bps, MIN. 4800 bps
  - **5.** Use it with EV<sub>DD</sub>≥V<sub>b</sub>.
- <R> 6. fclk in each operating mode is as below.

HS (high-speed main) mode: fclk = 24 MHzLS (low-speed main) mode: fclk = 8 MHzLV (low-voltage main) mode: fclk = 4 MHz

Caution Select the TTL input buffer for the RxDq pin and the N-ch open drain output (VDD tolerance (32-pin to 52-pin products)/EVDD tolerance (64-pin products)) mode for the TxDq pin by using port input mode register g (PIMg) and port output mode register g (POMg).

- Remarks 1. V<sub>b</sub>[V]: Communication line voltage
  - **2.** q: UART number (q = 0), g: PIM and POM number (g = 1)
  - 3. fMCK: Serial array unit operation clock frequency(Operation clock to be set by the CKSmn bit of serial mode register mn (SMRmn). m: Unit number,n: Channel number (mn = 00, 01)

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# (4) Communication at different potential (1.8 V, 2.5 V, 3 V) (UART mode) (dedicated baud rate generator output) (2/2)

 $(T_A = -40 \text{ to } +85^{\circ}\text{C}, 1.8 \text{ V} \le \text{EV}_{DD} = \text{V}_{DD} \le 5.5 \text{ V}, \text{Vss} = \text{EVss} = 0 \text{ V})$ 

| Parameter     | Symbol |              | Conditions  |  | HS   | Note 1               | LS   | Note 2               | LV   | Note 3               | Unit |
|---------------|--------|--------------|---|--|------|----------------------|------|----------------------|------|----------------------|------|
|               |        |              |   |  | MIN. | MAX.                 | MIN. | MAX.                 | MIN. | MAX.                 |      |
| Transfer rate |        | transmission | $4.0 \ V \le EV_{DD} \le 5.5 \ V,$ $2.7 \ V \le V_b \le 4.0 \ V$  |  |      | Notes<br>4, 5        |      | Notes<br>4, 5        |      | Notes<br>4, 5        | bps  |
|               |        |              |   | Theoretical value of the maximum transfer rate $C_b=50 \text{ pF},  R_b=1.4 \text{ k}\Omega,$ $V_b=2.7 \text{ V}$          |      | 2.8<br>Note 6        |      | 2.8<br>Note 6        |      | 2.8<br>Note 6        | Mbps |
|               |        |              | $2.7 \text{ V} \le \text{EV}_{DD} < 4.0 \text{ V},$<br>$2.3 \text{ V} \le \text{V}_{b} \le 2.7 \text{ V}$ |  |      | Notes<br>5, 7        |      | Notes<br>5, 7        |      | Notes<br>5, 7        | bps  |
|               |        |              |   | Theoretical value of the maximum transfer rate $C_b = 50 \ \text{pF}, \ R_b = 2.7 \ \text{k}\Omega$ $V_b = 2.3 \ \text{V}$ |      | 1.2<br>Note 8        |      | 1.2<br>Note 8        |      | 1.2<br>Note 8        | Mbps |
|               |        |              | $2.4 \ V \le EV_{DD} < 3.3 \ V,$ $1.6 \ V \le V_b \le 2.0 \ V$  |  |      | Notes<br>5, 9,<br>10 |      | Notes<br>5, 9,<br>10 |      | Notes<br>5, 9,<br>10 | bps  |
|               |        |              |   | Theoretical value of the maximum transfer rate $C_b = 50 \text{ pF},  R_b = 5.5 \text{ k}\Omega$ $V_b = 1.6 \text{ V}$     |      | 0.43<br>Note 11      |      | 0.43<br>Note 11      |      | 0.43<br>Note 11      | Mbps |
|               |        |              | $\begin{array}{l} 1.8 \ V \leq EV_{DD} < 3.3 \ V, \\ 1.6 \ V \leq V_b \leq 2.0 \ V \end{array}$           |  |      |                      |      | Notes<br>5, 9,<br>10 |      | Notes<br>5, 9,<br>10 | bps  |
|               |        |              |   | Theoretical value of the maximum transfer rate $C_b = 50 \text{ pF}, R_b = 5.5 \text{ k}\Omega,$ $V_b = 1.6 \text{ V}$     |      |                      |      | 0.43<br>Note 11      |      | 0.43<br>Note 11      | Mbps |

- <R> Notes 1. HS is condition of HS (high-speed main) mode.
- <R> 2. LS is condition of LS (low-speed main) mode.
  - 3. LV is condition of LV (low-voltage main) mode.
  - **4.** The smaller maximum transfer rate derived by using fmck/6 or the following expression is the valid maximum transfer rate.

Expression for calculating the transfer rate when  $4.0~\text{V} \leq \text{EV}_{DD} \leq 5.5~\text{V}$  and  $2.7~\text{V} \leq \text{V}_{b} \leq 4.0~\text{V}$ 

$$\label{eq:maximum transfer rate} \begin{aligned} & \frac{1}{ \left\{ -C_b \times R_b \times ln \ (1 - \frac{2.2}{V_b}) \right\} \times 3} \end{aligned} \ [bps]$$

$$\frac{\frac{1}{\text{Transfer rate} \times 2} - \{-C_b \times R_b \times \ln (1 - \frac{2.2}{V_b})\}}{\frac{1}{(\frac{1}{\text{Transfer rate}}) \times \text{Number of transferred bits}}} \times 100 \, [\%]$$

- \* This value is the theoretical value of the relative difference between the transmission and reception sides.
- 5. Transfer rate in the SNOOZE mode: MAX. 9600 bps, MIN. 4800 bps
- **6.** This value as an example is calculated when the conditions described in the "Conditions" column are met. Refer to Note 4 above to calculate the maximum transfer rate under conditions of the customer.



**Notes 7.** The smaller maximum transfer rate derived by using fmck/6 or the following expression is the valid maximum transfer rate.

Expression for calculating the transfer rate when 2.7 V  $\leq$  EV<sub>DD</sub> < 4.0 V and 2.3 V  $\leq$  V<sub>b</sub>  $\leq$  2.7 V

Maximum transfer rate = 
$$\frac{1}{\{-C_b \times R_b \times ln (1 - \frac{2.0}{V_b})\} \times 3}$$
 [bps]

$$\frac{\frac{1}{\text{Transfer rate} \times 2} - \{-C_b \times R_b \times \text{In} \}}{\frac{1}{(1 - \frac{2.0}{V_b})}} \times \text{Number of transferred bits}$$

- \* This value is the theoretical value of the relative difference between the transmission and reception sides.
- **8.** This value as an example is calculated when the conditions described in the "Conditions" column are met. Refer to Note 7 above to calculate the maximum transfer rate under conditions of the customer.
- **9.** Use it with  $EV_{DD} \ge V_b$ .
- **10.** The smaller maximum transfer rate derived by using fmck/6 or the following expression is the valid maximum transfer rate.

Expression for calculating the transfer rate when 1.8 V  $\leq$  EV<sub>DD</sub> < 3.3 V and 1.6 V  $\leq$  V<sub>b</sub>  $\leq$  2.0 V

Maximum transfer rate = 
$$\frac{1}{\{-C_b \times R_b \times \ln (1 - \frac{1.5}{V_b})\} \times 3}$$
 [bps]

$$\text{Baud rate error (theoretical value)} = \frac{\frac{1}{\text{Transfer rate} \times 2} - \{-C_b \times R_b \times \ln{(1 - \frac{1.5}{V_b})}\}}{\frac{1}{(\text{Transfer rate})} \times \text{Number of transferred bits}} \times 100 \, [\%]$$

- \* This value is the theoretical value of the relative difference between the transmission and reception sides.
- **11.** This value as an example is calculated when the conditions described in the "Conditions" column are met. Refer to Note 10 above to calculate the maximum transfer rate under conditions of the customer.

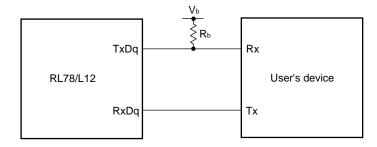
Caution Select the TTL input buffer for the RxDq pin and the N-ch open drain output (Vpd tolerance (32-pin to 52-pin products)/Epd tolerance (64-pin products)) mode for the TxDq pin by using port input mode register g (PIMg) and port output mode register g (POMg).

**Remarks 1.**  $R_b[\Omega]$ :Communication line (TxDq) pull-up resistance,

C<sub>b</sub>[F]: Communication line (TxDq) load capacitance, V<sub>b</sub>[V]: Communication line voltage

- 2. q: UART number (q = 0, 1), g: PIM and POM number (g = 1)
- 3. fмcκ: Serial array unit operation clock frequency(Operation clock to be set by the CKSmn bit of serial mode register mn (SMRmn).m: Unit number, n: Channel number (mn = 00, 01))

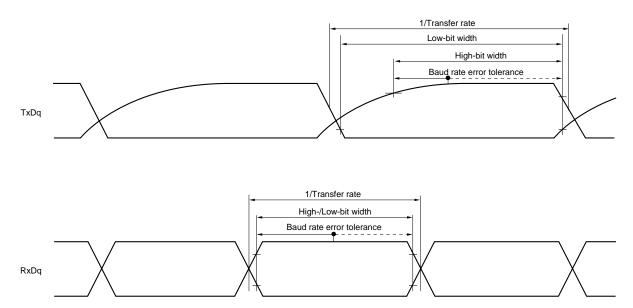
UART mode connection diagram (during communication at different potential)







### UART mode bit width (during communication at different potential) (reference)



Caution Select the TTL input buffer for the RxDq pin and the N-ch open drain output (VDD tolerance (32-pin to 52-pin products)/EVDD tolerance (64-pin products)) mode for the TxDq pin by using port input mode register g (PIMg) and port output mode register g (POMg).

Remarks 1.  $R_b[\Omega]$ :Communication line (TxDq) pull-up resistance,  $V_b[V]$ : Communication line voltage

**2.** q: UART number (q = 0), g: PIM and POM number (g = 1)

# (5) Communication at different potential (2.5 V, 3 V) (fmck/2) (CSI mode) (master mode, SCKp... internal clock output, corresponding CSI00 only)

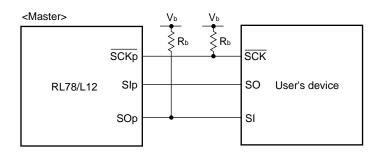
(TA = -40 to +85°C, 2.7 V  $\leq$  EVDD = VDD  $\leq$  5.5 V, Vss = EVss = 0 V)

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| Parameter                | Symbol           | Conditions  | HS      | Note 1 | LS      | Note 2 | LV      | Note 3 | Unit |
|--------------------------|------------------|---|---------|--------|---------|--------|---------|--------|------|
|                          |                  |   | MIN.    | MAX.   | MIN.    | MAX.   | MIN.    | MAX.   |      |
| SCKp cycle time          | tkcy1            | $4.0 \ V \leq EV_{DD} \leq 5.5 \ V,  2.7 \ V \leq V_b \leq 4.0 \ V,$                                  | 200     |        | 1150    |        | 1150    |        | ns   |
|                          |                  | $C_b=20~pF,~R_b=1.4~k\Omega$  | Note 4  |        | Note 4  |        | Note 4  |        |      |
|                          |                  | $2.7 \text{ V} \le \text{EV}_{DD} < 4.0 \text{ V}, 2.3 \text{ V} \le \text{V}_{b} \le 2.7 \text{ V},$ | 300     |        | 1150    |        | 1150    |        | ns   |
|                          |                  | $C_b=20~pF,~R_b=2.7~k\Omega$  | Note 4  |        | Note 4  |        | Note 4  |        |      |
| SCKp high-level width    | <b>t</b> кн1     | $4.0 \ V \leq EV_{DD} \leq 5.5 \ V, \ 2.7 \ V \leq V_b \leq 4.0 \ V,$                                 | tkcy1/2 |        | tkcy1/2 |        | tkcy1/2 |        | ns   |
|                          |                  | $C_b=20~pF,~R_b=1.4~k\Omega$  | - 50    |        | - 50    |        | - 50    |        |      |
|                          |                  | $2.7 \; V \leq EV_{DD} < 4.0 \; V,  2.3 \; V \leq V_b \leq 2.7 \; V,$                                 | tkcy1/2 |        | tkcy1/2 |        | tkcy1/2 |        | ns   |
|                          |                  | $C_b=20~pF,~R_b=2.7~k\Omega$  | - 120   |        | - 120   |        | - 120   |        |      |
| SCKp low-level width     | t <sub>KL1</sub> | $4.0 \ V \leq EV_{DD} \leq 5.5 \ V, \ 2.7 \ V \leq V_b \leq 4.0 \ V,$                                 | tkcy1/2 |        | tkcy1/2 |        | tkcy1/2 |        | ns   |
|                          |                  | $C_b=20~pF,~R_b=1.4~k\Omega$  | -7      |        | - 50    |        | - 50    |        |      |
|                          |                  | $2.7 \; V \leq EV_{DD} < 4.0 \; V,  2.3 \; V \leq V_b \leq 2.7 \; V,$                                 | tkcy1/2 |        | tkcy1/2 |        | tkcy1/2 |        | ns   |
|                          |                  | $C_b=20~pF,~R_b=2.7~k\Omega$  | - 10    |        | - 50    |        | - 50    |        |      |
| SIp setup time           | tsik1            | $4.0 \ V \leq EV_{DD} \leq 5.5 \ V, \ 2.7 \ V \leq V_b \leq 4.0 \ V,$                                 | 58      |        | 479     |        | 479     |        | ns   |
| (to SCKp↑) Note 5        |                  | $C_b=20~pF,~R_b=1.4~k\Omega$  |         |        |         |        |         |        |      |
|                          |                  | $2.7 \; V \leq EV_{DD} < 4.0 \; V,  2.3 \; V \leq V_b \leq 2.7 \; V,$                                 | 121     |        | 479     |        | 479     |        | ns   |
|                          |                  | $C_b=20~pF,~R_b=2.7~k\Omega$  |         |        |         |        |         |        |      |
| SIp hold time            | tksi1            | $4.0 \ V \leq EV_{DD} \leq 5.5 \ V, \ 2.7 \ V \leq V_b \leq 4.0 \ V,$                                 | 10      |        | 10      |        | 10      |        | ns   |
| (from SCKp↑) Note 5      |                  | $C_b=20~pF,~R_b=1.4~k\Omega$  |         |        |         |        |         |        |      |
|                          |                  | $2.7 \; V \leq EV_{DD} < 4.0 \; V,  2.3 \; V \leq V_b \leq 2.7 \; V,$                                 | 10      |        | 10      |        | 10      |        | ns   |
|                          |                  | $C_b=20~pF,~R_b=2.7~k\Omega$  |         |        |         |        |         |        |      |
| Delay time from SCKp↓ to | <b>t</b> KSO1    | $4.0 \ V \leq EV_{DD} \leq 5.5 \ V, \ 2.7 \ V \leq V_b \leq 4.0 \ V,$                                 |         | 60     |         | 60     |         | 60     | ns   |
| SOp output Note 5        |                  | $C_b=20~pF,~R_b=1.4~k\Omega$  |         |        |         |        |         |        |      |
|                          |                  | $2.7 \; V \leq EV_{DD} < 4.0 \; V,  2.3 \; V \leq V_b \leq 2.7 \; V,$                                 |         | 130    |         | 130    |         | 130    | ns   |
|                          |                  | $C_b=20~pF,~R_b=2.7~k\Omega$  |         |        |         |        |         |        |      |
| SIp_setup time           | tsik1            | $4.0 \ V \leq EV_{DD} \leq 5.5 \ V,  2.7 \ V \leq V_b \leq 4.0 \ V,$                                  | 23      |        | 110     |        | 110     |        | ns   |
| (to SCKp↓) Note 6        |                  | $C_b=20~pF,~R_b=1.4~k\Omega$  |         |        |         |        |         |        |      |
|                          |                  | $2.7 \; V \leq EV_{DD} < 4.0 \; V,  2.3 \; V \leq V_b \leq 2.7 \; V,$                                 | 33      |        | 110     |        | 110     |        | ns   |
|                          |                  | $C_b=20~pF,~R_b=2.7~k\Omega$  |         |        |         |        |         |        |      |
| SIp hold time            | <b>t</b> KSI1    | $4.0 \ V \leq EV_{DD} \leq 5.5 \ V,  2.7 \ V \leq V_b \leq 4.0 \ V,$                                  | 10      |        | 10      |        | 10      |        | ns   |
| (from SCKp↓) Note 6      |                  | $C_b=20~pF,~R_b=1.4~k\Omega$  |         |        |         |        |         |        |      |
|                          |                  | $2.7 \; V \leq EV_{DD} < 4.0 \; V,  2.3 \; V \leq V_b \leq 2.7 \; V,$                                 | 10      |        | 10      |        | 10      |        | ns   |
|                          |                  | $C_b=20~pF,~R_b=2.7~k\Omega$  |         |        |         |        |         |        |      |
| Delay time from SCKp↑ to | tkso1            | $4.0 \ V \leq EV_{DD} \leq 5.5 \ V,  2.7 \ V \leq V_b \leq 4.0 \ V,$                                  |         | 10     |         | 10     |         | 10     | ns   |
| SOp output Note 6        |                  | $C_b=20~pF,~R_b=1.4~k\Omega$  |         |        |         |        |         |        |      |
|                          |                  | $2.7 \; V \leq EV_{DD} < 4.0 \; V,  2.3 \; V \leq V_b \leq 2.7 \; V,$                                 |         | 10     |         | 10     |         | 10     | ns   |
|                          |                  | $C_b = 20 \text{ pF}, R_b = 2.7 \text{ k}\Omega$  |         |        |         |        |         |        |      |

(Note, Caution and Remark are listed on the next page.)

#### CSI mode connection diagram (during communication at different potential)



- <R> Notes 1. HS is condition of HS (high-speed main) mode.
- <R> 2. LS is condition of LS (low-speed main) mode.
- <R> 3. LV is condition of LV (low-voltage main) mode.
  - 4. The value must also be 2/fмск or more.
  - 5. When DAPmn = 0 and CKPmn = 0, or DAPmn = 1 and CKPmn = 1.
  - 6. When DAPmn = 0 and CKPmn = 1, or DAPmn = 1 and CKPmn = 0.

Caution Select the TTL input buffer for the SIp pin and the N-ch open drain output (VDD tolerance (32-pin to 52-pin products)/EVDD tolerance (64-pin products)) mode for the SOp pin and SCKp pin by using port input mode register g (PIMg) and port output mode register g (POMg).

- **Remarks 1.** Rb[ $\Omega$ ]:Communication line ( $\overline{SCKp}$ , SOp) pull-up resistance, Cb[F]: Communication line ( $\overline{SCKp}$ , SOp) load capacitance, Vb[V]: Communication line voltage
  - 2. p: CSI number (p = 00, 01), m: Unit number (m = 0), n: Channel number (n = 0, 1), g: PIM and POM number (g = 1)
  - 3. fmck: Serial array unit operation clock frequency (Operation clock to be set by the CKSmn bit of serial mode register mn (SMRmn). m: Unit number, n: Channel number (mn = 00, 01)



# (6) Communication at different potential (1.8 V, 2.5 V, 3 V) (fmck/4) (CSI mode) (master mode, SCKp... internal clock output) (1/2)

 $(T_A = -40 \text{ to } +85^{\circ}\text{C}, 1.8 \text{ V} \le \text{EV}_{DD} = \text{V}_{DD} \le 5.5 \text{ V}, \text{Vss} = \text{EV}_{SS} = 0 \text{ V})$ 

| < | R | > |
|---|---|---|
|   |   |   |

| Parameter             | Symbol           | Conditions  | HS               | Note 1 | LS               | Note 2 | LV               | Note 3 | Unit |
|-----------------------|------------------|---|------------------|--------|------------------|--------|------------------|--------|------|
|                       |                  |   | MIN.             | MAX.   | MIN.             | MAX.   | MIN.             | MAX.   |      |
| SCKp cycle time       | tkcY1            | $ 4.0 \text{ V} \leq \text{EV}_{DD} \leq 5.5 \text{ V}, \ 2.7 \text{ V} \leq \text{V}_b \leq 4.0 \text{ V}, $ $ C_b = 30 \text{ pF}, \ R_b = 1.4 \text{ k}\Omega $  | 300<br>Note 4    |        | 1150<br>Note 4   |        | 1150<br>Note 4   |        | ns   |
|                       |                  | $ 2.7 \text{ V} \le \text{EV}_{DD} < 4.0 \text{ V}, \ 2.3 \text{ V} \le \text{V}_b \le 2.7 \text{ V}, \\ C_b = 30 \text{ pF}, \ R_b = 2.7 \text{ k}\Omega $   | 500<br>Note 4    |        | 1150<br>Note 4   |        | 1150<br>Note 4   |        | ns   |
|                       |                  | $ 2.4 \text{ V} \le \text{EV}_{DD} < 3.3 \text{ V}, \ 1.6 \text{ V} \le \text{V}_b \le 2.0 \text{ V}, $ $ C_b = 30 \text{ pF}, \ R_b = 5.5 \text{ k}\Omega $  | 1150<br>Note 4   |        | 1150<br>Note 4   |        | 1150<br>Note 4   |        | ns   |
|                       |                  | $ \begin{aligned} &1.8 \; V \leq \text{EV}_{\text{DD}} < 3.3 \; \text{V},  1.6 \; \text{V} \leq \text{V}_{\text{b}} \leq 2.0 \; \text{V}, \\ &C_{\text{b}} = 30 \; \text{pF},  R_{\text{b}} = 5.5 \; \text{k}\Omega \end{aligned} $ |                  |        | 1150<br>Note 4   |        | 1150<br>Note 4   |        | ns   |
| SCKp high-level width | tкн1             | $ 4.0 \ V \leq EV_{DD} \leq 5.5 \ V, \ 2.7 \ V \leq V_b \leq 4.0 \ V, $ $ C_b = 30 \ pF, \ R_b = 1.4 \ k\Omega $  | tксү1/2<br>- 75  |        | tксү1/2<br>- 75  |        | tkcy1/2<br>- 75  |        | ns   |
|                       |                  | $ 2.7 \text{ V} \leq \text{EV}_{\text{DD}} < 4.0 \text{ V}, \ 2.3 \text{ V} \leq \text{V}_{\text{b}} \leq 2.7 \text{ V}, $ $ C_{\text{b}} = 30 \text{ pF}, \ R_{\text{b}} = 2.7 \text{ k}\Omega $                                   | tксу1/2<br>- 170 |        | tксү1/2<br>- 170 |        | tксү1/2<br>- 170 |        | ns   |
|                       |                  | $2.4 \ V \le EV_{DD} < 3.3 \ V, \ 1.6 \ V \le V_b \le 2.0 \ V,$ $C_b = 30 \ pF, \ R_b = 5.5 \ k\Omega$  | tkcy1/2<br>- 458 |        | tксү1/2<br>- 458 |        | tkcy1/2<br>- 458 |        | ns   |
|                       |                  | $1.8 \ V \le EV_{DD} < 3.3 \ V, \ 1.6 \ V \le V_b \le 2.0 \ V,$ $C_b = 30 \ pF, \ R_b = 5.5 \ k\Omega$  |                  |        | tксү1/2<br>- 458 |        | tkcy1/2<br>- 458 |        | ns   |
| SCKp low-level width  | t <sub>KL1</sub> | $ 4.0 \ V \leq EV_{DD} \leq 5.5 \ V, \ 2.7 \ V \leq V_b \leq 4.0 \ V, $ $ C_b = 30 \ pF, \ R_b = 1.4 \ k\Omega $  | tксү1/2<br>- 12  |        | tксү1/2<br>- 50  |        | tkcy1/2<br>- 50  |        | ns   |
|                       |                  | $ 2.7 \text{ V} \leq \text{EV}_{DD} < 4.0 \text{ V}, \ 2.3 \text{ V} \leq \text{V}_b \leq 2.7 \text{ V}, $ $ C_b = 30 \text{ pF}, \ R_b = 2.7 \text{ k}\Omega $   | tксу1/2<br>- 18  |        | tксү1/2<br>- 50  |        | tксү1/2<br>- 50  |        | ns   |
|                       |                  | $ 2.4 \text{ V} \le \text{EV}_{DD} < 3.3 \text{ V}, \ 1.6 \text{ V} \le \text{V}_b \le 2.0 \text{ V}, \\ C_b = 30 \text{ pF}, \ R_b = 5.5 \text{ k}\Omega $   | tксу1/2<br>- 50  |        | tксү1/2<br>- 50  |        | tксү1/2<br>- 50  |        | ns   |
|                       |                  | $ \begin{aligned} &1.8 \; V \leq \text{EV}_{\text{DD}} < 3.3 \; \text{V},  1.6 \; \text{V} \leq \text{V}_{\text{b}} \leq 2.0 \; \text{V}, \\ &C_{\text{b}} = 30 \; \text{pF},  R_{\text{b}} = 5.5 \; \text{k}\Omega \end{aligned} $ |                  |        | tксү1/2<br>- 50  |        | tксү1/2<br>- 50  |        | ns   |

- <R> Notes 1. HS is condition of HS (high-speed main) mode.
  - 2. LS is condition of LS (low-speed main) mode.
    - 3. LV is condition of LV (low-voltage main) mode.
    - 4. The value must also be 4/fмск or more.
  - Cautions 1. Select the TTL input buffer for the SIp pin and the N-ch open drain output (VDD tolerance (32-pin to 52-pin products)/EDD tolerance (64-pin products)) mode for the SOp pin and SCKp pin by using port input mode register g (PIMg) and port output mode register g (POMg).
    - 2. Use it with  $EV_{DD} \ge V_b$ .
  - **Remarks 1.** R<sub>b</sub>[Ω]:Communication line (SCKp, SOp) pull-up resistance, C<sub>b</sub>[F]: Communication line (SCKp, SOp) load capacitance, V<sub>b</sub>[V]: Communication line voltage
    - 2. p: CSI number (p = 00, 01), m: Unit number (m = 0), n: Channel number (n = 0, 1), g: PIM and POM number (g = 1)



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# (6) Communication at different potential (1.8 V, 2.5 V, 3 V) (fmck/4) (CSI mode) (master mode, SCKp... internal clock output) (2/2)

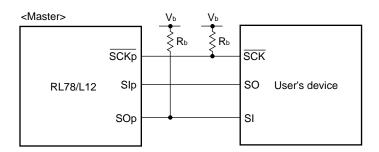
 $(T_A = -40 \text{ to } +85^{\circ}\text{C}, 1.8 \text{ V} \le \text{EV}_{DD} = \text{V}_{DD} \le 5.5 \text{ V}, \text{Vss} = \text{EV}_{SS} = 0 \text{ V})$ 

<R>

| Parameter  | Symbol | Conditions   | HS   | Note 1 | LS   | Note 2 | LV   | Note 3 | Unit |
|--|--------|--|------|--------|------|--------|------|--------|------|
|  |        |  | MIN. | MAX.   | MIN. | MAX.   | MIN. | MAX.   |      |
| SIp setup time (to $\overline{SCKp}\uparrow$ ) Note 4                    | tsıĸ1  | $ \left  \begin{array}{l} 4.0 \; V \leq E  V_{DD} \leq 5.5 \; V,  2.7 \; V \leq V_b \leq 4.0 \; V, \\ C_b = 30 \; pF, \; R_b = 1.4 \; k\Omega \end{array} \right. $  | 81   |        | 479  |        | 479  |        | ns   |
|  |        | $ \label{eq:continuous}                                   $  | 177  |        | 479  |        | 479  |        | ns   |
|  |        | $ \label{eq:continuous}                                   $  | 479  |        | 479  |        | 479  |        | ns   |
|  |        | $ \begin{array}{l} 1.8 \; V \leq E  V_{DD} < 3.3 \; V, \; 1.6 \; V \leq V_b \leq 2.0 \; V, \\ C_b = 30 \; pF, \; R_b = 5.5 \; k\Omega \end{array} $  |      |        | 479  |        | 479  |        | ns   |
| SIp hold time (from $\overline{SCKp}^{\uparrow}$ ) Note 4                | tksi1  | $ \left  \begin{array}{l} 4.0 \; V \leq E V_{DD} \leq 5.5 \; V,  2.7 \; V \leq V_b \leq 4.0 \; V, \\ C_b = 30 \; pF, \; R_b = 1.4 \; k\Omega \end{array} \right. $   | 19   |        | 19   |        | 19   |        | ns   |
|  |        | $ 2.7 \text{ V} \leq \text{EV}_{DD} < 4.0 \text{ V}, \ 2.3 \text{ V} \leq \text{V}_b \leq 2.7 \text{ V}, \\ C_b = 30 \text{ pF}, \ R_b = 2.7 \text{ k}\Omega $   | 19   |        | 19   |        | 19   |        | ns   |
|  |        | $ 2.4~V \leq EV_{DD} < 3.3~V,~1.6~V \leq V_b \leq 2.0~V, \\ C_b = 30~pF,~R_b = 5.5~k\Omega $   | 19   |        | 19   |        | 19   |        | ns   |
|  |        | $ \begin{array}{ c c c c c } \hline 1.8 \ V \leq E \ V_{DD} < 3.3 \ V, \ 1.6 \ V \leq V_b \leq 2.0 \ V, \\ C_b = 30 \ pF, \ R_b = 5.5 \ k\Omega \end{array} $  |      |        | 19   |        | 19   |        | ns   |
| Delay time from $\overline{\text{SCKp}} \downarrow$ to SOp output Note 4 | tkso1  | $ \begin{aligned} 4.0 \ V \leq E V_{DD} \leq 5.5 \ V, \ 2.7 \ V \leq V_b \leq 4.0 \ V, \\ C_b = 30 \ pF, \ R_b = 1.4 \ k\Omega \end{aligned} $   |      | 100    |      | 100    |      | 100    | ns   |
|  |        | $ \label{eq:continuous}                                   $  |      | 195    |      | 195    |      | 195    | ns   |
|  |        | $ \label{eq:continuous}                                   $  |      | 483    |      | 483    |      | 483    | ns   |
|  |        | $ \begin{array}{ l c c c c } \hline 1.8 \ V \leq E \ V_{DD} < 3.3 \ V, \ 1.6 \ V \leq V_b \leq 2.0 \ V, \\ C_b = 30 \ pF, \ R_b = 5.5 \ k\Omega \end{array} $  |      |        |      | 483    |      | 483    | ns   |
| SIp setup time (to $\overline{SCKp}\downarrow$ ) Note 5                  | tsıĸ1  | $ \left  \begin{array}{l} 4.0 \; V \leq E  V_{DD} \leq 5.5 \; V,  2.7 \; V \leq V_b \leq 4.0 \; V, \\ C_b = 30 \; pF, \; R_b = 1.4 \; k\Omega \end{array} \right. $  | 44   |        | 110  |        | 110  |        | ns   |
|  |        | $ \begin{cases} 2.7 \; \text{V} \leq \text{EV}_{\text{DD}} < 4.0 \; \text{V},  2.3 \; \text{V} \leq \text{V}_{\text{b}} \leq 2.7 \; \text{V}, \\ C_{\text{b}} = 30 \; \text{pF}, \; R_{\text{b}} = 2.7 \; \text{k}\Omega \end{cases} $ | 44   |        | 110  |        | 110  |        | ns   |
|  |        | $ \label{eq:continuous}                                   $  | 110  |        | 110  |        | 110  |        | ns   |
|  |        | $ \begin{array}{ c c c c c } \hline 1.8 \ V \leq E \ V_{DD} < 3.3 \ V, \ 1.6 \ V \leq V_b \leq 2.0 \ V, \\ C_b = 30 \ pF, \ R_b = 5.5 \ k\Omega \end{array} $  |      |        | 110  |        | 110  |        | ns   |
| SIp hold time (from $\overline{SCKp} \downarrow$ ) Note 5                | tksi1  | $ \left  \begin{array}{l} 4.0 \; V \leq E V_{DD} \leq 5.5 \; V,  2.7 \; V \leq V_b \leq 4.0 \; V, \\ C_b = 30 \; pF, \; R_b = 1.4 \; k\Omega \end{array} \right. $   | 19   |        | 19   |        | 19   |        | ns   |
|  |        | $ \label{eq:continuous}                                   $  | 19   |        | 19   |        | 19   |        | ns   |
|  |        | $ 2.4~V \leq EV_{DD} < 4.0~V,~2.3~V \leq V_b \leq 2.7~V, \\ C_b = 30~pF,~R_b = 2.7~k\Omega $   | 19   |        | 19   |        | 19   |        | ns   |
|  |        | $ \begin{cases} 1.8 \ V \leq EV_{DD} < 3.3 \ V, \ 1.6 \ V \leq V_b \leq 2.0 \ V, \\ C_b = 30 \ pF, \ R_b = 5.5 \ k\Omega \end{cases} $   |      |        | 19   |        | 19   |        | ns   |
| Delay time from SCKp↑ to SOp output Note 5                               | tkso1  | $ \begin{cases} 4.0 \text{ V} \leq \text{EV}_{\text{DD}} \leq 5.5 \text{ V},  2.7 \text{ V} \leq \text{V}_{\text{b}} \leq 4.0 \text{ V}, \\ C_{\text{b}} = 30 \text{ pF},  R_{\text{b}} = 1.4 \text{ k}\Omega \end{cases} $            |      | 25     |      | 25     |      | 25     | ns   |
|  |        | $ \label{eq:continuous} \begin{array}{ c c c c } \hline 2.7 \ V \leq E \ V_{DD} < 4.0 \ V, \ 2.3 \ V \leq V_b \leq 2.7 \ V, \\ C_b = 30 \ pF, \ R_b = 2.7 \ k\Omega \end{array} $  |      | 25     |      | 25     |      | 25     | ns   |
|  |        | $ \begin{cases} 2.4 \; V \leq E V_{DD} < 3.3 \; V, \; 1.6 \; V \leq V_b \leq 2.0 \; V, \\ C_b = 30 \; pF, \; R_b = 5.5 \; k\Omega \end{cases} $  |      | 25     |      | 25     |      | 25     | ns   |
|  |        | $ \begin{array}{c} 1.8 \; V \leq EV_{DD} < 3.3 \; V,  1.6 \; V \leq V_b \leq 2.0 \; V, \\ C_b = 30 \; pF, \; R_b = 5.5 \; k\Omega \end{array} $  |      |        |      | 25     |      | 25     | ns   |

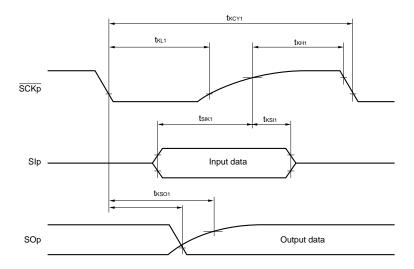
(Note, Caution and Remark are listed on the next page.)

#### CSI mode connection diagram (during communication at different potential)

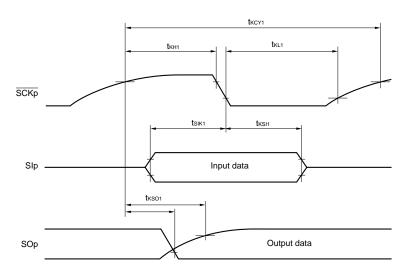


- <R> Notes 1. HS is condition of HS (high-speed main) mode.
- <R> 2. LS is condition of LS (low-speed main) mode.
- <R> 3. LV is condition of LV (low-voltage main) mode.
  - 4. When DAPmn = 0 and CKPmn = 0, or DAPmn = 1 and CKPmn = 1.
  - 5. When DAPmn = 0 and CKPmn = 1, or DAPmn = 1 and CKPmn = 0.
  - Cautions 1. Select the TTL input buffer for the SIp pin and the N-ch open drain output (VDD tolerance (32-pin to 52-pin products)/EDD tolerance (64-pin products)) mode for the SOp pin and SCKp pin by using port input mode register g (PIMg) and port output mode register g (POMg).
    - 2. Use it with EVDD ≥ Vb.
  - **Remarks 1.** R<sub>b</sub>[ $\Omega$ ]:Communication line ( $\overline{SCKp}$ , SOp) pull-up resistance, C<sub>b</sub>[F]: Communication line ( $\overline{SCKp}$ , SOp) load capacitance, V<sub>b</sub>[V]: Communication line voltage
    - 2. p: CSI number (p = 00, 01), m: Unit number (m = 0), n: Channel number (n = 0, 1), g: PIM and POM number (g = 1)

CSI mode serial transfer timing (master mode) (during communication at different potential)
(When DAPmn = 0 and CKPmn = 0, or DAPmn = 1 and CKPmn = 1.)



CSI mode serial transfer timing (master mode) (during communication at different potential)
(When DAPmn = 0 and CKPmn = 1, or DAPmn = 1 and CKPmn = 0.)



Caution Select the TTL input buffer for the SIp pin and the N-ch open drain output (VDD tolerance (32-pin to 52-pin products)/EVDD tolerance (64-pin products)) mode for the SOp pin and SCKp pin by using port input mode register g (PIMg) and port output mode register g (POMg).

**Remark** p: CSI number (p = 00, 01), m: Unit number (m = 0), n: Channel number (n = 0, 1), g: PIM and POM number (g = 1)

# (7) Communication at different potential (1.8 V, 2.5 V, 3 V) (CSI mode) (slave mode, SCKp... external clock input)

 $(T_A = -40 \text{ to } +85^{\circ}\text{C}, 1.8 \text{ V} \le \text{EV}_{DD} = \text{V}_{DD} \le 5.5 \text{ V}, \text{Vss} = \text{EV}_{SS} = 0 \text{ V})$ 

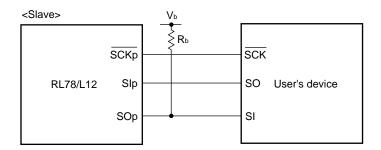
<R>

| Parameter                                      | Symbol            | Con   | ditions                              | HS              | Note 1          | LS              | Note 2          | LV              | Note 3          | Uni |
|--|-------------------|---|--------------------------------------|-----------------|-----------------|-----------------|-----------------|-----------------|-----------------|-----|
|  |                   |   |                                      | MIN.            | MAX.            | MIN.            | MAX.            | MIN.            | MAX.            |     |
| SCKp cycle time Note 4                         | tkcy2             | $4.0 \text{ V} \le \text{EV}_{DD} \le 5.5 \text{ V},$   | 20 MHz < fмcк ≤ 24 MHz               | 12/fмск         |                 |                 |                 |                 |                 | ns  |
|  |                   | $2.7 \text{ V} \le V_b \le 4.0 \text{ V}$   | 8 MHz < fмcк ≤ 20 MHz                | 10/fмск         |                 |                 |                 |                 |                 | ns  |
|  |                   |   | 4 MHz < fмck ≤ 8 MHz                 | 8/fмск          |                 | 16/fмск         |                 |                 |                 | ns  |
|  |                   |   | fмcк ≤ 4 MHz                         | 6/ƒмск          |                 | 10/fмск         |                 | 10/fмск         |                 | ns  |
|  |                   | $2.7 \text{ V} \le \text{EV}_{DD} < 4.0 \text{ V},$   | 20 MHz < fмcк ≤ 24 MHz               | <b>16/f</b> мск |                 |                 |                 |                 |                 | ns  |
|  |                   | $2.3 \text{ V} \le V_b \le 2.7 \text{ V}$   | 16 MHz < fмcк ≤ 20 MHz               | <b>14/f</b> мск |                 |                 |                 |                 |                 | ns  |
|  |                   |   | 8 MHz < fмcк ≤ 16 MHz                | <b>12/f</b> мск |                 |                 |                 |                 |                 | ns  |
|  |                   |   | 4 MHz < fMCK ≤ 8 MHz                 | 8/fмск          |                 | 16/fмск         |                 |                 |                 | ns  |
|  |                   |   | f <sub>MCK</sub> ≤4 MHz              | 6/fмск          |                 | 10/fмск         |                 | 10/fмск         |                 | ns  |
|  |                   | $2.4 \text{ V} \le \text{EV}_{DD} < 3.3 \text{ V},$   | 20 MHz < fмcк ≤ 24 MHz               | 36/fмск         |                 |                 |                 |                 |                 | ns  |
|  |                   | $1.6~V \leq V_b \leq 2.0~V^{\text{Note 5}}$   | 16 MHz < fмcк ≤ 20 MHz               | 32/fмск         |                 |                 |                 |                 |                 | ns  |
|  |                   |   | 8 MHz < fмcк ≤ 16 MHz                | 26/fмск         |                 |                 |                 |                 |                 | ns  |
|  |                   |   | 4 MHz < fmck ≤ 8 MHz                 | 16/fмск         |                 | <b>16/f</b> мск |                 |                 |                 | ns  |
|  |                   |   | fmck ≤ 4 MHz                         | 10/fмск         |                 | 10/fмск         |                 | 10/fмск         |                 | ns  |
|  |                   | $1.8 \text{ V} \le \text{EV}_{DD} < 3.3 \text{ V},$   | 4 MHz < fMCK ≤ 8 MHz                 |                 |                 | 16/fмск         |                 |                 |                 | ns  |
|  |                   | $1.6 \text{ V} \le V_b \le 2.0 \text{ V}^{\text{Note 5}}$   | f <sub>MCK</sub> ≤ 4 MHz             |                 |                 | 10/fмск         |                 | 10/fмск         |                 | ns  |
| SCKp high-/low-level<br>width Note 5           | tkH2,             | $4.0~V \leq EV_{DD} \leq 5.5~V,~2.7~V \leq V_b \leq 4.0~V$  |                                      |                 |                 | tkcy2/2<br>- 50 |                 | tkcy2/2<br>- 50 |                 | ns  |
|  |                   | $2.7~\textrm{V} \leq \textrm{EV}_\textrm{DD} < 4.0~\textrm{V},~2.3~\textrm{V} \leq \textrm{V}_\textrm{b} \leq 2.7~\textrm{V}$ |                                      |                 |                 | tkcy2/2<br>- 50 |                 | tkcy2/2<br>- 50 |                 | ns  |
|  |                   | 2.4 V ≤ EV <sub>DD</sub> < 3.3  | $V, 1.6 \ V \le V_b \le 2.0 \ V$     | tkcy2/2<br>- 50 |                 | tkcy2/2<br>- 50 |                 | tkcy2/2<br>- 50 |                 | ns  |
|  |                   | 1.8 V ≤ EV <sub>DD</sub> < 3.3  | $V, 1.6 \ V \le V_b \le 2.0 \ V$     |                 |                 | tkcy2/2         |                 | tkcy2/2<br>- 50 |                 | ns  |
| SIp setup time<br>(to SCKp↑) Note 6            | tsık2             | 2.7 V ≤ EV <sub>DD</sub> < 5.5  | $V, 2.3 \ V \le V_b \le 4.0 \ V$     | 1/fмск +<br>20  |                 | 1/fмск+<br>30   |                 | 1/fмск +<br>30  |                 | ns  |
| , ,  |                   | 2.4 V ≤ EV <sub>DD</sub> < 3.3  | $V, 1.6 \ V \le V_b \le 2.0 \ V$     | 1/fмск +<br>30  |                 | 1/fмск +<br>30  |                 | 1/fмск +<br>30  |                 | ns  |
|  |                   | 1.8 V ≤ EV <sub>DD</sub> < 3.3  | $V, 1.6 \ V \le V_b \le 2.0 \ V$     |                 |                 | 1/fmck +        |                 | 1/fмcк + 30     |                 | ns  |
| SIp hold time<br>(from SCKp↑) Note 7           | t <sub>KSI2</sub> | 2.7 V ≤ EV <sub>DD</sub> < 5.5  | $V, 2.3 \ V \le V_b \le 4.0 \ V$     | 1/fмск +        |                 | 1/fмск+         |                 | 1/fmck +        |                 | ns  |
| (nom corp /)                                   |                   | 2.4 V ≤ EV <sub>DD</sub> < 3.3  | $V, 1.6 \ V \le V_b \le 2.0 \ V$     | 1/fмск +        |                 | 1/fмcк+         |                 | 1/fмcк +        |                 | ns  |
|  |                   | 1.8 V ≤ EV <sub>DD</sub> < 3.3  | $V, 1.6 \ V \le V_b \le 2.0 \ V$     |                 |                 | 1/fмск+         |                 | 1/fмск + 31     |                 | ns  |
| Delay time from SCKp↓ to SOp output Notes 5, 8 | tkso2             | $4.0 \text{ V} \le \text{EV}_{DD} \le 5.5$<br>$C_b = 30 \text{ pF}, R_b = 1.4$  | $V, 2.7 V \le V_b \le 4.0 V,$ 4 kΩ   |                 | 2/fмск<br>+ 120 | ÷.              | 2/fмск<br>+ 573 | - <del></del> - | 2/fмск<br>+ 573 | ns  |
| 5 Sop output                                   |                   | $2.7 \text{ V} \le \text{EV}_{DD} < 4.0$<br>C <sub>b</sub> = 30 pF, R <sub>b</sub> = 2.                                       | $V, 2.3 V \le V_b \le 2.7 V,$ $7 kΩ$ |                 | 2/fмск<br>+ 214 |                 | 2/fмск<br>+ 573 |                 | 2/fмск<br>+ 573 | ns  |
|  |                   | -   | $V, 1.6 V \le V_b \le 2.0 V,$        |                 | 2/fмск<br>+ 573 |                 | 2/fмск<br>+ 573 |                 | 2/fмск<br>+ 573 | ns  |
|  |                   | -   | $V, 1.6 V \le V_b \le 2.0 V,$        |                 |                 |                 | 2/fмск<br>+ 573 |                 | 2/fмск<br>+ 573 | ns  |

(Note, Caution and Remark are listed on the next page.)

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#### CSI mode connection diagram (during communication at different potential)



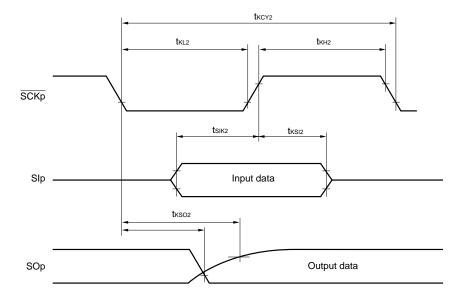
- Notes 1. HS is condition of HS (high-speed main) mode. <R>
- 2. LS is condition of LS (low-speed main) mode. <R>
  - 3. LV is condition of LV (low-voltage main) mode.
  - 4. Transfer rate in the SNOOZE mode: MAX. 1 Mbps
  - **5.** Use it with  $EV_{DD} \ge V_b$ .
  - 6. When DAPmn = 0 and CKPmn = 0, or DAPmn = 1 and CKPmn = 1. The SIp setup time becomes "to SCKp↓" when DAPmn = 0 and CKPmn = 1, or DAPmn = 1 and CKPmn = 0.
  - 7. When DAPmn = 0 and CKPmn = 0, or DAPmn = 1 and CKPmn = 1. The SIp hold time becomes "from SCKp↓" when DAPmn = 0 and CKPmn = 1, or DAPmn = 1 and CKPmn = 0.
  - 8. When DAPmn = 0 and CKPmn = 0, or DAPmn = 1 and CKPmn = 1. The delay time to SOp output becomes "from  $\overline{SCKp}$ \" when DAPmn = 0 and CKPmn = 1, or DAPmn = 1 and CKPmn = 0.

Caution Select the TTL input buffer for the SIp pin and SCKp pin and the N-ch open drain output (VDD tolerance (32-pin to 52-pin products)/EDD tolerance (64-pin products)) mode for the SOp pin by using port input mode register g (PIMg) and port output mode register g (POMg).

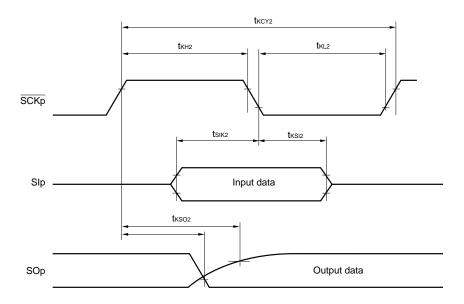
- Remarks 1. R<sub>b</sub>[Ω]:Communication line (SOp) pull-up resistance, C<sub>b</sub>[F]: Communication line (SOp) load capacitance, Vb[V]: Communication line voltage
  - 2. p: CSI number (p = 00, 01), m: Unit number (m = 0), n: Channel number (n = 0, 1), g: PIM and POM number (g = 1)
  - 3. fmck: Serial array unit operation clock frequency (Operation clock to be set by the CKSmn bit of serial mode register mn (SMRmn). m: Unit number, n: Channel number (mn = 00, 01))



CSI mode serial transfer timing (slave mode) (during communication at different potential)
(When DAPmn = 0 and CKPmn = 0, or DAPmn = 1 and CKPmn = 1.)



CSI mode serial transfer timing (slave mode) (during communication at different potential)
(When DAPmn = 0 and CKPmn = 1, or DAPmn = 1 and CKPmn = 0.)



Caution Select the TTL input buffer for the SIp pin and SCKp pin and the N-ch open drain output (VDD tolerance (32-pin to 52-pin products)/EVDD tolerance (64-pin products)) mode for the SOp pin by using port input mode register g (PIMg) and port output mode register g (POMg).

**Remark** p: CSI number (p = 00, 01), m: Unit number (m = 0), n: Channel number (n = 0, 1), g: PIM and POM number (g = 1)

# 2.5.2 Serial interface IICA

 $(T_A = -40 \text{ to } +85^{\circ}\text{C}, 1.6 \text{ V} \le \text{EV}_{DD} = \text{V}_{DD} \le 5.5 \text{ V}, \text{Vss} = \text{EV}_{SS} = 0 \text{ V})$ 

(1/2)

| (T <sub>A</sub> = -40 to +85°C, 1.6 V ≤ EV <sub>D</sub> |              |   |      | Standard Mode Note 1 |      |        |      |        |      |  |  |
|---|--------------|---|------|----------------------|------|--------|------|--------|------|--|--|
| Parameter   | Symbol       | Conditions  |      |                      |      |        |      | Note 4 | Unit |  |  |
|   |              |   |      | Note 2               |      | Note 3 |      | 1      |      |  |  |
|   |              |   | MIN. | MAX.                 | MIN. | MIN.   | MAX. | MIN.   |      |  |  |
| SCLA0 clock frequency                                   | fscL         | $2.7 \text{ V} \leq \text{EV}_{\text{DD}} \leq 5.5 \text{ V}$ | 0    | 100                  | 0    | 100    | 0    | 100    | kHz  |  |  |
|   |              | $2.4 \text{ V} \leq \text{EV}_{\text{DD}} \leq 5.5 \text{ V}$ | 0    | 100                  | 0    | 100    | 0    | 100    |      |  |  |
|   |              | $1.8 \text{ V} \leq \text{EV}_{DD} \leq 5.5 \text{ V}$        |      |                      | 0    | 100    | 0    | 100    |      |  |  |
|   |              | $1.6 \text{ V} \le \text{EV}_{\text{DD}} \le 5.5 \text{ V}$   |      |                      |      |        | 0    | 100    |      |  |  |
| Setup time of restart conditionNote 5                   | tsu:sta      | $2.7 \text{ V} \le \text{EV}_{\text{DD}} \le 5.5 \text{ V}$   | 4.7  |                      | 4.7  |        | 4.7  |        | μS   |  |  |
|   |              | $2.4 \text{ V} \le \text{EV}_{DD} \le 5.5 \text{ V}$          | 4.7  |                      | 4.7  |        | 4.7  |        |      |  |  |
|   |              | 1.8 V ≤ EV <sub>DD</sub> ≤ 5.5 V                              |      |                      | 4.7  |        | 4.7  |        |      |  |  |
|   |              | $1.6 \text{ V} \leq \text{EV}_{\text{DD}} \leq 5.5 \text{ V}$ |      |                      |      |        | 4.7  |        |      |  |  |
| Hold time   | thd:STA      | $2.7~\text{V} \leq \text{EV}_{\text{DD}} \leq 5.5~\text{V}$   | 4.0  |                      | 4.0  |        | 4.0  |        | μS   |  |  |
|   |              | $2.4~V \leq EV_{DD} \leq 5.5~V$                               | 4.0  |                      | 4.0  |        | 4.0  |        |      |  |  |
|   |              | $1.8~V \leq EV_{DD} \leq 5.5~V$                               |      |                      | 4.0  |        | 4.0  |        |      |  |  |
|   |              | $1.6 \text{ V} \leq \text{EV}_{DD} \leq 5.5 \text{ V}$        |      |                      |      |        | 4.0  |        |      |  |  |
| Hold time when SCLA0 = "L"                              | tLOW         | $2.7 \text{ V} \le \text{EV}_{DD} \le 5.5 \text{ V}$          | 4.7  |                      | 4.7  |        | 4.7  |        | μS   |  |  |
|   |              | $2.4 \text{ V} \leq \text{EV}_{DD} \leq 5.5 \text{ V}$        | 4.7  |                      | 4.7  |        | 4.7  |        |      |  |  |
|   |              | $1.8 \text{ V} \leq \text{EV}_{\text{DD}} \leq 5.5 \text{ V}$ |      |                      | 4.7  |        | 4.7  |        |      |  |  |
|   |              | $1.6~V \leq EV_{DD} \leq 5.5~V$                               |      |                      |      |        | 4.7  |        |      |  |  |
| Hold time when SCLA0 = "H"                              | tніgн        | $2.7~\text{V} \leq \text{EV}_{\text{DD}} \leq 5.5~\text{V}$   | 4.0  |                      | 4.0  |        | 4.0  |        | μS   |  |  |
|   |              | $2.4~V \leq EV_{DD} \leq 5.5~V$                               | 4.0  |                      | 4.0  |        | 4.0  |        |      |  |  |
|   |              | $1.8~V \leq EV_{DD} \leq 5.5~V$                               |      |                      | 4.0  |        | 4.0  |        |      |  |  |
|   |              | $1.6~V \le EV_{DD} \le 5.5~V$                                 |      |                      |      |        | 4.0  |        |      |  |  |
| Data setup time (reception)                             | tsu:dat      | $2.7 \text{ V} \le \text{EV}_{\text{DD}} \le 5.5 \text{ V}$   | 250  |                      | 250  |        | 250  |        | ns   |  |  |
|   |              | $2.4~V \leq EV_{DD} \leq 5.5~V$                               | 250  |                      | 250  |        | 250  |        |      |  |  |
|   |              | $1.8~V \leq EV_{DD} \leq 5.5~V$                               |      |                      | 250  |        | 250  |        |      |  |  |
|   |              | 1.6 V ≤ EV <sub>DD</sub> ≤ 5.5 V                              |      |                      |      |        | 250  |        | Ì    |  |  |
| Data hold time (transmission) <sup>Note 6</sup>         | thd:dat      | $2.7~\text{V} \leq \text{EV}_{\text{DD}} \leq 5.5~\text{V}$   | 0    | 3.45                 | 0    | 3.45   | 0    | 3.45   | μS   |  |  |
|   |              | $2.4 \text{ V} \le \text{EV}_{\text{DD}} \le 5.5 \text{ V}$   | 0    | 3.45                 | 0    | 3.45   | 0    | 3.45   |      |  |  |
|   |              | 1.8 V ≤ EV <sub>DD</sub> ≤ 5.5 V                              |      |                      | 0    | 3.45   | 0    | 3.45   |      |  |  |
|   |              | 1.6 V ≤ EV <sub>DD</sub> ≤ 5.5 V                              |      |                      |      |        | 0    | 3.45   |      |  |  |
| Setup time of stop condition                            | tsu:sto      | $2.7 \text{ V} \le \text{EV}_{DD} \le 5.5 \text{ V}$          | 4.0  |                      | 4.0  |        | 4.0  |        | μS   |  |  |
|   |              | $2.4 \text{ V} \le \text{EV}_{DD} \le 5.5 \text{ V}$          | 4.0  |                      | 4.0  |        | 4.0  |        |      |  |  |
|   |              | 1.8 V ≤ EV <sub>DD</sub> ≤ 5.5 V                              |      |                      | 4.0  |        | 4.0  |        |      |  |  |
|   |              | 1.6 V ≤ EV <sub>DD</sub> ≤ 5.5 V                              |      |                      |      |        | 4.0  |        |      |  |  |
| Bus-free time   | <b>t</b> BUF | 2.7 V ≤ EV <sub>DD</sub> ≤ 5.5 V                              | 4.7  |                      | 4.7  |        | 4.7  |        | μS   |  |  |
|   |              | 2.4 V ≤ EV <sub>DD</sub> ≤ 5.5 V                              | 4.7  |                      | 4.7  |        | 4.7  |        | ,    |  |  |
|   |              | $1.8 \text{ V} \le \text{EV}_{DD} \le 5.5 \text{ V}$          |      |                      | 4.7  |        | 4.7  |        |      |  |  |
|   |              | $1.6 \text{ V} \le \text{EV}_{DD} \le 5.5 \text{ V}$          |      |                      |      |        | 4.7  |        | 1    |  |  |

(Note and Remark are listed on the next page.)

| Parameter             | Symbol       | Conditions  |      |        | Fast M | ode Note 7 |      |        |      | ode Plus | Unit |
|-----------------------|--------------|---|------|--------|--------|------------|------|--------|------|----------|------|
|                       |              |   | HS   | Note 2 | LS     | Note 3     | LV   | Note 4 | HS   | Note 2   |      |
|                       |              |   | MIN. | MAX.   | MIN.   | MIN.       | MAX. | MIN.   | MAX. | MIN.     |      |
| SCLA0 clock frequency | fscL         | $2.7~\text{V} \leq \text{EV}_{\text{DD}} \leq 5.5~\text{V}$   | 0    | 400    | 0      | 400        | 0    | 400    | 0    | 1000     | kHz  |
|                       |              | $2.4~V \leq EV_{DD} \leq 5.5~V$                               | 0    | 400    | 0      | 400        | 0    | 400    |      |          |      |
|                       |              | $1.8 \text{ V} \leq \text{EV}_{\text{DD}} \leq 5.5 \text{ V}$ |      |        | 0      | 400        | 0    | 400    |      |          |      |
| Setup time of restart | tsu:sta      | $2.7~\text{V} \leq \text{EV}_{\text{DD}} \leq 5.5~\text{V}$   | 0.6  |        | 0.6    |            | 0.6  |        | 0.26 |          | μS   |
| condition Note 5      |              | $2.4~V \leq EV_{DD} \leq 5.5~V$                               | 0.6  |        | 0.6    |            | 0.6  |        |      |          |      |
|                       |              | $1.8 \text{ V} \leq \text{EV}_{\text{DD}} \leq 5.5 \text{ V}$ |      |        | 0.6    |            | 0.6  |        |      |          |      |
| Hold time             | thd:STA      | $2.7~\text{V} \leq \text{EV}_{\text{DD}} \leq 5.5~\text{V}$   | 0.6  |        | 0.6    |            | 0.6  |        | 0.26 |          | μS   |
|                       |              | $2.4~V \leq EV_{DD} \leq 5.5~V$                               | 0.6  |        | 0.6    |            | 0.6  |        |      |          |      |
|                       |              | 1.8 V ≤ EV <sub>DD</sub> ≤ 5.5 V                              |      |        | 0.6    |            | 0.6  |        |      |          |      |
| Hold time when SCLA0  | tLOW         | $2.7~\text{V} \leq \text{EV}_{\text{DD}} \leq 5.5~\text{V}$   | 1.3  |        | 1.3    |            | 1.3  |        | 0.5  |          | μS   |
| = "L"                 |              | $2.4~V \leq EV_{DD} \leq 5.5~V$                               | 1.3  |        | 1.3    |            | 1.3  |        |      |          |      |
|                       |              | 1.8 V ≤ EV <sub>DD</sub> ≤ 5.5 V                              |      |        | 1.3    |            | 1.3  |        |      |          |      |
| Hold time when SCLA0  | tніgн        | $2.7~\text{V} \leq \text{EV}_{\text{DD}} \leq 5.5~\text{V}$   | 0.6  |        | 0.6    |            | 0.6  |        | 0.26 |          | μS   |
| = "H"                 |              | $2.4~V \leq EV_{DD} \leq 5.5~V$                               | 0.6  |        | 0.6    |            | 0.6  |        |      |          |      |
|                       |              | 1.8 V ≤ EV <sub>DD</sub> ≤ 5.5 V                              |      |        | 0.6    |            | 0.6  |        |      |          |      |
| Data setup time       | tsu:dat      | $2.7~\text{V} \leq \text{EV}_{\text{DD}} \leq 5.5~\text{V}$   | 100  |        | 100    |            | 100  |        | 50   |          | ns   |
| (reception)           |              | $2.4~V \leq EV_{DD} \leq 5.5~V$                               | 100  |        | 100    |            | 100  |        |      |          |      |
|                       |              | 1.8 V ≤ EV <sub>DD</sub> ≤ 5.5 V                              |      |        | 100    |            | 100  |        |      |          |      |
| Data hold time        | thd:dat      | $2.7~\text{V} \leq \text{EV}_{\text{DD}} \leq 5.5~\text{V}$   | 0    | 0.9    | 0      | 0.9        | 0    | 0.9    | 0    | 450      | μS   |
| (transmission)Note 6  |              | $2.4~V \leq EV_{DD} \leq 5.5~V$                               | 0    | 0.9    | 0      | 0.9        | 0    | 0.9    |      |          |      |
|                       |              | 1.8 V ≤ EV <sub>DD</sub> ≤ 5.5 V                              |      |        | 0      | 0.9        | 0    | 0.9    |      |          |      |
| Setup time of stop    | tsu:sto      | $2.7~\text{V} \leq \text{EV}_{\text{DD}} \leq 5.5~\text{V}$   | 0.6  |        | 0.6    |            | 0.6  |        | 0.26 |          | μS   |
| condition             |              | $2.4~\text{V} \leq \text{EV}_{\text{DD}} \leq 5.5~\text{V}$   | 0.6  |        | 0.6    |            | 0.6  |        |      |          |      |
|                       |              | 1.8 V ≤ EV <sub>DD</sub> ≤ 5.5 V                              |      |        | 0.6    |            | 0.6  |        |      |          |      |
| Bus-free time         | <b>t</b> BUF | $2.7~\text{V} \leq \text{EV}_{\text{DD}} \leq 5.5~\text{V}$   | 1.3  |        | 1.3    |            | 1.3  |        | 0.5  |          | μS   |
|                       |              | $2.4~V \leq EV_{DD} \leq 5.5~V$                               | 1.3  |        | 1.3    |            | 1.3  |        |      |          |      |
|                       |              | 1.8 V ≤ EV <sub>DD</sub> ≤ 5.5 V                              |      |        | 1.3    |            | 1.3  |        |      |          |      |

- In normal mode, use it with fcLK  $\geq$  1 MHz, 1.6 V  $\leq$  EVDD  $\leq$  5.5 V. <R>
- <R> 2. HS is condition of HS (high-speed main) mode.
- 3. LS is condition of LS (low-speed main) mode. <R>
  - 4. LV is condition of LV (low-voltage main) mode.
  - The first clock pulse is generated after this period when the start/restart condition is detected.
  - The maximum value (MAX.) of thd:DAT is during normal transfer and a wait state is inserted in the ACK (acknowledge) timing.
  - 7. In fast mode, use it with fcLK  $\geq$  3.5 MHz, 1.8 V  $\leq$  EVDD  $\leq$  5.5 V.
- <R> In fast mode plus, use it with fcLk  $\geq$  10 MHz, 2.7 V  $\leq$  EVDD  $\leq$  5.5 V.

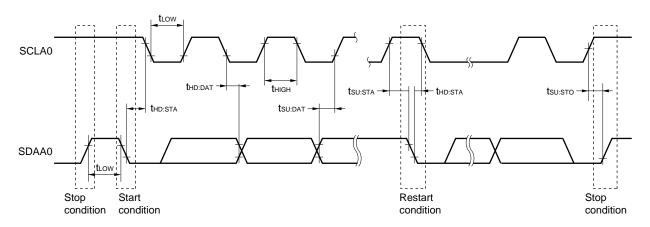
Remark The maximum value of Cb (communication line capacitance) and the value of Rb (communication line pull-up resistor) at that time in each mode are as follows.

> Standard mode:  $C_b = 400 \text{ pF}$ ,  $R_b = 2.7 \text{ k}\Omega$  $C_b = 320 \text{ pF}, R_b = 1.1 \text{ k}\Omega$ Fast mode: Fast mode plus:  $C_b = 120 \text{ pF}$ ,  $R_b = 1.1 \text{ k}\Omega$

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# IICA serial transfer timing



# 2.5.3 On-chip debug (UART)

 $(T_A = -40 \text{ to } +85^{\circ}\text{C}, 1.8 \text{ V} \le \text{EV}_{DD} = \text{V}_{DD} \le 5.5 \text{ V}, \text{V}_{SS} = \text{EV}_{SS} = 0 \text{ V})$ 

| Parameter     | Symbol | Conditions | MIN.    | TYP. | MAX. | Unit |
|---------------|--------|------------|---------|------|------|------|
| Transfer rate |        |            | 115.2 k |      | 1 M  | bps  |

# 2.6 Analog Characteristics

### 2.6.1 A/D converter characteristics

(1) When AVREF (+) = AVREFP/ANIO (ADREFP1 = 0, ADREFP0 = 1), AVREF (-) = AVREFM/ANI1 (ADREFM = 1), target ANI pin : ANI16 to ANI23 (supply ANI pin to EVDD)

(TA = -40 to +85°C, 1.6 V  $\leq$  EVDD = VDD  $\leq$  5.5 V, Vss = EVss = 0 V, Reference voltage (+) = AVREFP, Reference voltage (-) = AVREFM)

| Parameter                              | Symbol            | Cone   | ditions  | MIN.   | TYP. | MAX.               | Unit     |
|--|-------------------|--|--|--------|------|--------------------|----------|
| Resolution                             | Res               |  |  | 8      |      | 10                 | bit      |
| Overall error <sup>Note 1</sup>        | AINL              | 10-bit resolution  | $1.8~V \leq V_{DD} \leq 5.5~V$                     |        | 1.2  | ±5.0               | LSB      |
|  |                   | AVREFP = VDD   | $1.6~V \leq V_{DD} \leq 5.5~V$                     |        | 1.2  | ±8.5               | LSB      |
| Conversion time                        | tconv             | 10-bit resolution  | $3.6~\text{V} \leq \text{Vdd} \leq 5.5~\text{V}$   | 2.125  |      | 39                 | μS       |
|  |                   | AVREFP = VDD   | $2.7~\text{V} \leq \text{Vdd} \leq 5.5~\text{V}$   | 3.1875 |      | 39                 | μS       |
|  |                   |  | $1.8~V \leq V_{DD} \leq 5.5~V$                     | 17     |      | 39                 | μS       |
|  |                   |  | $1.6~V \leq V_{DD} \leq 5.5~V$                     | 57     |      | 95                 | μS       |
| Zero-scale error <sup>Notes 1, 2</sup> | EZS               | 10-bit resolution  | $1.8~V \leq V_{DD} \leq 5.5~V$                     |        |      | ±0.35              | %FSR     |
|  |                   | AVREFP = VDD   | $1.6~V \leq V_{DD} \leq 5.5~V$                     |        |      | ±0.60              | %FSR     |
| Full-scale error <sup>Notes 1, 2</sup> | EFS               | 10-bit resolution  | $1.8~V \leq V_{DD} \leq 5.5~V$                     |        |      | ±0.35              | %FSR     |
|  |                   | AVREFP = VDD   | $1.6~\text{V} \leq \text{Vdd} \leq 5.5~\text{V}$   |        |      | ±0.60              | %FSR     |
| Integral linearity errorNote 1         | ILE               | 10-bit resolution  | $1.8~V \leq V_{DD} \leq 5.5~V$                     |        |      | ±3.5               | LSB      |
|  |                   | AVREFP = VDD   | $1.6~\text{V} \leq \text{Vdd} \leq 5.5~\text{V}$   |        |      | ±6.0               | LSB      |
| Differential linearity error Note 1    | DLE               | 10-bit resolution  | $1.8~V \leq V_{DD} \leq 5.5~V$                     |        |      | ±2.0               | LSB      |
|  |                   | AVREFP = VDD   | $1.6 \text{ V} \leq \text{Vdd} \leq 5.5 \text{ V}$ |        |      | ±2.5               | LSB      |
| Reference voltage (+)                  | AVREFP            |  |  | 1.6    |      | V <sub>DD</sub>    | <b>V</b> |
| Analog input voltage                   | Vain              |  |  | 0      |      | AVREFP<br>and EVDD | V        |
|  | V <sub>B</sub> GR | Select internal reference 2.4 V $\leq$ VDD $\leq$ 5.5 V, H mode only | • .  | 1.38   | 1.45 | 1.5                | V        |

**Notes 1.** Excludes quantization error ( $\pm 1/2$  LSB).

2. This value is indicated as a ratio (%FSR) to the full-scale value.

(2) When AVREF (+) = VDD (ADREFP1 = 0, ADREFP0 = 0), AVREF (-) = Vss (ADREFM = 0), target ANI pin : ANIO, ANI1, ANI16 to ANI23

 $(T_A = -40 \text{ to } +85^{\circ}\text{C}, 1.6 \text{ V} \leq \text{EV}_{DD} = \text{V}_{DD} \leq 5.5 \text{ V}, \text{V}_{SS} = \text{EV}_{SS} = 0 \text{ V}, \text{Reference voltage (+)} = \text{V}_{DD}, \text{Reference voltage (-)} = \text{V}_{SS})$ 

| Parameter                                  | Symbol | Coi   | nditions  | MIN.   | TYP. | MAX.             | Unit |
|--|--------|---|---|--------|------|------------------|------|
| Resolution                                 | Res    |   |   | 8      |      | 10               | bit  |
| Overall error <sup>Note 1</sup>            | AINL   | 10-bit resolution   | 1.8 V ≤ VDD ≤ 5.5 V                               |        | 1.2  | ±7.0             | LSB  |
|  |        |   | $1.6~V \leq V_{DD} \leq 5.5~V$                    |        | 1.2  | ±10.5            | LSB  |
| Conversion time                            | tconv  | 10-bit resolution   | $3.6~V \leq V_{DD} \leq 5.5~V$                    | 2.125  |      | 39               | μS   |
|  |        |   | $2.7~V \leq V_{DD} \leq 5.5~V$                    | 3.1875 |      | 39               | μS   |
|  |        |   | $1.8~V \leq V_{DD} \leq 5.5~V$                    | 17     |      | 39               | μS   |
|  |        |   | $1.6~V \leq V_{DD} \leq 5.5~V$                    | 57     |      | 95               | μS   |
| Zero-scale error <sup>Notes 1, 2</sup>     | EZS    | 10-bit resolution   | 10-bit resolution 1.8 V ≤ V <sub>DD</sub> ≤ 5.5 V |        |      | ±0.60            | %FSR |
|  |        |   | $1.6~V \leq V_{DD} \leq 5.5~V$                    |        |      | ±0.85            | %FSR |
| Full-scale error <sup>Notes 1, 2</sup>     | EFS    | 10-bit resolution   | 10-bit resolution 1.8 V ≤ V <sub>DD</sub> ≤ 5.5 V |        |      | ±0.60            | %FSR |
|  |        |   | $1.6~V \leq V_{DD} \leq 5.5~V$                    |        |      | ±0.85            | %FSR |
| Integral linearity error <sup>Note 1</sup> | ILE    | 10-bit resolution   | $1.8~V \leq V_{DD} \leq 5.5~V$                    |        |      | ±4.0             | LSB  |
|  |        |   | $1.6~V \leq V_{DD} \leq 5.5~V$                    |        |      | ±6.5             | LSB  |
| Differential linearity error Note 1        | DLE    | 10-bit resolution   | $1.8~V \leq V_{DD} \leq 5.5~V$                    |        |      | ±2.0             | LSB  |
|  |        |   | $1.6~V \leq V_{DD} \leq 5.5~V$                    |        |      | ±2.5             | LSB  |
| Analog input voltage                       | Vain   | ANIO, ANI1  |   | 0      |      | V <sub>DD</sub>  | V    |
|  |        | ANI16 to ANI23  Select internal reference voltage output, 2.4 V ≤ VDD ≤ 5.5 V, HS (high-speed main) mode only |   | 0      |      | EV <sub>DD</sub> | V    |
|  | VBGR   |   |   | 1.38   | 1.45 | 1.5              | V    |

Notes 1. Excludes quantization error (±1/2 LSB).

2. This value is indicated as a ratio (%FSR) to the full-scale value.

(3) When AVREF (+) = Internal reference voltage (ADREFP1 = 1, ADREFP0 = 0), AVREF (-) = AVREFM/ANI1 (ADREFM = 1), target ANI pin : ANI0, ANI16 to ANI23

(TA = -40 to +85°C, 2.4 V  $\leq$  VDD = EVDD  $\leq$  5.5 V, Vss = EVss = 0 V, Reference voltage (+) = VBGR, Reference voltage (-) = AVREFM = 0 V) (HS (high-speed main) mode only)

| Parameter                                  | Symbol           | Cor              | Conditions                     |      |      | MAX.             | Unit |
|--|------------------|------------------|--------------------------------|------|------|------------------|------|
| Resolution                                 | Res              |                  | 8                              |      |      | bit              |      |
| Conversion time                            | tconv            | 8-bit resolution | $2.4~V \leq V_{DD} \leq 5.5~V$ | 17   |      | 39               | μs   |
| Zero-scale error <sup>Notes 1, 2</sup>     | EZS              | 8-bit resolution | $2.4~V \leq V_{DD} \leq 5.5~V$ |      |      | ±0.60            | %FSR |
| Integral linearity error <sup>Note 1</sup> | ILE              | 8-bit resolution | $2.4~V \leq V_{DD} \leq 5.5~V$ |      |      | ±2.0             | LSB  |
| Differential linearity error Note 1        | DLE              | 8-bit resolution | $2.4~V \leq V_{DD} \leq 5.5~V$ |      |      | ±1.0             | LSB  |
| Reference voltage (+)                      | V <sub>BGR</sub> |                  |                                | 1.38 | 1.45 | 1.5              | V    |
| Analog input voltage                       | Vain             |                  |                                | 0    |      | V <sub>BGR</sub> | V    |

Notes 1. Excludes quantization error (±1/2 LSB).

2. This value is indicated as a ratio (%FSR) to the full-scale value.

### 2.6.2 Temperature sensor/internal reference voltage characteristics

# (TA = -40 to +85°C, 2.4 V $\leq$ VDD = EVDD $\leq$ 5.5 V, Vss = EVss = 0 V) (HS (high-speed main) mode only)

| Parameter                         | Symbol              | Conditions   | MIN. | TYP. | MAX. | Unit  |
|-----------------------------------|---------------------|--|------|------|------|-------|
| Temperature sensor output voltage | V <sub>TMPS25</sub> | Setting ADS register = 80H, T <sub>A</sub> = +25°C |      | 1.05 |      | V     |
| Internal reference voltage        | VCONST              | Setting ADS register = 81H                         | 1.38 | 1.45 | 1.5  | V     |
| Temperature coefficient           | FVTMPS              | Temperature sensor that depends on the temperature |      | -3.6 |      | mV/°C |
| Operation stabilization wait time | tamp                |  | 5    |      |      | μS    |

# 2.6.3 POR circuit characteristics

# $(T_A = -40 \text{ to } +85^{\circ}\text{C}, \text{ Vss} = 0 \text{ V})$

| Parameter            | Symbol           | Conditions             | MIN. | TYP. | MAX. | Unit |
|----------------------|------------------|------------------------|------|------|------|------|
| Detection voltage    | V <sub>POR</sub> | Power supply rise time | 1.47 | 1.51 | 1.55 | V    |
|                      | V <sub>PDR</sub> | Power supply fall time | 1.46 | 1.50 | 1.54 | V    |
| Minimum pulse width  | T <sub>PW</sub>  |                        | 300  |      |      | μS   |
| Detection delay time |                  |                        |      |      | 350  | us   |

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# 2.6.4 LVD circuit characteristics

(Ta = -40 to +85°C, VPDR  $\leq$  EVDD = VDD  $\leq$  5.5 V, Vss = EVss = 0 V)

|             | Parameter            | Symbol              | Conditions             | MIN. | TYP. | MAX. | Unit     |
|-------------|----------------------|---------------------|------------------------|------|------|------|----------|
| Detection   | Supply voltage level | V <sub>LVD0</sub>   | Power supply rise time | 3.98 | 4.06 | 4.14 | >        |
| voltage     |                      |                     | Power supply fall time | 3.90 | 3.98 | 4.06 | V        |
|             |                      | V <sub>LVD1</sub>   | Power supply rise time | 3.68 | 3.75 | 3.82 | ٧        |
|             |                      |                     | Power supply fall time | 3.60 | 3.67 | 3.74 | >        |
|             |                      | V <sub>LVD2</sub>   | Power supply rise time | 3.07 | 3.13 | 3.19 | >        |
|             |                      |                     | Power supply fall time | 3.00 | 3.06 | 3.12 | ٧        |
|             |                      | V <sub>LVD3</sub>   | Power supply rise time | 2.96 | 3.02 | 3.08 | ٧        |
|             |                      |                     | Power supply fall time | 2.90 | 2.96 | 3.02 | ٧        |
|             |                      | V <sub>LVD4</sub>   | Power supply rise time | 2.86 | 2.92 | 2.97 | ٧        |
|             |                      |                     | Power supply fall time | 2.80 | 2.86 | 2.91 | >        |
|             |                      | V <sub>LVD5</sub>   | Power supply rise time | 2.76 | 2.81 | 2.87 | >        |
|             |                      |                     | Power supply fall time | 2.70 | 2.75 | 2.81 | >        |
|             |                      | V <sub>L</sub> VD6  | Power supply rise time | 2.66 | 2.71 | 2.76 | <b>V</b> |
|             |                      |                     | Power supply fall time | 2.60 | 2.65 | 2.70 | ٧        |
|             |                      | V <sub>L</sub> VD7  | Power supply rise time | 2.56 | 2.61 | 2.66 | ٧        |
|             |                      |                     | Power supply fall time | 2.50 | 2.55 | 2.60 | <b>V</b> |
|             |                      | V <sub>LVD8</sub>   | Power supply rise time | 2.45 | 2.50 | 2.55 | V        |
|             |                      |                     | Power supply fall time | 2.40 | 2.45 | 2.50 | ٧        |
|             |                      | V <sub>LVD9</sub>   | Power supply rise time | 2.05 | 2.09 | 2.13 | V        |
|             |                      |                     | Power supply fall time | 2.00 | 2.04 | 2.08 | V        |
|             |                      | V <sub>L</sub> VD10 | Power supply rise time | 1.94 | 1.98 | 2.02 | V        |
|             |                      |                     | Power supply fall time | 1.90 | 1.94 | 1.98 | V        |
|             |                      | V <sub>LVD11</sub>  | Power supply rise time | 1.84 | 1.88 | 1.91 | V        |
|             |                      |                     | Power supply fall time | 1.80 | 1.84 | 1.87 | V        |
|             |                      | V <sub>LVD12</sub>  | Power supply rise time | 1.74 | 1.77 | 1.81 | V        |
|             |                      |                     | Power supply fall time | 1.70 | 1.73 | 1.77 | V        |
|             |                      | V <sub>LVD13</sub>  | Power supply rise time | 1.64 | 1.67 | 1.70 | V        |
|             |                      |                     | Power supply fall time | 1.60 | 1.63 | 1.66 | V        |
| Minimum pu  | ulse width           | tuw                 |                        | 300  |      |      | μS       |
| Detection d | elay time            | <b>t</b> LD         |                        |      |      | 300  | μS       |

# **LVD Detection Voltage of Interrupt & Reset Mode**

 $(T_A = -40 \text{ to } +85^{\circ}\text{C}, V_{PDR} \le EV_{DD} = V_{DD} \le 5.5 \text{ V}, V_{SS} = EV_{SS} = 0 \text{ V})$ 

| Parameter           | Symbol              | Cor                         | ditions                      | MIN. | TYP. | MAX. | Unit |
|---------------------|---------------------|-----------------------------|------------------------------|------|------|------|------|
| Interrupt and reset | V <sub>LVD13</sub>  | VPOC2, VPOC1, VPOC0 = 0, 0, | O, falling reset voltage     | 1.60 | 1.63 | 1.66 | V    |
| mode                | V <sub>LVD12</sub>  | LVIS1, LVIS0 = 1, 0         | Rising release reset voltage | 1.74 | 1.77 | 1.81 | V    |
|                     |                     | (+0.1 V)                    | Falling interrupt voltage    | 1.70 | 1.73 | 1.77 | V    |
|                     | V <sub>LVD11</sub>  | LVIS1, LVIS0 = 0, 1         | Rising release reset voltage | 1.84 | 1.88 | 1.91 | V    |
|                     |                     | (+0.2 V)                    | Falling interrupt voltage    | 1.80 | 1.84 | 1.87 | ٧    |
|                     | V <sub>LVD4</sub>   | LVIS1, LVIS0 = 0, 0         | Rising release reset voltage | 2.86 | 2.92 | 2.97 | ٧    |
|                     |                     | (+1.2 V)                    | Falling interrupt voltage    | 2.80 | 2.86 | 2.91 | V    |
|                     | V <sub>LVD11</sub>  | VPOC2, VPOC1, VPOC0 = 0, 0, | 1, falling reset voltage     | 1.80 | 1.84 | 1.87 | ٧    |
|                     | V <sub>LVD10</sub>  | LVIS1, LVIS0 = 1, 0         | Rising release reset voltage | 1.94 | 1.98 | 2.02 | V    |
|                     |                     | (+0.1 V)                    | Falling interrupt voltage    | 1.90 | 1.94 | 1.98 | V    |
|                     | V <sub>LVD9</sub>   | LVIS1, LVIS0 = 0, 1         | Rising release reset voltage | 2.05 | 2.09 | 2.13 | ٧    |
|                     |                     | (+0.2 V)                    | Falling interrupt voltage    | 2.00 | 2.04 | 2.08 | V    |
|                     | V <sub>LVD2</sub>   | LVIS1, LVIS0 = 0, 0         | Rising release reset voltage | 3.07 | 3.13 | 3.19 | V    |
|                     |                     | (+1.2 V)                    | Falling interrupt voltage    | 3.00 | 3.06 | 3.12 | ٧    |
|                     | V <sub>LVD8</sub>   | VPOC2, VPOC1, VPOC0 = 0, 1, | O, falling reset voltage     | 2.40 | 2.45 | 2.50 | ٧    |
|                     | V <sub>LVD7</sub>   | LVIS1, LVIS0 = 1, 0         | Rising release reset voltage | 2.56 | 2.61 | 2.66 | ٧    |
|                     |                     | (+0.1 V)                    | Falling interrupt voltage    | 2.50 | 2.55 | 2.60 | V    |
|                     | V <sub>LVD6</sub>   | LVIS1, LVIS0 = 0, 1         | Rising release reset voltage | 2.66 | 2.71 | 2.76 | V    |
|                     |                     | (+0.2 V)                    | Falling interrupt voltage    | 2.60 | 2.65 | 2.70 | V    |
|                     | V <sub>LVD1</sub>   | LVIS1, LVIS0 = 0, 0         | Rising release reset voltage | 3.68 | 3.75 | 3.82 | V    |
|                     |                     | (+1.2 V)                    | Falling interrupt voltage    | 3.60 | 3.67 | 3.74 | V    |
|                     | V <sub>LVD5</sub>   | VPOC2, VPOC1, VPOC0 = 0, 1, | 1, falling reset voltage     | 2.70 | 2.75 | 2.81 | V    |
|                     | V <sub>LVD4</sub>   | LVIS1, LVIS0 = 1, 0         | Rising release reset voltage | 2.86 | 2.92 | 2.97 | V    |
|                     |                     | (+0.1 V)                    | Falling interrupt voltage    | 2.80 | 2.86 | 2.91 | V    |
|                     | V <sub>LVD3</sub>   | LVIS1, LVIS0 = 0, 1         | Rising release reset voltage | 2.96 | 3.02 | 3.08 | V    |
|                     |                     | (+0.2 V)                    | Falling interrupt voltage    | 2.90 | 2.96 | 3.02 | V    |
|                     | V <sub>LVD0</sub> L | LVIS1, LVIS0 = 0, 0         | Rising release reset voltage | 3.98 | 4.06 | 4.14 | V    |
|                     |                     | (+1.2 V)                    | Falling interrupt voltage    | 3.90 | 3.98 | 4.06 | V    |

# 2.6.5 Supply voltage rise time

### $(T_A = -40 \text{ to } +85^{\circ}\text{C}, \text{ Vss} = 0 \text{ V})$

| Parameter   | Symbol           | Conditions | MIN. | TYP. | MAX. | Unit |
|---|------------------|------------|------|------|------|------|
| V <sub>DD</sub> rise slope (V <sub>DD</sub> : 0 V to V <sub>DD</sub> (MIN.) Note) | SV <sub>DD</sub> |            |      |      | 54   | V/ms |

<R>> Note VDD (MIN.) in each operating mode is as below.

HS (high-speed main) mode: 2.7 V@1 MHz to 24 MHz

2.4 V@1 MHz to 16 MHz

LS (low-speed main) mode: 1.8 V@1 MHz to 8 MHz LV (low-voltage main) mode: 1.6 V@1 MHz to 4 MHz

<R> Caution When LVD off, be sure to use external RESET pin.



# 2.7 LCD Characteristics

### 2.7.1 Resistance division method

### (1) Static display mode

 $(T_A = -40 \text{ to } +85^{\circ}\text{C}, V_{L4} \text{ (MIN.)} \le V_{DD} \le 5.5 \text{ V}, V_{SS} = 0 \text{ V})$ 

| Parameter         | Symbol          | Conditions | MIN. | TYP. | MAX.            | Unit |
|-------------------|-----------------|------------|------|------|-----------------|------|
| LCD drive voltage | V <sub>L4</sub> |            | 2.0  |      | V <sub>DD</sub> | V    |

# (2) 1/2 bias method, 1/4 bias method

 $(T_A = -40 \text{ to } +85^{\circ}\text{C}, V_{L4} \text{ (MIN.)} \le V_{DD} \le 5.5 \text{ V}, V_{SS} = 0 \text{ V})$ 

|     | Parameter | Symbol          | Conditions | MIN. | TYP. | MAX.            | Unit |
|-----|-----------|-----------------|------------|------|------|-----------------|------|
| LCD |           | V <sub>L4</sub> |            | 2.7  |      | V <sub>DD</sub> | ٧    |

## (3) 1/3 bias method

 $(T_A = -40 \text{ to } +85^{\circ}\text{C}, V_{L4} \text{ (MIN.)} \le V_{DD} \le 5.5 \text{ V}, V_{SS} = 0 \text{ V})$ 

| Param             | eter | Symbol          | Conditions | MIN. | TYP. | MAX.                            | Unit |
|-------------------|------|-----------------|------------|------|------|---------------------------------|------|
| LCD drive voltage |      | V <sub>L4</sub> |            | 2.5  |      | V <sub>DD</sub> <sup>Note</sup> | V    |

Note 5.5 V (MAX) when driving a memory-type liquid crystal (the MLCDEN bit of the MLCD register = 1).

# 2.7.2 Internal voltage boosting method

#### (1) 1/3 bias method

 $(T_A = -40 \text{ to } +85^{\circ}\text{C}, 1.8 \text{ V} \le V_{DD} \le 5.5 \text{ V}, \text{Vss} = 0 \text{ V})$ 

| Parameter                                 | Symbol          | Cond                                 | itions          | MIN.                       | TYP.       | MAX.  | Unit |      |
|---|-----------------|--------------------------------------|-----------------|----------------------------|------------|-------|------|------|
| LCD output voltage variation range        | V <sub>L1</sub> | C1 to C4 <sup>Note 1</sup>           | VLCD = 04H      | 0.90                       | 1.00       | 1.08  | V    |      |
|   |                 | $=0.47 \ \mu F^{\text{Note 2}}$      | VLCD = 05H      | 0.95                       | 1.05       | 1.13  | V    |      |
|   |                 |                                      | VLCD = 06H      | 1.00                       | 1.10       | 1.18  | V    |      |
|   |                 |                                      | VLCD = 07H      | 1.05                       | 1.15       | 1.23  | V    |      |
|   |                 |                                      | VLCD = 08H      | 1.10                       | 1.20       | 1.28  | V    |      |
|   |                 |                                      | VLCD = 09H      | 1.15                       | 1.25       | 1.33  | V    |      |
|   |                 |                                      | VLCD = 0AH      | 1.20                       | 1.30       | 1.38  | V    |      |
|   |                 |                                      | VLCD = 0BH      | 1.25                       | 1.35       | 1.43  | V    |      |
|   |                 |                                      | VLCD = 0CH      | 1.30                       | 1.40       | 1.48  | V    |      |
|   |                 |                                      |                 | VLCD = 0DH                 | 1.35       | 1.45  | 1.53 | V    |
|   |                 |                                      |                 |                            | VLCD = 0EH | 1.40  | 1.50 | 1.58 |
|   |                 |                                      | VLCD = 0FH      | 1.45                       | 1.55       | 1.63  | V    |      |
|   |                 |                                      | VLCD = 10H      | 1.50                       | 1.60       | 1.68  | V    |      |
|   |                 |                                      | VLCD = 11H      | 1.55                       | 1.65       | 1.73  | V    |      |
|   |                 |                                      | VLCD = 12H      | 1.60                       | 1.70       | 1.78  | V    |      |
|   |                 |                                      | VLCD = 13H      | 1.65                       | 1.75       | 1.83  | V    |      |
| Doubler output voltage                    | V <sub>L2</sub> | C1 to C4 <sup>Note 1</sup> =         | 0.47 <i>μ</i> F | 2 V <sub>L1</sub><br>-0.1  | 2 VL1      | 2 VL1 | V    |      |
| Tripler output voltage                    | V <sub>L4</sub> | C1 to C4 <sup>Note 1</sup> = 0.47 µF |                 | 3 V <sub>L1</sub><br>-0.15 | 3 VL1      | 3 VL1 | V    |      |
| Reference voltage setup time Note 2       | tvwait1         |                                      |                 | 5                          |            |       | ms   |      |
| Voltage boost wait time <sup>Note 3</sup> | tvwait2         | C1 to C4 <sup>Note 1</sup> =         | 0.47 <i>μ</i> F | 500                        |            |       | ms   |      |

Notes 1. This is a capacitor that is connected between voltage pins used to drive the LCD.

- C1: A capacitor connected between CAPH and CAPL
- C2: A capacitor connected between V<sub>L1</sub> and GND
- C3: A capacitor connected between  $V_{L2}$  and GND
- C4: A capacitor connected between V<sub>L4</sub> and GND
- $C1 = C2 = C3 = C4 = 0.47 \text{ pF} \pm 30 \%$
- 2. This is the time required to wait from when the reference voltage is specified by using the VLCD register (or when the internal voltage boosting method is selected [by setting the MDSET1 and MDSET0 bits of the LCDM0 register to 01B] if the default value reference voltage is used) until voltage boosting starts (VLCON = 1).
- 3. This is the wait time from when voltage boosting is started (VLCON = 1) until display is enabled (LCDON = 1).

#### (2) 1/4 bias method

 $(T_A = -40 \text{ to } +85^{\circ}\text{C}, 1.8 \text{ V} \le V_{DD} \le 5.5 \text{ V}, \text{Vss} = 0 \text{ V})$ 

| Parameter                                 | Symbol          | Cor   | nditions        | MIN.                    | TYP.              | MAX.              | Unit |
|---|-----------------|---|-----------------|-------------------------|-------------------|-------------------|------|
| LCD output voltage variation range        | V <sub>L1</sub> | C1 to C5 <sup>Note 1</sup><br>= 0.47 μF <sup>Note 2</sup> | VLCD = 04H      | 0.90                    | 1.00              | 1.08              | V    |
|   |                 | $= 0.47 \mu$ F  | VLCD = 05H      | 0.95                    | 1.05              | 1.13              | V    |
|   |                 |   | VLCD = 06H      | 1.00                    | 1.10              | 1.18              | V    |
|   |                 |   | VLCD = 07H      | 1.05                    | 1.15              | 1.23              | V    |
|   |                 |   | VLCD = 08H      | 1.10                    | 1.20              | 1.28              | V    |
|   |                 |   | VLCD = 09H      | 1.15                    | 1.25              | 1.33              | V    |
|   |                 |   | VLCD = 0AH      | 1.20                    | 1.30              | 1.38              | V    |
|   |                 |   | VLCD = 0BH      | 1.25                    | 1.35              | 1.43              | V    |
|   |                 |   | VLCD = 0CH      | 1.30                    | 1.40              | 1.48              | V    |
|   |                 |   | VLCD = 0DH      | 1.35                    | 1.45              | 1.53              | V    |
|   |                 |   | VLCD = 0EH      | 1.40                    | 1.50              | 1.58              | V    |
|   |                 |   | VLCD = 0FH      | 1.45                    | 1.55              | 1.63              | V    |
|   |                 |   | VLCD = 10H      | 1.50                    | 1.60              | 1.68              | V    |
|   |                 |   | VLCD = 11H      | 1.55                    | 1.65              | 1.73              | V    |
|   |                 |   | VLCD = 12H      | 1.60                    | 1.70              | 1.78              | V    |
|   |                 |   | VLCD = 13H      | 1.65                    | 1.75              | 1.83              | V    |
| Doubler output voltage                    | VL2             | C1 to C5 <sup>Note 1</sup> =                              | 0.47 μF         | 2 VL1-0.08              | 2 V <sub>L1</sub> | 2 VL1             | V    |
| Tripler output voltage                    | VL3             | C1 to C5 <sup>Note 1</sup> =                              | 0.47 <i>μ</i> F | 3 V <sub>L1</sub> -0.12 | 3 VL1             | 3 VL1             | V    |
| Quadruply output voltage                  | VL4             | C1 to C5 <sup>Note 1</sup> =                              | 0.47 <i>μ</i> F | 4 V <sub>L1</sub> –0.16 | 4 V <sub>L1</sub> | 4 V <sub>L1</sub> | V    |
| Reference voltage setup time Note 2       | tvwait1         |   |                 | 5                       |                   |                   | ms   |
| Voltage boost wait time <sup>Note 3</sup> | tvwait2         | C1 to C5 <sup>Note 1</sup> =                              | 0.47 <i>μ</i> F | 500                     |                   |                   | ms   |

Notes 1. This is a capacitor that is connected between voltage pins used to drive the LCD.

- C1: A capacitor connected between CAPH and CAPL
- C2: A capacitor connected between VL1 and GND
- C3: A capacitor connected between V<sub>L2</sub> and GND
- C4: A capacitor connected between V<sub>L3</sub> and GND
- C5: A capacitor connected between VL4 and GND
- $C1 = C2 = C3 = C4 = C5 = 0.47 \text{ pF} \pm 30 \%$
- 2. This is the time required to wait from when the reference voltage is specified by using the VLCD register (or when the internal voltage boosting method is selected [by setting the MDSET1 and MDSET0 bits of the LCDM0 register to 01B] if the default value reference voltage is used) until voltage boosting starts (VLCON = 1).
- 3. This is the wait time from when voltage boosting is started (VLCON = 1) until display is enabled (LCDON = 1).

# 2.7.3 Capacitor split method

### (1) 1/3 bias method

 $(T_A = -40 \text{ to } +85^{\circ}\text{C}, 2.2 \text{ V} \le V_{DD} = \text{EV}_{DD} \le 5.5 \text{ V}, \text{Vss} = 0 \text{ V})$ 

| Parameter                                   | Symbol          | Conditions                                | MIN.                        | TYP.                | MAX.                        | Unit |
|---|-----------------|---|-----------------------------|---------------------|-----------------------------|------|
| V <sub>L4</sub> voltage                     | V <sub>L4</sub> | C1 to C4 = 0.47 $\mu$ F <sup>Note 2</sup> |                             | V <sub>DD</sub>     |                             | V    |
| V <sub>L2</sub> voltage                     | V <sub>L2</sub> | C1 to C4 = 0.47 $\mu$ F <sup>Note 2</sup> | 2/3 V <sub>L4</sub><br>-0.1 | 2/3 V <sub>L4</sub> | 2/3 V <sub>L4</sub><br>+0.1 | V    |
| V <sub>L1</sub> voltage                     | V <sub>L1</sub> | C1 to C4 = 0.47 $\mu$ F <sup>Note 2</sup> | 1/3 V <sub>L4</sub><br>-0.1 | 1/3 V <sub>L4</sub> | 1/3 V <sub>L4</sub><br>+0.1 | V    |
| Capacitor split wait time <sup>Note 1</sup> | tvwait          |   | 100                         |                     |                             | ms   |

**Notes 1.** This is the wait time from when voltage bucking is started (VLCON = 1) until display is enabled (LCDON = 1).

- 2. This is a capacitor that is connected between voltage pins used to drive the LCD.
  - C1: A capacitor connected between CAPH and CAPL
  - C2: A capacitor connected between VL1 and GND
  - C3: A capacitor connected between  $V_{\text{L2}}$  and GND
  - C4: A capacitor connected between VL4 and GND
  - $C1 = C2 = C3 = C4 = 0.47 \text{ pF} \pm 30 \%$

<R>

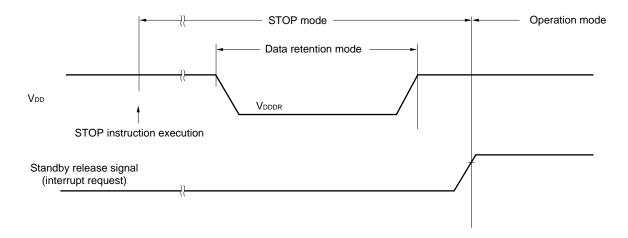
<R>

### 2.8 Data Memory STOP Mode Low Supply Voltage Data Retention Characteristics

#### $(T_A = -40 \text{ to } +85^{\circ}\text{C})$

ParameterSymbolConditionsMIN.TYP.MAX.UnitData retention supply voltageVDDDR1.46Note5.5V

**Note** The value depends on the POR detection voltage. When the voltage drops, the data is retained before a POR reset is effected, but data is not retained when a POR reset is effected.



# 2.9 Flash Memory Programming Characteristics

 $(T_A = -40 \text{ to } +85^{\circ}\text{C}, 1.8 \text{ V} \le \text{EV}_{DD} = \text{V}_{DD} \le 5.5 \text{ V}, \text{Vss} = \text{EV}_{SS} = 0 \text{ V})$ 

| Parameter                     | Symbol | Conditions                     |  | MIN.    | TYP.      | MAX. | Unit  |
|-------------------------------|--------|--------------------------------|--|---------|-----------|------|-------|
| System clock frequency        | fclk   | $1.8~V \leq V_{DD} \leq 5.5~V$ | $1.8 \text{ V} \leq \text{Vdd} \leq 5.5 \text{ V}$ |         |           | 24   | MHz   |
| Number of code flash rewrites | Cerwr  | Retained for 20 years          | $T_A = 85^{\circ}C^{\text{Note 3}}$                | 1,000   |           |      | Times |
| Number of data flash rewrites |        | Retained for 1 year            | $T_A = 25^{\circ}C^{\text{Note 3}}$                |         | 1,000,000 |      |       |
|                               |        | Retained for 5 years           | T <sub>A</sub> = 85°C Note 3                       | 100,000 |           |      |       |
|                               |        | Retained for 20 years          | T <sub>A</sub> = 85°C Note 3                       | 10,000  |           |      |       |

**Notes 1.** 1 erase + 1 write after the erase is regarded as 1 rewrite.

The retaining years are until next rewrite after the rewrite.

- 2. When using flash memory programmer and Renesas Electronics self programming library
- **3.** This characteristic indicates the flash memory characteristic and based on Renesas Electronics reliability test.

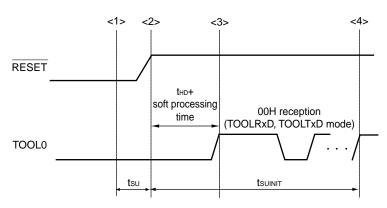
Remark When updating data multiple times, use the flash memory as one for updating data.



### 2.10 Timing Specifications for Switching Flash Memory Programming Modes

| Parameter   | Symbol  | Conditions  | MIN. | TYP. | MAX. | Unit |
|---|---------|---|------|------|------|------|
| How long from when a pin reset ends until the initial communication settings are specified            | tsuinit | POR and LVD reset must end before the pin reset ends. |      |      | 100  | ms   |
| How long from when the TOOL0 pin is placed at the low level until a pin reset ends                    | tsu     | POR and LVD reset must end before the pin reset ends. | 10   |      |      | μS   |
| How long the TOOL0 pin must be kept at the low level after a reset ends (except soft processing time) | tно     | POR and LVD reset must end before the pin reset ends. | 1    |      |      | ms   |





- <1> The low level is input to the TOOL0 pin.
- <2> The pins reset ends. (POR and LVD reset must end before the pin reset ends.)
- <3> The TOOL0 pin is set to the high level.
- <4> Setting of the flash memory programming mode by UART reception and completion of the baud rate setting.

**Remark** tsuinit: The segment shows that it is necessary to finish specifying the initial communication settings within 100 ms from when the reset ends.

tsu: How long from when the TOOL0 pin is placed at the low level until a pin reset ends (MIN. 10  $\mu$ s)

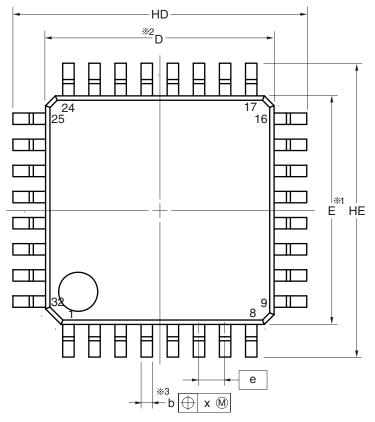
thd: How long to keep the TOOL0 pin at the low level from when the external or internal resets ends (except software processing time)

# 3. PACKAGE DRAWINGS

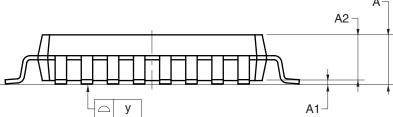
# 3.1 32-pin products

### R5F10RB8AFP, R5F10RBAAFP, R5F10RBCAFP

| JEITA Package Code | RENESAS Code | Previous Code  | MASS (TYP.) [g] |
|--------------------|--------------|----------------|-----------------|
| P-LQFP32-7x7-0.80  | PLQP0032GB-A | P32GA-80-GBT-1 | 0.2             |



detail of lead end



(UNIT:mm)

|          | (UNIT:mm)       |
|----------|-----------------|
| ITEM     | DIMENSIONS      |
| D        | 7.00±0.10       |
| Е        | 7.00±0.10       |
| HD       | 9.00±0.20       |
| HE       | 9.00±0.20       |
| Α        | 1.70 MAX.       |
| A1       | 0.10±0.10       |
| A2       | 1.40            |
| b        | $0.37{\pm}0.05$ |
| С        | 0.145±0.055     |
| L        | 0.50±0.20       |
| $\theta$ | 0° to 8°        |
| е        | 0.80            |
| х        | 0.20            |
| У        | 0.10            |

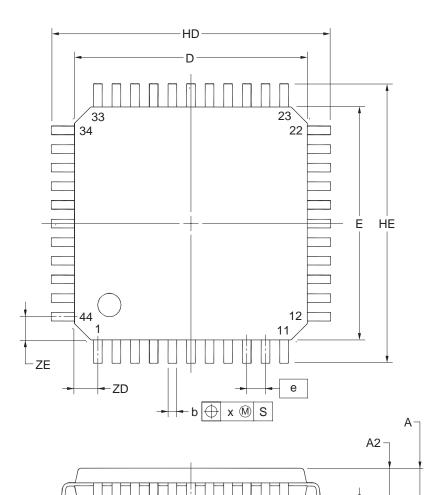
### NOTE

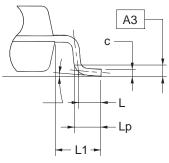
- 1.Dimensions "%1" and "%2" do not include mold flash.
- 2.Dimension "%3" does not include trim offset.

# 3.2 44-pin products

# R5F10RF8AFP, R5F10RFAAFP, R5F10RFCAFP

| JEITA Package Code  | RENESAS Code | Previous Code  | MASS (TYP.) [g] |
|---------------------|--------------|----------------|-----------------|
| P-LQFP44-10x10-0.80 | PLQP0044GC-A | P44GB-80-UES-2 | 0.36            |





detail of lead end

(UNIT:mm)

| ITEM | DIMENSIONS                |
|------|---------------------------|
| D    | 10.00±0.20                |
| Е    | 10.00±0.20                |
| HD   | 12.00±0.20                |
| HE   | 12.00±0.20                |
| Α    | 1.60 MAX.                 |
| A1   | 0.10±0.05                 |
| A2   | 1.40±0.05                 |
| A3   | 0.25                      |
| b    | $0.37^{+0.08}_{0.07}$     |
| С    | $0.145^{+0.055}_{-0.045}$ |
| L    | 0.50                      |
| Lp   | 0.60±0.15                 |
| L1   | 1.00±0.20                 |
|      | 3°+5°                     |
| е    | 0.80                      |
| Х    | 0.20                      |
| У    | 0.10                      |
| ZD   | 1.00                      |

1.00

# S NOTE

Each lead centerline is located within 0.20 mm of

its true position at maximum material condition.

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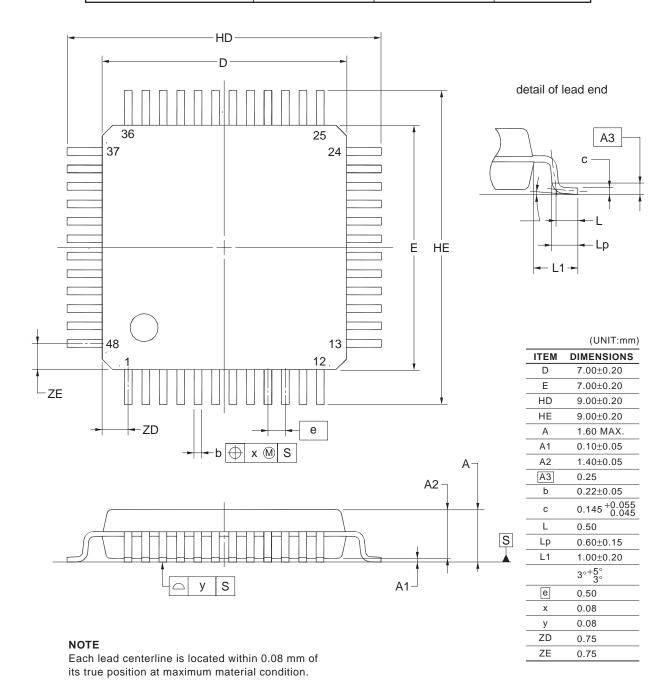
ZE

S

# 3.3 48-pin products

### R5F10RG8AFB, R5F10RGAAFB, R5F10RGCAFB

| JEITA Package Code | RENESAS Code | Previous Code  | MASS (TYP.) [g] |
|--------------------|--------------|----------------|-----------------|
| P-LFQFP48-7x7-0.50 | PLQP0048KF-A | P48GA-50-8EU-1 | 0.16            |

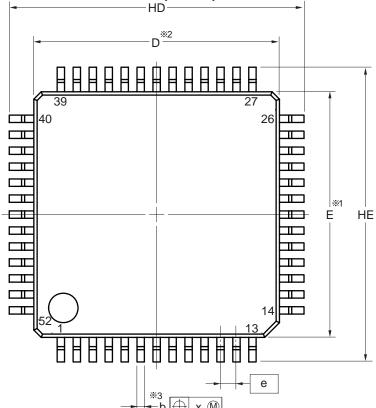


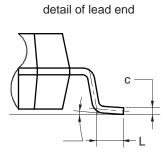
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# 3.4 52-pin products

R5F10RJ8AFA, R5F10RJAAFA, R5F10RJCAFA









#### NOTE

- 1.Dimensions "%1" and "%2" do not include mold flash.
- 2.Dimension "%3" does not include trim offset.

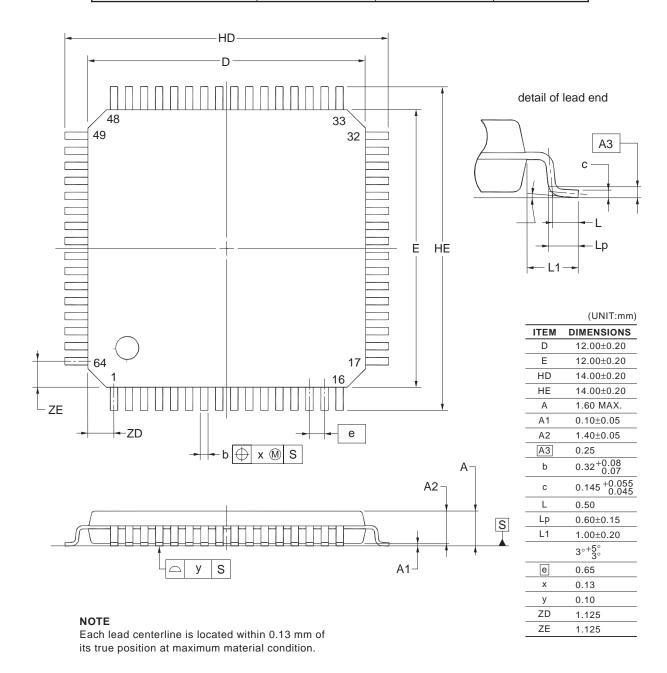
|      | (UNIT:mm)   |
|------|-------------|
| ITEM | DIMENSIONS  |
| D    | 10.00±0.10  |
| E    | 10.00±0.10  |
| HD   | 12.00±0.20  |
| HE   | 12.00±0.20  |
| А    | 1.70 MAX.   |
| A1   | 0.10±0.05   |
| A2   | 1.40        |
| b    | 0.32±0.05   |
| С    | 0.145±0.055 |
| L    | 0.50±0.15   |
|      | 0° to 8°    |
| е    | 0.65        |
| Х    | 0.13        |
| У    | 0.10        |

P52GB-65-GBS

# 3.5 64-pin products

### R5F10RLAAFA, R5F10RLCAFA

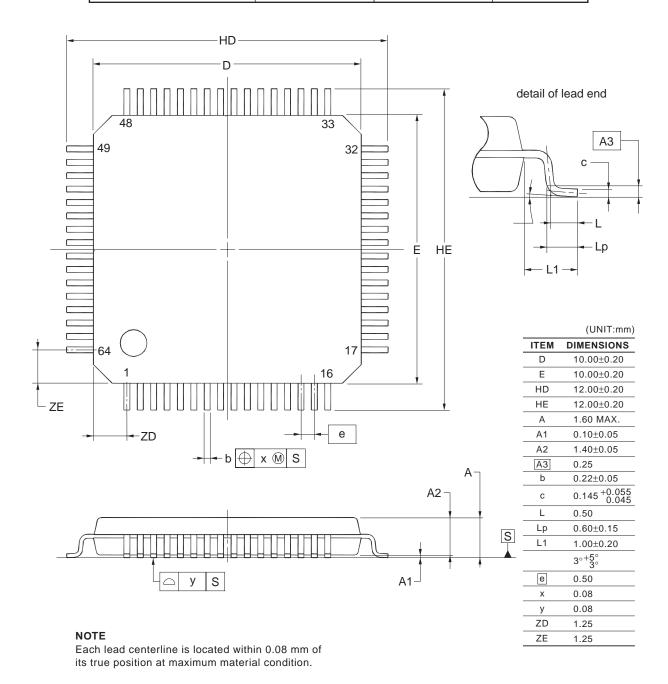
| JEITA Package Code  | RENESAS Code | Previous Code  | MASS (TYP.) [g] |
|---------------------|--------------|----------------|-----------------|
| P-LQFP64-12x12-0.65 | PLQP0064JA-A | P64GK-65-UET-2 | 0.51            |



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### R5F10RLAAFB, R5F10RLCAFB

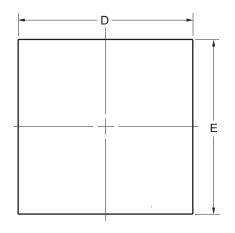
| JEITA Package Code   | RENESAS Code | Previous Code  | MASS (TYP.) [g] |
|----------------------|--------------|----------------|-----------------|
| P-LFQFP64-10x10-0.50 | PLQP0064KF-A | P64GB-50-UEU-2 | 0.35            |

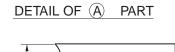


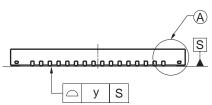
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### R5F10RLAANB, R5F10RLCANB

| JEITA Package Code | RENESAS Code | Previous Code  | MASS (TYP.) [g] |
|--------------------|--------------|----------------|-----------------|
| P-HWQFN64-8x8-0.40 | PWQN0064LA-A | P64K8-40-9B5-1 | 0.16            |







|      | (UNIT:mm)       |
|------|-----------------|
| ITEM | DIMENSIONS      |
| D    | $8.00 \pm 0.05$ |
| Е    | 8.00±0.05       |
| Α    | 0.75±0.05       |
| b    | 0.20±0.05       |
| е    | 0.40            |
| Lp   | 0.40±0.10       |
| х    | 0.05            |
| У    | 0.05            |

|  | ITEM                             |   | D2   |      | E2   |      |      |      |
|--|----------------------------------|---|------|------|------|------|------|------|
|  |                                  |   | MIN  | NOM  | MAX  | MIN  | NOM  | MAX  |
|  | EXPOSED<br>DIE PAD<br>VARIATIONS | Α | 6.45 | 6.50 | 6.55 | 6.45 | 6.50 | 6.55 |

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В

| Revision | History |
|----------|---------|
|----------|---------|

# RL78/L12 Data Sheet

|      |              |          | Description   |
|------|--------------|----------|---|
| Rev. | Date         | Page     | Summary   |
| 0.01 | Feb 20, 2012 | -        | First Edition issued  |
| 0.02 | Sep 26, 2012 | 7, 8     | Modification of caution 2 in 1.3.5 64-pin products  |
|      |              | 15       | Modification of I/O port in 1.6 Outline of Functions  |
|      |              | -        | Modification of 2. ELECTRICAL SPECIFICATIONS (TARGET)   |
|      |              | -        | Update of package drawings in 3. PACKAGE DRAWINGS   |
| 1.00 | Jan 31, 2013 | 11 to 15 | Modification of 1.5 Block Diagram   |
|      |              | 16       | Modification of Note 2 in 1.6 Outline of Functions  |
|      |              | 17       | Modification of 1.6 Outline of Functions  |
|      |              | -        | Deletion of target in 2. ELECTRICAL SPECIFICATIONS  |
|      |              | 18       | Addition of caution 2 to 2. ELECTRICAL SPECIFICATIONS   |
|      |              | 19       | Addition of description, note 3, and remark 2 to 2.1 Absolute Maximum Ratings   |
|      |              | 20       | Modification of description and addition of <b>note</b> to <b>2.1 Absolute Maximum</b> Ratings  |
|      |              | 22, 23   | Modification of 2.2 Oscillator Characteristics  |
|      |              | 30       | Modification of notes 1 to 4 in 2.3.2 Supply current characteristics  |
|      |              | 32       | Modification of notes 1, 3 to 6, 8 in 2.3.2 Supply current characteristics  |
|      |              | 34       | Modification of <b>notes 7</b> , <b>9</b> , <b>11</b> , and addition of <b>notes 8</b> , <b>12</b> to <b>2.3.2 Supply</b> current characteristics |
|      |              | 36       | Addition of description to 2.4 AC Characteristics   |
|      |              | 38, 40   | Modification of 2.5.1 Serial array unit   |
|      |              | to 42,   |   |
|      |              | 44 to    |   |
|      |              | 46, 48   |   |
|      |              | to 52,   |   |
|      |              | 54, 55   | Madification of 0.5.0. Contact interferentials  |
|      |              | 57, 58   | Modification of 2.5.2 Serial interface IICA   |
|      |              | 62       | Modification of 2.6.2 Temperature sensor/internal reference voltage characteristics   |
|      |              | 64       | Addition of note and caution in 2.6.5 Supply voltage rise time  |
|      |              | 69       | Modification of 2.8 Data Memory STOP Mode Low Supply Voltage Data Retention Characteristics   |
|      |              | 69       | Modification of conditions in 2.9 Timing Specs for Switching Flash Memory Programming Modes   |
|      |              | 70       | Modification of 2.10 Timing Specifications for Switching Flash Memory Programming Modes   |

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#### NOTES FOR CMOS DEVICES

- (1) VOLTAGE APPLICATION WAVEFORM AT INPUT PIN: Waveform distortion due to input noise or a reflected wave may cause malfunction. If the input of the CMOS device stays in the area between VIL (MAX) and VIH (MIN) due to noise, etc., the device may malfunction. Take care to prevent chattering noise from entering the device when the input level is fixed, and also in the transition period when the input level passes through the area between VIL (MAX) and VIH (MIN).
- (2) HANDLING OF UNUSED INPUT PINS: Unconnected CMOS device inputs can be cause of malfunction. If an input pin is unconnected, it is possible that an internal input level may be generated due to noise, etc., causing malfunction. CMOS devices behave differently than Bipolar or NMOS devices. Input levels of CMOS devices must be fixed high or low by using pull-up or pull-down circuitry. Each unused pin should be connected to VDD or GND via a resistor if there is a possibility that it will be an output pin. All handling related to unused pins must be judged separately for each device and according to related specifications governing the device.
- (3) PRECAUTION AGAINST ESD: A strong electric field, when exposed to a MOS device, can cause destruction of the gate oxide and ultimately degrade the device operation. Steps must be taken to stop generation of static electricity as much as possible, and quickly dissipate it when it has occurred. Environmental control must be adequate. When it is dry, a humidifier should be used. It is recommended to avoid using insulators that easily build up static electricity. Semiconductor devices must be stored and transported in an anti-static container, static shielding bag or conductive material. All test and measurement tools including work benches and floors should be grounded. The operator should be grounded using a wrist strap. Semiconductor devices must not be touched with bare hands. Similar precautions need to be taken for PW boards with mounted semiconductor devices.
- (4) STATUS BEFORE INITIALIZATION: Power-on does not necessarily define the initial status of a MOS device. Immediately after the power source is turned ON, devices with reset functions have not yet been initialized. Hence, power-on does not guarantee output pin levels, I/O settings or contents of registers. A device is not initialized until the reset signal is received. A reset operation must be executed immediately after power-on for devices with reset functions.
- (5) POWER ON/OFF SEQUENCE: In the case of a device that uses different power supplies for the internal operation and external interface, as a rule, switch on the external power supply after switching on the internal power supply. When switching the power supply off, as a rule, switch off the external power supply and then the internal power supply. Use of the reverse power on/off sequences may result in the application of an overvoltage to the internal elements of the device, causing malfunction and degradation of internal elements due to the passage of an abnormal current. The correct power on/off sequence must be judged separately for each device and according to related specifications governing the device.
- (6) INPUT OF SIGNAL DURING POWER OFF STATE: Do not input signals or an I/O pull-up power supply while the device is not powered. The current injection that results from input of such a signal or I/O pull-up power supply may cause malfunction and the abnormal current that passes in the device at this time may cause degradation of internal elements. Input of signals during the power off state must be judged separately for each device and according to related specifications governing the device.

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